

# MPC8313E PowerQUICC™ II Pro Processor Hardware Specifications

This document provides an overview of the MPC8313E PowerQUICC™ II Pro processor features, including a block diagram showing the major functional components. The MPC8313E is a cost-effective, low-power, highly integrated host processor that addresses the requirements of several printing and imaging, consumer, and industrial applications, including main CPUs and I/O processors in printing systems, networking switches and line cards, wireless LANs (WLANs), network access servers (NAS), VPN routers, intelligent NIC, and industrial controllers. The MPC8313E extends the PowerQUICC™ family, adding higher CPU performance, additional functionality, and faster interfaces while addressing the requirements related to time-to-market, price, power consumption, and package size.

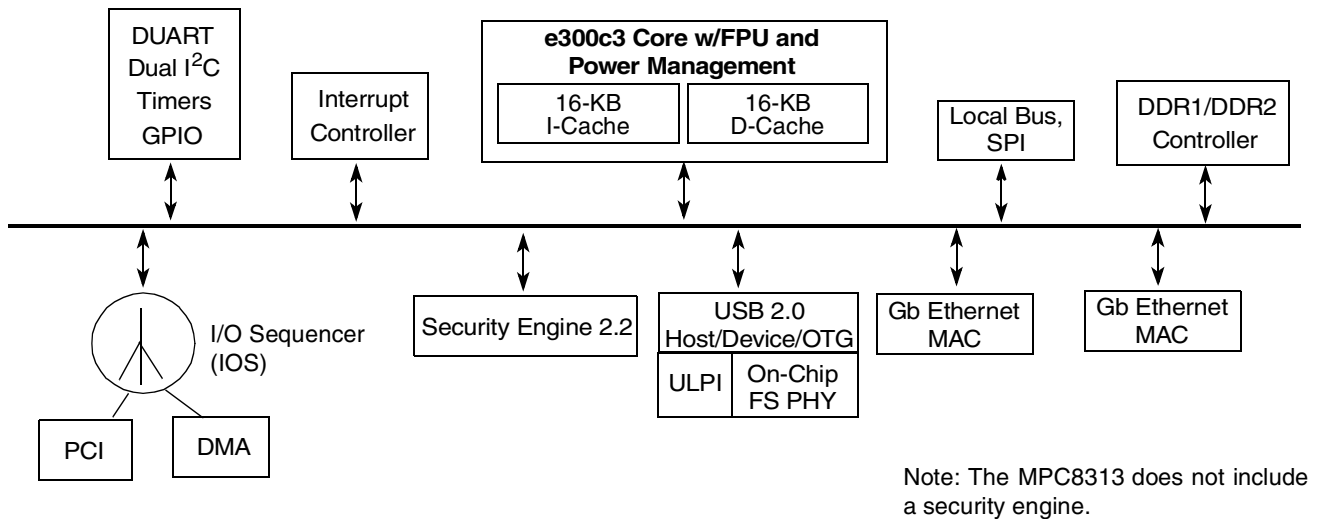
## 1 Overview

The MPC8313E incorporates the e300c3 core, which includes 16 Kbytes of L1 instruction and data caches and on-chip memory management units (MMUs). The MPC8313E has interfaces to dual enhanced three-speed 10, 100, 1000 Mbps Ethernet controllers, a DDR1/DDR2 SDRAM memory controller, an enhanced local bus controller, a 32-bit PCI controller, a dedicated security

### Contents

|                                                      |    |
|------------------------------------------------------|----|
| 1. Overview .....                                    | 1  |
| 2. Electrical Characteristics .....                  | 6  |
| 3. Power Characteristics .....                       | 10 |
| 4. Clock Input Timing .....                          | 12 |
| 5. RESET Initialization .....                        | 13 |
| 6. DDR and DDR2 SDRAM .....                          | 14 |
| 7. DUART .....                                       | 21 |
| 8. Ethernet: Three-Speed Ethernet, MII Management .. | 21 |
| 9. USB .....                                         | 35 |
| 10. Local Bus .....                                  | 37 |
| 11. JTAG .....                                       | 42 |
| 12. I <sup>2</sup> C .....                           | 45 |
| 13. PCI .....                                        | 47 |
| 14. Timers .....                                     | 49 |
| 15. GPIO .....                                       | 50 |
| 16. IPIC .....                                       | 51 |
| 17. SPI .....                                        | 52 |
| 18. Package and Pin Listings .....                   | 54 |
| 19. Clocking .....                                   | 68 |
| 20. Thermal .....                                    | 73 |
| 21. System Design Information .....                  | 79 |
| 22. Document Revision History .....                  | 86 |
| 23. Ordering Information .....                       | 88 |

engine, a USB 2.0 dual-role controller and an on-chip full-speed PHY, a programmable interrupt controller, dual I<sup>2</sup>C controllers, a 4-channel DMA controller, and a general-purpose I/O port. A block diagram of the MPC8313E is shown in Figure 1.



**Figure 1. MPC8313E Block Diagram**

The MPC8313E's security engine (SEC 2.2) allows CPU-intensive cryptographic operations to be offloaded from the main CPU core. The security-processing accelerator provides hardware acceleration for the DES, 3DES, AES, SHA-1, and MD-5 algorithms.

## 1.1 MPC8313E Features

The following features are supported in the MPC8313E.

- Embedded PowerPC™ e300 processor core; operates at up to 333 MHz.
- High-performance, low-power, and cost-effective host processor
- DDR1/DDR2 memory controller—one 16-/32-bit interface at up to 333 MHz supporting both DDR1 and DDR2
- e300c3 core, built on Power Architecture™ technology, with 16-Kbyte instruction cache and 16-Kbyte data cache, a floating point unit, and two integer units
- Peripheral interfaces such as 32-bit PCI interface with up to 66-MHz operation, 16-bit enhanced local bus interface with up to 66-MHz operation, and USB 2.0 (full speed) with an on-chip PHY.
- Security engine provides acceleration for control and data plane security protocols
- Power management controller for low-power consumption
- High degree of software compatibility with previous-generation PowerQUICC processor-based designs for backward compatibility and easier software migration

## 1.2 Serial Interfaces

The following interfaces are supported in the MPC8313E:

- Dual UART, dual I<sup>2</sup>C, and an SPI interface

## 1.3 Security Engine

The security engine is optimized to handle all the algorithms associated with IPSec, IEEE Std 802.11i™, and iSCSI. The security engine contains one crypto-channel, a controller, and a set of crypto execution units (EUs). The execution units are as follows:

- Data encryption standard execution unit (DEU), supporting DES and 3DES
- Advanced encryption standard unit (AESU), supporting AES
- Message digest execution unit (MDEU), supporting MD5, SHA1, SHA-224, SHA-256, and HMAC with any algorithm
- One crypto-channel supporting multi-command descriptor chains

## 1.4 DDR Memory Controller

The MPC8313E DDR1/DDR2 memory controller includes the following features:

- Single 16- or 32-bit interface supporting both DDR1 and DDR2 SDRAM
- Support for up to 333 MHz
- Support for two physical banks (chip selects), each bank independently addressable
- 64-Mbit to 1-Gbit devices with x8/x16/x32 data ports (no direct x4 support)
- Support for one 16-bit device or two 8-bit devices on a 16-bit bus, OR one 32-bit device or two 16-bit devices on a 32-bit bus
- Support for up to 16 simultaneous open pages
- Supports auto refresh
- On-the-fly power management using CKE
- 1.8-/2.5-V SSTL2 compatible I/O

## 1.5 PCI Controller

The MPC8313E PCI controller includes the following features:

- PCI specification revision 2.3 compatible
- Single 32-bit data PCI interface operates at up to 66 MHz
- PCI 3.3-V compatible (not 5-V compatible)
- Support for host and agent modes
- On-chip arbitration, supporting three external masters on PCI
- Selectable hardware-enforced coherency

## 1.6 USB Dual-Role Controller

The MPC8313E USB controller includes the following features:

- Supports USB on-the-go mode, which includes both device and host functionality, when using an external ULPI (UTMI + low-pin interface) PHY
- Compatible with USB Specification, Rev. 2.0
- Supports operation as a stand-alone USB device
  - Supports one upstream facing port
  - Supports three programmable USB endpoints
- Supports operation as a stand-alone USB host controller
  - Supports USB root hub with one downstream-facing port
  - Enhanced host controller interface (EHCI) compatible
- Supports full-speed (12 Mbps), and low-speed (1.5 Mbps) operation. Low-speed operation is supported only in host mode.
- Supports UTMI + low pin interface (ULPI) or on-chip USB 2.0 full-speed PHY

## 1.7 Dual Enhanced Three-Speed Ethernet Controllers (eTSECs)

The MPC8313E eTSECs include the following features:

- Two RGMII/SGMII/MII/RMII/RTBI interfaces
- Two controllers designed to comply with IEEE Std 802.3™, 802.3u™, 802.3x™, 802.3z™, 802.3au™, and 802.3ab™
- Support for Wake-on-Magic Packet™, a method to bring the device from standby to full operating mode
- MII management interface for external PHY control and status
- Three-speed support (10/100/1000 Mbps)
- On-chip high-speed serial interface to external SGMII PHY interface
- Support for IEEE Std 1588™
- Support for two full-duplex FIFO interface modes
- Multiple PHY interface configuration
- TCP/IP acceleration and QoS features available
- IP v4 and IP v6 header recognition on receive
- IP v4 header checksum verification and generation
- TCP and UDP checksum verification and generation
- Per-packet configurable acceleration
- Recognition of VLAN, stacked (queue in queue) VLAN, IEEE Std 802.2™, PPPoE session, MPLS stacks, and ESP/AH IP-security headers
- Transmission from up to eight physical queues.
- Reception to up to eight physical queues

- Full- and half-duplex Ethernet support (1000 Mbps supports only full-duplex):
  - IEEE 802.3 full-duplex flow control (automatic PAUSE frame generation or software-programmed PAUSE frame generation and recognition)
  - Programmable maximum frame length supports jumbo frames (up to 9.6 Kbytes) and IEEE 802.1 virtual local area network (VLAN) tags and priority
  - VLAN insertion and deletion
    - Per-frame VLAN control word or default VLAN for each eTSEC
    - Extracted VLAN control word passed to software separately
  - Retransmission following a collision
  - CRC generation and verification of inbound/outbound packets
  - Programmable Ethernet preamble insertion and extraction of up to 7 bytes
- MAC address recognition:
  - Exact match on primary and virtual 48-bit unicast addresses
    - VRRP and HSRP support for seamless router fail-over
  - Up to 16 exact-match MAC addresses supported
  - Broadcast address (accept/reject)
  - Hash table match on up to 512 multicast addresses
  - Promiscuous mode
- Buffer descriptors backward compatible with MPC8260 and MPC860T 10/100 Ethernet programming models
- RMON statistics support
- 10-Kbyte internal transmit and 2-Kbyte receive FIFOs
- MII management interface for control and status

## 1.8 Programmable Interrupt Controller (PIC)

The programmable interrupt controller (PIC) implements the necessary functions to provide a flexible solution for general-purpose interrupt control. The PIC programming model supports 5 external and 34 internal discrete interrupt sources. Interrupts can also be redirected to an external interrupt controller.

## 1.9 Power Management Controller (PMC)

The MPC8313E power management controller includes the following features:

- Provides power management when the device is used in both host and agent modes
- Supports PCI Power Management 1.2 D0, D1, D2, D3hot, and D3cold states
- On-chip split power supply controlled through external power switch for minimum standby power
- Support for PME generation in PCI agent mode, PME detection in PCI host mode
- Supports wake-up from Ethernet (magic packet), USB, GPIO, and PCI (PME input as host)

## 1.10 Serial Peripheral Interface (SPI)

The serial peripheral interface (SPI) allows the MPC8313E to exchange data between other PowerQUICC family chips, Ethernet PHYs for configuration, and peripheral devices such as EEPROMs, real-time clocks, A/D converters, and ISDN devices.

The SPI is a full-duplex, synchronous, character-oriented channel that supports a four-wire interface (receive, transmit, clock, and slave select). The SPI block consists of transmitter and receiver sections, an independent baud-rate generator, and a control unit.

## 1.11 DMA Controller, Dual I<sup>2</sup>C, DUART, Local Bus Controller, and Timers

The MPC8313E provides an integrated four-channel DMA controller with the following features:

- Allows chaining (both extended and direct) through local memory-mapped chain descriptors (accessible by local masters)
- Supports misaligned transfers

There are two I<sup>2</sup>C controllers. These synchronous, multi-master buses can be connected to additional devices for expansion and system development.

The DUART supports full-duplex operation and is compatible with the PC16450 and PC16550 programming models. 16-byte FIFOs are supported for both the transmitter and the receiver.

The MPC8313E local bus controller (LBC) port allows connections with a wide variety of external DSPs and ASICs. Three separate state machines share the same external pins and can be programmed separately to access different types of devices. The general-purpose chip select machine (GPCM) controls accesses to asynchronous devices using a simple handshake protocol. The three user programmable machines (UPMs) can be programmed to interface to synchronous devices or custom ASIC interfaces. Each chip select can be configured so that the associated chip interface can be controlled by the GPCM or UPM controller. The FCM provides a glueless interface to parallel-bus NAND Flash E2PROM devices. The FCM contains three basic configuration register groups—BR<sub>n</sub>, OR<sub>n</sub>, and FMR. Both may exist in the same system. The local bus can operate at up to 66 MHz.

The MPC8313E system timers include the following features: periodic interrupt timer, real time clock, software watchdog timer, and two general-purpose timer blocks.

## 2 Electrical Characteristics

This section provides the AC and DC electrical specifications and thermal characteristics for the MPC8313E. The MPC8313E is currently targeted to these specifications. Some of these specifications are independent of the I/O cell, but are included for a more complete reference. These are not purely I/O buffer design specifications.

### 2.1 Overall DC Electrical Characteristics

This section covers the ratings, conditions, and other characteristics.

## 2.1.1 Absolute Maximum Ratings

Table 1 provides the absolute maximum ratings.

**Table 1. Absolute Maximum Ratings** <sup>1</sup>

| Characteristic                                                                                     |                                                                                                        | Symbol              | Max Value                                                          | Unit | Notes |
|----------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------|---------------------|--------------------------------------------------------------------|------|-------|
| Core supply voltage                                                                                |                                                                                                        | $V_{DD}$            | −0.3 to 1.26                                                       | V    | —     |
| PLL supply voltage                                                                                 |                                                                                                        | $AV_{DD}$           | −0.3 to 1.26                                                       | V    | —     |
| Core power supply for SerDes transceivers                                                          |                                                                                                        | XCOREVDD            | −0.3 to 1.26                                                       | V    | —     |
| Pad power supply for SerDes transceivers                                                           |                                                                                                        | XPADVDD             | −0.3 to 1.26                                                       | V    | —     |
| DDR and DDR2 DRAM I/O voltage                                                                      |                                                                                                        | $GV_{DD}$           | −0.3 to 2.75<br>−0.3 to 1.98                                       | V    | —     |
| PCI, local bus, DUART, system control and power management, I <sup>2</sup> C, and JTAG I/O voltage |                                                                                                        | $NV_{DD}/LV_{DD}$   | −0.3 to 3.6                                                        | V    | —     |
| eTSEC, USB                                                                                         |                                                                                                        | $LV_{DDA}/LV_{DDB}$ | −0.3 to 3.6                                                        | V    | —     |
| Input voltage                                                                                      | DDR DRAM signals                                                                                       | $MV_{IN}$           | −0.3 to ( $GV_{DD} + 0.3$ )                                        | V    | 2, 5  |
|                                                                                                    | DDR DRAM reference                                                                                     | $MV_{REF}$          | −0.3 to ( $GV_{DD} + 0.3$ )                                        | V    | 2, 5  |
|                                                                                                    | Enhanced Three-speed Ethernet signals                                                                  | $LV_{IN}$           | −0.3 to ( $LV_{DDA} + 0.3$ )<br>or<br>−0.3 to ( $LV_{DDB} + 0.3$ ) | V    | 4, 5  |
|                                                                                                    | Local bus, DUART, SYS_CLK_IN, system control, and power management, I <sup>2</sup> C, and JTAG signals | $OV_{IN}$           | −0.3 to ( $NV_{DD} + 0.3$ )                                        | V    | 3, 5  |
|                                                                                                    | PCI                                                                                                    | $OV_{IN}$           | −0.3 to ( $NV_{DD} + 0.3$ )                                        | V    | 6     |
| Storage temperature range                                                                          |                                                                                                        | $T_{STG}$           | −55 to 150                                                         | °C   | —     |

**Notes:**

- Functional and tested operating conditions are given in Table 2. Absolute maximum ratings are stress ratings only, and functional operation at the maximums is not guaranteed. Stresses beyond those listed may affect device reliability or cause permanent damage to the device.
- Caution:**  $MV_{IN}$  must not exceed  $GV_{DD}$  by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
- Caution:**  $OV_{IN}$  must not exceed  $NV_{DD}$  by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
- Caution:**  $LV_{IN}$  must not exceed  $LV_{DDA}/LV_{DDB}$  by more than 0.3 V. This limit may be exceeded for a maximum of 20 ms during power-on reset and power-down sequences.
- (L,M,O) $V_{IN}$  and  $MV_{REF}$  may overshoot/undershoot to a voltage and for a maximum duration as shown in Figure 2.
- $OV_{IN}$  on the PCI interface may overshoot/undershoot according to the PCI Electrical Specification for 3.3-V operation, as shown in Figure 3.

## 2.1.2 Power Supply Voltage Specification

Table 2 provides the recommended operating conditions for the MPC8313E. Note that the values in Table 2 are the recommended and tested operating conditions. If a particular block is given a voltage falling within the range in the Recommended Value column, the MPC8313E is capable of delivering the amount of current listed in the Current Requirement column; this is the maximum current possible. Proper device operation outside of these conditions is not guaranteed.

Table 2. Recommended Operating Conditions

| Characteristic                                    | Symbol            | Recommended Value <sup>1</sup>                                             | Unit | Current Requirement |
|---------------------------------------------------|-------------------|----------------------------------------------------------------------------|------|---------------------|
| Core supply voltage                               | V <sub>DD</sub>   | 1.0 V ± 50 mV                                                              | V    | 469 mA              |
| Internal core logic constant power                | V <sub>DDC</sub>  | 1.0 V ± 50 mV                                                              | V    | 377 mA              |
| SerDes internal digital power                     | XCOREVDD          | 1.0                                                                        | V    | 170 mA              |
| SerDes internal digital ground                    | XCOREVSS          | 0.0                                                                        | V    | —                   |
| SerDes I/O digital power                          | XPADVDD           | 1.0                                                                        | V    | 10 mA               |
| SerDes I/O digital ground                         | XPADVSS           | 0.0                                                                        | V    | —                   |
| SerDes analog power for PLL                       | SDAVDD            | 1.0 V ± 50 mV                                                              | V    | 10 mA               |
| SerDes analog ground for PLL                      | SDAVSS            | 0.0                                                                        | V    | —                   |
| Dedicated 3.3 V analog power for USB PLL          | USB_PLL_PWR3      | 3.3 V ± 300 mV                                                             | V    | 2–3 mA              |
| Dedicated 1.0 V analog power for USB PLL          | USB_PLL_PWR1      | 1.0 V ± 50 mV                                                              | V    | 2–3 mA              |
| Dedicated analog ground for USB PLL               | USB_PLL_GND       | 0.0                                                                        | V    | —                   |
| Dedicated USB power for USB Bias circuit          | USB_VDDA_BIAS     | 3.3 V ± 300 mV                                                             | V    | 4–5 mA              |
| Dedicated USB ground for USB Bias circuit         | USB_VSSA_BIAS     | 0.0                                                                        | V    | —                   |
| Dedicated power for USB Transceiver               | USB_VDDA          | 3.3 V ± 300 mV                                                             | V    | 75 mA               |
| Dedicated ground for USB transceiver              | USB_VSSA          | 0.0                                                                        | V    | —                   |
| Analog power for e300 core APLL                   | AV <sub>DD1</sub> | 1.0 V ± 50 mV                                                              | V    | 2–3 mA              |
| Analog power for system APLL                      | AV <sub>DD2</sub> | 1.0 V ± 50 mV                                                              | V    | 2–3 mA              |
| DDR1 DRAM I/O voltage (333 MHz, 32-bit operation) | GV <sub>DD</sub>  | 2.5 V ± 125 mV                                                             | V    | 131 mA              |
| DDR2 DRAM I/O voltage (333 MHz, 32-bit operation) | GV <sub>DD</sub>  | 1.8 V ± 80 mV                                                              | V    | 140 mA              |
| Differential reference voltage for DDR controller | MV <sub>REF</sub> | 1/2 DDR Supply<br>(0.49 × GV <sub>DD</sub> to<br>0.51 × GV <sub>DD</sub> ) | V    | —                   |
| Standard I/O voltage                              | NV <sub>DD</sub>  | 3.3 V ± 300 mV <sup>2</sup>                                                | V    | 74 mA               |
| eTSEC2 IO supply                                  | LV <sub>DDA</sub> | 2.5 V ± 125 mV/3.3 V<br>± 300 mV                                           | V    | 22 mA               |
| eTSEC1/USB DR IO supply                           | LV <sub>ddb</sub> | 2.5 V ± 125 mV/3.3 V<br>± 300 mV                                           | V    | 44 mA               |
| Supply for eLBC IOs                               | LV <sub>DD</sub>  | 3.3 V ± 300 mV                                                             | V    | 16 mA               |
| Analog and digital ground                         | VSS               | 0.0                                                                        | V    | —                   |
| Junction temperature                              | T <sub>J</sub>    | 0 to 105                                                                   | °C   | —                   |

<sup>1</sup> GV<sub>DD</sub>, NV<sub>DD</sub>, AV<sub>DD</sub>, and V<sub>DD</sub> must track each other and must vary in the same direction—either in the positive or negative direction.

<sup>2</sup> Some GPIO pins may operate from a 2.5-V supply when configured for other functions.

### 2.1.3 Output Driver Characteristics

Table 3 provides information on the characteristics of the output driver strengths. The values are preliminary estimates.

**Table 3. Output Drive Capability**

| Driver Type                                        | Output Impedance ( $\Omega$ ) | Supply Voltage                                    |
|----------------------------------------------------|-------------------------------|---------------------------------------------------|
| Local bus interface utilities signals              | 42                            | NV <sub>DD</sub> = 3.3 V                          |
| PCI signals                                        | 25                            |                                                   |
| DDR signal                                         | 18                            | GV <sub>DD</sub> = 2.5 V                          |
| DDR2 signal                                        | 18                            | GV <sub>DD</sub> = 1.8 V                          |
| DUART, system control, I <sup>2</sup> C, JTAG, SPI | 42                            | NV <sub>DD</sub> = 3.3 V                          |
| GPIO signals                                       | 42                            | NV <sub>DD</sub> = 3.3 V                          |
| eTSEC signals                                      | 42                            | LV <sub>DDA</sub> , LV <sub>ddb</sub> = 2.5/3.3 V |
| USB Signals                                        | 42                            | LV <sub>ddb</sub> = 2.5/3.3 V                     |

## 2.2 Power Sequencing

The MPC8313E does not require the core supply voltage (V<sub>DD</sub> and V<sub>DDC</sub>) and IO supply voltages (GV<sub>DD</sub>, LV<sub>DD</sub>, and OV<sub>DD</sub>) to be applied in any particular order. Note that during power ramp-up, before the power supplies are stable and if the I/O voltages are supplied before the core voltage, there might be a period of time that all input and output pins are actively driven and cause contention and excessive current. In order to avoid actively driving the I/O pins and to eliminate excessive current draw, apply the core voltage (V<sub>DD</sub> and V<sub>DDC</sub>) before the I/O voltage (GV<sub>DD</sub>, LV<sub>DD</sub>, and OV<sub>DD</sub>) and assert PORESET before the power supplies fully ramp up. In the case where the core voltage is applied first, the core voltage supply must rise to 90% of its nominal value before the I/O supplies reach 0.7 V; see Figure 2. Once both the power supplies (I/O voltage and core voltage) are stable, wait for a minimum of 32 clock cycles before negating PORESET.

Note that there is no specific power down sequence requirement for the MPC8313E. I/O voltage supplies (GV<sub>DD</sub>, LV<sub>DD</sub>, and OV<sub>DD</sub>) do not have any ordering requirements with respect to one another.

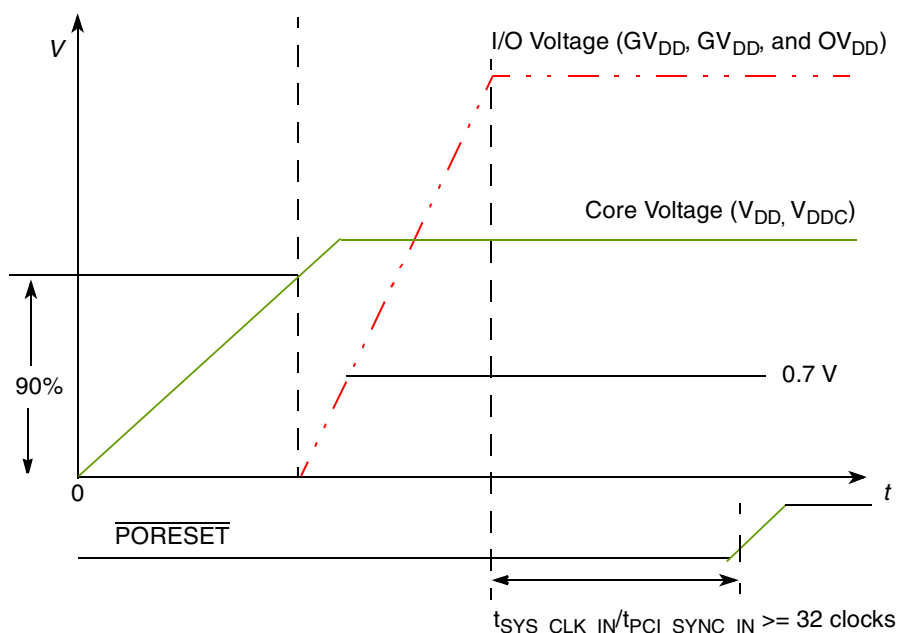


Figure 2. Power-Up Sequencing Example

### 3 Power Characteristics

The estimated typical power dissipation, not including I/O supply power, for this family of MPC8313E devices is shown in Table 4, and Table 5 shows the estimated typical I/O power dissipation.

Table 4. MPC8313E Power Dissipation<sup>1</sup>

| Core Frequency (MHz) | CSB Frequency (MHz) | Typical <sup>2, 3</sup> | Maximum <sup>4, 3</sup> | Unit |
|----------------------|---------------------|-------------------------|-------------------------|------|
| 333                  | 167                 | 820                     | 1020                    | mW   |

<sup>1</sup> The values do not include I/O supply power or  $AV_{dd}$  but do include core, USB PLL, and a portion of SerDes digital power (not including XCOREVDD, XPADVDD, or SDAVDD, which all have dedicated power supplies for the SerDes PHY).

<sup>2</sup> Typical power is based on a voltage of  $V_{dd} = 1.05$  V and an artificial smoker test running at room temperature.

<sup>3</sup> These are preliminary estimates.

<sup>4</sup> Maximum power is based on a voltage of  $V_{dd} = 1.05$  V, a junction temperature of  $T_j = 105^\circ$  C, and an artificial smoker test.

Table 5 describes a typical scenario where blocks with the stated percentage of utilization and impedances consume the amount of power described.

**Table 5. MPC8313E Typical I/O Power Dissipation**

| Interface                                                                                                                                                                  | Parameter        | GV <sub>DD</sub><br>(1.8 V) | GV <sub>DD</sub><br>(2.5 V) | NV <sub>DD</sub><br>(3.3 V) | LV <sub>DDA</sub> /LV <sub>ddb</sub><br>(3.3 V) | LV <sub>DDA</sub> /LV <sub>ddb</sub><br>(2.5 V) | LV <sub>DD</sub><br>(3.3 V) | Unit | Comments                                      |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------|-----------------------------|-----------------------------|-----------------------------|-------------------------------------------------|-------------------------------------------------|-----------------------------|------|-----------------------------------------------|
| DDR 1, 60% utilization,<br>50% read/write<br>Rs = 22 Ω<br>Rt = 50 Ω<br>single pair of clock<br>Capacitive Load:<br>Data = 8pF, Control<br>Address = 8pF,<br>Clock = 8pF    | 333 MHz, 32 bits | —                           | 0.355                       | —                           | —                                               | —                                               | —                           | W    | —                                             |
|                                                                                                                                                                            | 266 MHz, 32 bits | —                           | 0.323                       | —                           | —                                               | —                                               | —                           | W    | —                                             |
| DDR 2, 60%<br>utilization, 50%<br>read/write<br>Rs = 22 Ω<br>Rt = 75 Ω<br>single pair of clock<br>Capacitive Load:<br>Data = 8pF, Control<br>Address = 8pF,<br>Clock = 8pF | 333 MHz, 32 bits | 0.266                       | —                           | —                           | —                                               | —                                               | —                           | W    | —                                             |
|                                                                                                                                                                            | 266 MHz, 32 bits | 0.246                       | —                           | —                           | —                                               | —                                               | —                           | W    | —                                             |
| PCI I/O load = 50pF                                                                                                                                                        | 33 MHz           | —                           | —                           | 0.120                       | —                                               | —                                               | —                           | W    | —                                             |
|                                                                                                                                                                            | 66 MHz           | —                           | —                           | 0.249                       | —                                               | —                                               | —                           | W    | —                                             |
| Local bus I/O<br>load = 20pF                                                                                                                                               | 66 MHz           | —                           | —                           | —                           | —                                               | —                                               | 0.056                       | W    | —                                             |
|                                                                                                                                                                            | 50 MHz           | —                           | —                           | —                           | —                                               | —                                               | 0.040                       | W    | —                                             |
| TSEC I/O load = 20pF                                                                                                                                                       | MII, 25 MHz      | —                           | —                           | —                           | 0.008                                           | —                                               | —                           | W    | Multiple by<br>number of<br>interface<br>used |
|                                                                                                                                                                            | RGMII, 125 MHz   | —                           | —                           | —                           | 0.078                                           | 0.044                                           | —                           | W    |                                               |
| USBDR controller<br>load = 20pF                                                                                                                                            | 60 MHz           | —                           | —                           | —                           | 0.078                                           | —                                               | —                           | W    | —                                             |
| Other I/O                                                                                                                                                                  | —                | —                           | —                           | 0.015                       | —                                               | —                                               | —                           | W    | —                                             |

Table 6 shows the estimated core power dissipation of the MPC8313E while transitioning into the D3warm low power state.

**Table 6. MPC8313E Low Power Modes Power Dissipation <sup>1</sup>,**

| 333-MHz core, 167-MHz CSB <sup>2</sup> | Maximum <sup>3</sup> | Unit |
|----------------------------------------|----------------------|------|
| D3 warm                                | 400                  | mW   |

<sup>1</sup> All interfaces are enabled. For further power savings, disable the clocks to unused blocks.

<sup>2</sup> The interfaces are run at the following frequencies: DDR: 167 MHz, eLBC 167 MHz, PCI 33 MHz, eTSEC1 and 2: 167 MHz, SEC: 167 MHz, USB: 167 MHz. See the SCCR register for more information.

<sup>3</sup> Maximum power is based on a voltage of 1.05 V and a junction temperature of 105° C.

## 4 Clock Input Timing

This section provides the clock input DC and AC electrical characteristics for the MPC8313E.

### 4.1 DC Electrical Characteristics

Table 7 provides the system clock input (SYS\_CLK\_IN/PCI\_SYNC\_IN) DC timing specifications for the MPC8313E.

**Table 7. SYS\_CLK\_IN DC Electrical Characteristics**

| Parameter                 | Condition                                                                                             | Symbol   | Min  | Max             | Unit          |
|---------------------------|-------------------------------------------------------------------------------------------------------|----------|------|-----------------|---------------|
| Input high voltage        | —                                                                                                     | $V_{IH}$ | 2.7  | $NV_{DD} + 0.3$ | V             |
| Input low voltage         | —                                                                                                     | $V_{IL}$ | -0.3 | 0.4             | V             |
| SYS_CLK_IN Input current  | $0\text{ V} \leq V_{IN} \leq NV_{DD}$                                                                 | $I_{IN}$ | —    | $\pm 10$        | $\mu\text{A}$ |
| PCI_SYNC_IN Input current | $0\text{ V} \leq V_{IN} \leq 0.5\text{ V}$<br>or<br>$NV_{DD} - 0.5\text{ V} \leq V_{IN} \leq NV_{DD}$ | $I_{IN}$ | —    | $\pm 10$        | $\mu\text{A}$ |
| PCI_SYNC_IN Input current | $0.5\text{ V} \leq V_{IN} \leq NV_{DD} - 0.5\text{ V}$                                                | $I_{IN}$ | —    | $\pm 50$        | $\mu\text{A}$ |

### 4.2 AC Electrical Characteristics

The primary clock source for the MPC8313E can be one of two inputs, SYS\_CLK\_IN or PCI\_CLK, depending on whether the device is configured in PCI host or PCI agent mode. Table 8 provides the system clock input (SYS\_CLK\_IN/PCI\_CLK) AC timing specifications for the MPC8313E.

**Table 8. SYS\_CLK\_IN AC Timing Specifications**

| Parameter/Condition           | Symbol                    | Min | Typical | Max   | Unit | Notes |
|-------------------------------|---------------------------|-----|---------|-------|------|-------|
| SYS_CLK_IN/PCI_CLK frequency  | $f_{\text{SYS\_CLK\_IN}}$ | 24  | —       | 66.67 | MHz  | 1     |
| SYS_CLK_IN/PCI_CLK cycle time | $t_{\text{SYS\_CLK\_IN}}$ | 15  | —       | —     | ns   | —     |

Table 8. SYS\_CLK\_IN AC Timing Specifications (continued)

|                                       |                            |     |     |      |    |      |
|---------------------------------------|----------------------------|-----|-----|------|----|------|
| SYS_CLK_IN/PCI_CLK rise and fall time | $t_{KH}, t_{KL}$           | 0.6 | 0.8 | 1.2  | ns | 2    |
| SYS_CLK_IN/PCI_CLK duty cycle         | $t_{KHK}/t_{SYS\_CLK\_IN}$ | 40  | —   | 60   | %  | 3    |
| SYS_CLK_IN/PCI_CLK jitter             | —                          | —   | —   | ±150 | ps | 4, 5 |

**Notes:**

1. **Caution:** The system, core, security block must not exceed their respective maximum or minimum operating frequencies.
2. Rise and fall times for SYS\_CLK\_IN/PCI\_CLK are measured at 0.4 V and 2.7 V.
3. Timing is guaranteed by design and characterization.
4. This represents the total input jitter—short term and long term—and is guaranteed by design.
5. The SYS\_CLK\_IN/PCI\_CLK driver's closed loop jitter bandwidth should be < 500 kHz at –20 dB. The bandwidth must be set low to allow cascade-connected PLL-based devices to track SYS\_CLK\_IN drivers with the specified jitter.

## 5 RESET Initialization

This section describes the DC and AC electrical specifications for the reset initialization timing and electrical requirements of the MPC8313E.

### 5.1 RESET DC Electrical Characteristics

Table 9 provides the DC electrical characteristics for the RESET pins.

Table 9. RESET Pins DC Electrical Characteristics

| Characteristic      | Symbol   | Condition                             | Min  | Max             | Unit |
|---------------------|----------|---------------------------------------|------|-----------------|------|
| Input high voltage  | $V_{IH}$ | —                                     | 2.1  | $NV_{DD} + 0.3$ | V    |
| Input low voltage   | $V_{IL}$ | —                                     | –0.3 | 0.8             | V    |
| Input current       | $I_{IN}$ | $0\text{ V} \leq V_{IN} \leq NV_{DD}$ |      | ±5              | μA   |
| Output high voltage | $V_{OH}$ | $I_{OH} = -8.0\text{ mA}$             | 2.4  | —               | V    |
| Output low voltage  | $V_{OL}$ | $I_{OL} = 8.0\text{ mA}$              | —    | 0.5             | V    |
| Output low voltage  | $V_{OL}$ | $I_{OL} = 3.2\text{ mA}$              | —    | 0.4             | V    |

### 5.2 RESET AC Electrical Characteristics

Table 10 provides the reset initialization AC timing specifications.

Table 10. RESET Initialization Timing Specifications

| Parameter/Condition                                                                                                                     | Min | Max | Unit                | Notes |
|-----------------------------------------------------------------------------------------------------------------------------------------|-----|-----|---------------------|-------|
| Required assertion time of $\overline{HRESET}$ or $\overline{SRESET}$ (input) to activate reset flow                                    | 32  | —   | $t_{PCI\_SYNC\_IN}$ | 1     |
| Required assertion time of $\overline{PORESET}$ with stable clock and power applied to SYS_CLK_IN when the device is in PCI host mode   | 32  | —   | $t_{SYS\_CLK\_IN}$  | 2     |
| Required assertion time of $\overline{PORESET}$ with stable clock and power applied to PCI_SYNC_IN when the device is in PCI agent mode | 32  | —   | $t_{PCI\_SYNC\_IN}$ | 1     |

**Table 10. RESET Initialization Timing Specifications (continued)**

|                                                                                                                                                                                            |     |   |                            |      |
|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----|---|----------------------------|------|
| $\overline{\text{HRESET}}$ / $\overline{\text{SRESET}}$ assertion (output)                                                                                                                 | 512 | — | $t_{\text{PCI\_SYNC\_IN}}$ | 1    |
| $\overline{\text{HRESET}}$ negation to $\overline{\text{SRESET}}$ negation (output)                                                                                                        | 16  | — | $t_{\text{PCI\_SYNC\_IN}}$ | 1    |
| Input setup time for POR configuration signals (CFG_RESET_SOURCE[0:3] and CFG_SYS_CLK_IN_DIV ) with respect to negation of $\overline{\text{PORESET}}$ when the device is in PCI host mode | 4   | — | $t_{\text{SYS\_CLK\_IN}}$  | 2    |
| Input setup time for POR configuration signals (CFG_RESET_SOURCE[0:2] and CFG_CLKIN_DIV) with respect to negation of $\overline{\text{PORESET}}$ when the device is in PCI agent mode      | 4   | — | $t_{\text{PCI\_SYNC\_IN}}$ | 1    |
| Input hold time for POR configuration signals with respect to negation of $\overline{\text{HRESET}}$                                                                                       | 0   | — | ns                         | —    |
| Time for the device to turn off POR configuration signals with respect to the assertion of $\overline{\text{HRESET}}$                                                                      | —   | 4 | ns                         | 3    |
| Time for the device to turn on POR configuration signals with respect to the negation of $\overline{\text{HRESET}}$                                                                        | 1   | — | $t_{\text{PCI\_SYNC\_IN}}$ | 1, 3 |

**Notes:**

1.  $t_{\text{PCI\_SYNC\_IN}}$  is the clock period of the input clock applied to PCI\_SYNC\_IN. When the device is in PCI host mode the primary clock is applied to the SYS\_CLK\_IN input, and PCI\_SYNC\_IN period depends on the value of CFG\_CLKIN\_DIV.
2.  $t_{\text{SYS\_CLK\_IN}}$  is the clock period of the input clock applied to SYS\_CLK\_IN. It is only valid when the device is in PCI host mode.
3. POR configuration signals consists of CFG\_RESET\_SOURCE[0:2] and CFG\_CLKIN\_DIV.

Table 11 provides the PLL lock times.

**Table 11. PLL Lock Times**

| Parameter/Condition | Min | Max | Unit          | Notes |
|---------------------|-----|-----|---------------|-------|
| PLL lock times      | —   | 100 | $\mu\text{s}$ | —     |

## 6 DDR and DDR2 SDRAM

This section describes the DC and AC electrical specifications for the DDR SDRAM interface. Note that DDR SDRAM is  $\text{GV}_{\text{DD}}(\text{typ}) = 2.5 \text{ V}$  and DDR2 SDRAM is  $\text{GV}_{\text{DD}}(\text{typ}) = 1.8 \text{ V}$ .

### 6.1 DDR and DDR2 SDRAM DC Electrical Characteristics

Table 12 provides the recommended operating conditions for the DDR2 SDRAM component(s) when  $\text{GV}_{\text{DD}}(\text{typ}) = 1.8 \text{ V}$ .

**Table 12. DDR2 SDRAM DC Electrical Characteristics for  $\text{GV}_{\text{DD}}(\text{typ}) = 1.8 \text{ V}$** 

| Parameter/Condition     | Symbol                   | Min                                 | Max                                 | Unit | Notes |
|-------------------------|--------------------------|-------------------------------------|-------------------------------------|------|-------|
| I/O supply voltage      | $\text{GV}_{\text{DD}}$  | 1.7                                 | 1.9                                 | V    | 1     |
| I/O reference voltage   | $\text{MV}_{\text{REF}}$ | $0.49 \times \text{GV}_{\text{DD}}$ | $0.51 \times \text{GV}_{\text{DD}}$ | V    | 2     |
| I/O termination voltage | $\text{V}_{\text{TT}}$   | $\text{MV}_{\text{REF}} - 0.04$     | $\text{MV}_{\text{REF}} + 0.04$     | V    | 3     |
| Input high voltage      | $\text{V}_{\text{IH}}$   | $\text{MV}_{\text{REF}} + 0.125$    | $\text{GV}_{\text{DD}} + 0.3$       | V    | —     |

**Table 12. DDR2 SDRAM DC Electrical Characteristics for  $GV_{DD}(typ) = 1.8\text{ V}$** 

|                                                    |          |       |                    |               |   |
|----------------------------------------------------|----------|-------|--------------------|---------------|---|
| Input low voltage                                  | $V_{IL}$ | -0.3  | $MV_{REF} - 0.125$ | V             | — |
| Output leakage current                             | $I_{OZ}$ | -9.9  | 9.9                | $\mu\text{A}$ | 4 |
| Output high current ( $V_{OUT} = 1.420\text{ V}$ ) | $I_{OH}$ | -13.4 | —                  | mA            | — |
| Output low current ( $V_{OUT} = 0.280\text{ V}$ )  | $I_{OL}$ | 13.4  | —                  | mA            | — |

**Notes:**

1.  $GV_{DD}$  is expected to be within 50 mV of the DRAM  $GV_{DD}$  at all times.
2.  $MV_{REF}$  is expected to be equal to  $0.5 \times GV_{DD}$ , and to track  $GV_{DD}$  DC variations as measured at the receiver. Peak-to-peak noise on  $MV_{REF}$  may not exceed  $\pm 2\%$  of the DC value.
3.  $V_{TT}$  is not applied directly to the device. It is the supply to which far end signal termination is made and is expected to be equal to  $MV_{REF}$ . This rail should track variations in the DC level of  $MV_{REF}$ .
4. Output leakage is measured with all outputs disabled,  $0\text{ V} \leq V_{OUT} \leq GV_{DD}$ .

Table 13 provides the DDR2 capacitance when  $GV_{DD}(typ) = 1.8\text{ V}$ .

**Table 13. DDR2 SDRAM Capacitance for  $GV_{DD}(typ)=1.8\text{ V}$** 

| Parameter/Condition                                       | Symbol    | Min | Max | Unit | Notes |
|-----------------------------------------------------------|-----------|-----|-----|------|-------|
| Input/output capacitance: DQ, DQS, $\overline{DQS}$       | $C_{IO}$  | 6   | 8   | pF   | 1     |
| Delta input/output capacitance: DQ, DQS, $\overline{DQS}$ | $C_{DIO}$ | —   | 0.5 | pF   | 1     |

**Note:**

1. This parameter is sampled.  $GV_{DD} = 1.8\text{ V} \pm 0.090\text{ V}$ ,  $f = 1\text{ MHz}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{OUT} = GV_{DD}/2$ ,  $V_{OUT}$  (peak-to-peak) = 0.2 V.

Table 14 provides the recommended operating conditions for the DDR SDRAM component(s) when  $GV_{DD}(typ) = 2.5\text{ V}$ .

**Table 14. DDR SDRAM DC Electrical Characteristics for  $GV_{DD}(typ) = 2.5\text{ V}$** 

| Parameter/Condition                               | Symbol     | Min                   | Max                   | Unit          | Notes |
|---------------------------------------------------|------------|-----------------------|-----------------------|---------------|-------|
| I/O supply voltage                                | $GV_{DD}$  | 2.3                   | 2.7                   | V             | 1     |
| I/O reference voltage                             | $MV_{REF}$ | $0.49 \times GV_{DD}$ | $0.51 \times GV_{DD}$ | V             | 2     |
| I/O termination voltage                           | $V_{TT}$   | $MV_{REF} - 0.04$     | $MV_{REF} + 0.04$     | V             | 3     |
| Input high voltage                                | $V_{IH}$   | $MV_{REF} + 0.15$     | $GV_{DD} + 0.3$       | V             | —     |
| Input low voltage                                 | $V_{IL}$   | -0.3                  | $MV_{REF} - 0.15$     | V             | —     |
| Output leakage current                            | $I_{OZ}$   | -9.9                  | -9.9                  | $\mu\text{A}$ | 4     |
| Output high current ( $V_{OUT} = 1.95\text{ V}$ ) | $I_{OH}$   | -16.2                 | —                     | mA            | —     |
| Output low current ( $V_{OUT} = 0.35\text{ V}$ )  | $I_{OL}$   | 16.2                  | —                     | mA            | —     |

**Notes:**

1.  $GV_{DD}$  is expected to be within 50 mV of the DRAM  $GV_{DD}$  at all times.
2.  $MV_{REF}$  is expected to be equal to  $0.5 \times GV_{DD}$ , and to track  $GV_{DD}$  DC variations as measured at the receiver. Peak-to-peak noise on  $MV_{REF}$  may not exceed  $\pm 2\%$  of the DC value.
3.  $V_{TT}$  is not applied directly to the device. It is the supply to which far end signal termination is made and is expected to be equal to  $MV_{REF}$ . This rail should track variations in the DC level of  $MV_{REF}$ .
4. Output leakage is measured with all outputs disabled,  $0\text{ V} \leq V_{OUT} \leq GV_{DD}$ .

Table 15 provides the DDR capacitance when  $GV_{DD}(\text{typ})=2.5\text{ V}$ .

**Table 15. DDR SDRAM Capacitance for  $GV_{DD}(\text{typ}) = 2.5\text{ V}$**

| Parameter/Condition                     | Symbol    | Min | Max | Unit | Notes |
|-----------------------------------------|-----------|-----|-----|------|-------|
| Input/output capacitance: DQ, DQS       | $C_{IO}$  | 6   | 8   | pF   | 1     |
| Delta input/output capacitance: DQ, DQS | $C_{DIO}$ | —   | 0.5 | pF   | 1     |

**Note:**

1. This parameter is sampled.  $GV_{DD} = 2.5\text{ V} \pm 0.125\text{ V}$ ,  $f = 1\text{ MHz}$ ,  $T_A = 25^\circ\text{C}$ ,  $V_{OUT} = GV_{DD}/2$ ,  $V_{OUT}$  (peak-to-peak) = 0.2 V.

Table 16 provides the current draw characteristics for  $MV_{REF}$ .

**Table 16. Current Draw Characteristics for  $MV_{REF}$**

| Parameter / Condition       | Symbol      | Min | Max | Unit          | Note |
|-----------------------------|-------------|-----|-----|---------------|------|
| Current draw for $MV_{REF}$ | $I_{MVREF}$ | —   | 500 | $\mu\text{A}$ | 1    |

1. The voltage regulator for  $MV_{REF}$  must be able to supply up to 500  $\mu\text{A}$  current.

## 6.2 DDR and DDR2 SDRAM AC Electrical Characteristics

This section provides the AC electrical characteristics for the DDR SDRAM interface.

### 6.2.1 DDR and DDR2 SDRAM Input AC Timing Specifications

Table 17 provides the input AC timing specifications for the DDR2 SDRAM when  $GV_{DD}(\text{typ})=1.8\text{ V}$ .

**Table 17. DDR2 SDRAM Input AC Timing Specifications for 1.8-V Interface**

At recommended operating conditions with  $GV_{DD}$  of  $1.8 \pm 5\%$

| Parameter             | Symbol   | Min               | Max               | Unit | Notes |
|-----------------------|----------|-------------------|-------------------|------|-------|
| AC input low voltage  | $V_{IL}$ | —                 | $MV_{REF} - 0.25$ | V    | —     |
| AC input high voltage | $V_{IH}$ | $MV_{REF} + 0.25$ | —                 | V    | —     |

Table 18 provides the input AC timing specifications for the DDR SDRAM when  $GV_{DD}(\text{typ})=2.5\text{ V}$ .

**Table 18. DDR SDRAM Input AC Timing Specifications for 2.5-V Interface**

At recommended operating conditions with  $GV_{DD}$  of  $2.5 \pm 5\%$ .

| Parameter             | Symbol   | Min               | Max               | Unit | Notes |
|-----------------------|----------|-------------------|-------------------|------|-------|
| AC input low voltage  | $V_{IL}$ | —                 | $MV_{REF} - 0.31$ | V    | —     |
| AC input high voltage | $V_{IH}$ | $MV_{REF} + 0.31$ | —                 | V    | —     |

Table 19 provides the input AC timing specifications for the DDR2 SDRAM interface.

**Table 19. DDR and DDR2 SDRAM Input AC Timing Specifications**

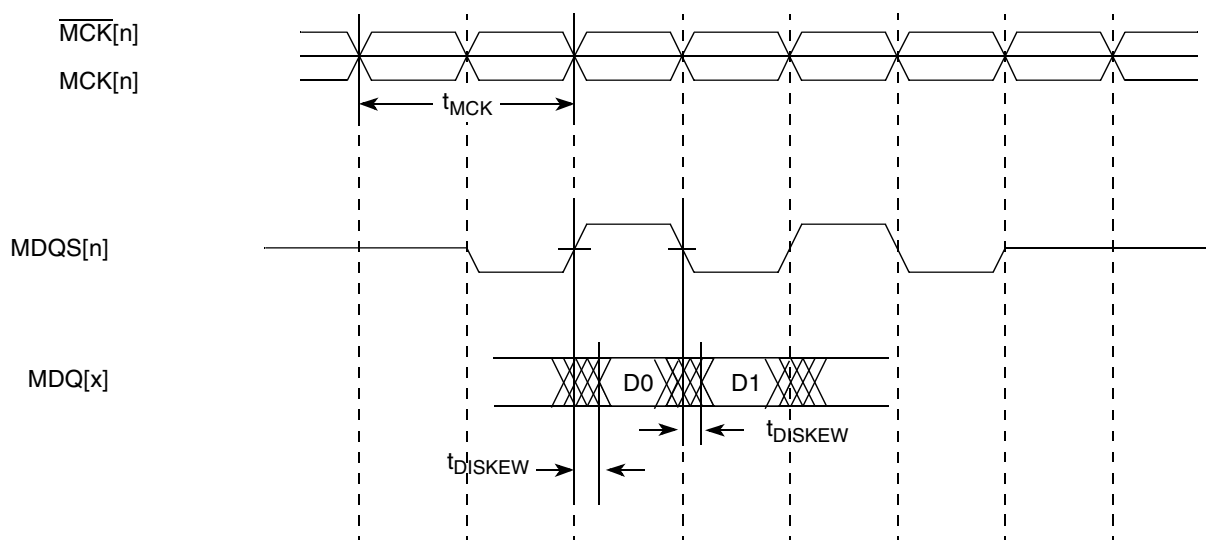
At recommended operating conditions, with  $GV_{DD}$  of  $2.5 \pm 5\%$

| Parameter                    | Symbol       | Min  | Max | Unit | Notes |
|------------------------------|--------------|------|-----|------|-------|
| Controller Skew for MDQS—MDQ | $t_{CISKEW}$ | —    | —   | ps   | 1, 2  |
| 333 MHz                      | —            | –750 | 750 | —    | —     |
| 266 MHz                      | —            | –750 | 750 | —    | —     |

**Note:**

1.  $t_{CISKEW}$  represents the total amount of skew consumed by the controller between MDQS[n] and any corresponding bit that is captured with MDQS[n]. This should be subtracted from the total timing budget.
2. The amount of skew that can be tolerated from MDQS to a corresponding MDQ signal is called  $t_{DISKEW}$ . This can be determined by the following equation:  $t_{DISKEW} = \pm(T/4 - \text{abs}(t_{CISKEW}))$  where T is the clock period and  $\text{abs}(t_{CISKEW})$  is the absolute value of  $t_{CISKEW}$ .

Figure 3 illustrates the DDR input timing diagram showing the  $t_{DISKEW}$  timing parameter.



**Figure 3. DDR Input Timing Diagram**

## 6.2.2 DDR and DDR2 SDRAM Output AC Timing Specifications

**Table 20. DDR and DDR2 SDRAM Output AC Timing Specifications**

At recommended operating conditions.

| Parameter                                                       | Symbol <sup>1</sup>                          | Min  | Max | Unit | Notes |
|-----------------------------------------------------------------|----------------------------------------------|------|-----|------|-------|
| MCK[n] cycle time, MCK[n]/ $\overline{\text{MCK}}$ [n] crossing | $t_{\text{MCK}}$                             | 6    | 10  | ns   | 2     |
| ADDR/CMD output setup with respect to MCK                       | $t_{\text{DDKHAS}}$                          |      |     | ns   | 3     |
| 333 MHz                                                         |                                              | 2.1  | —   |      |       |
| 266 MHz                                                         |                                              | 2.5  | —   |      |       |
| ADDR/CMD output hold with respect to MCK                        | $t_{\text{DDKHAX}}$                          |      |     | ns   | 3     |
| 333 MHz                                                         |                                              | 2.40 | —   |      |       |
| 266 MHz                                                         |                                              | 3.15 | —   |      |       |
| $\overline{\text{MCS}}$ [n] output setup with respect to MCK    | $t_{\text{DDKHCS}}$                          |      |     | ns   | 3     |
| 333 MHz                                                         |                                              | 2.40 | —   |      |       |
| 266 MHz                                                         |                                              | 3.15 | —   |      |       |
| $\overline{\text{MCS}}$ [n] output hold with respect to MCK     | $t_{\text{DDKHCX}}$                          |      |     | ns   | 3     |
| 333 MHz                                                         |                                              | 2.40 | —   |      |       |
| 266 MHz                                                         |                                              | 3.15 | —   |      |       |
| MCK to MDQS Skew                                                | $t_{\text{DDKMHM}}$                          | −0.6 | 0.6 | ns   | 4     |
| MDQ//MDM output setup with respect to MDQS                      | $t_{\text{DDKHDS}}$ ,<br>$t_{\text{DDKLDS}}$ |      |     | ps   | 5     |
| 333 MHz                                                         |                                              | 800  | —   |      |       |
| 266 MHz                                                         |                                              | 900  | —   |      |       |
| MDQ//MDM output hold with respect to MDQS                       | $t_{\text{DDKHDX}}$ ,<br>$t_{\text{DDKLDX}}$ |      |     | ps   | 5     |
| 333 MHz                                                         |                                              | 900  | —   |      |       |
| 266 MHz                                                         |                                              | 1100 | —   |      |       |

**Table 20. DDR and DDR2 SDRAM Output AC Timing Specifications (continued)**

At recommended operating conditions.

| Parameter           | Symbol <sup>1</sup> | Min                         | Max                         | Unit | Notes |
|---------------------|---------------------|-----------------------------|-----------------------------|------|-------|
| MDQS preamble start | $t_{DDKHMP}$        | $-0.5 \times t_{MCK} - 0.6$ | $-0.5 \times t_{MCK} + 0.6$ | ns   | 6     |
| MDQS epilogue end   | $t_{DDKHME}$        | -0.6                        | 0.6                         | ns   | 6     |

**Note:**

1. The symbols used for timing specifications follow the pattern of  $t_{(\text{first two letters of functional block})(\text{signal})(\text{state})(\text{reference})(\text{state})}$  for inputs and  $t_{(\text{first two letters of functional block})(\text{reference})(\text{state})(\text{signal})(\text{state})}$  for outputs. Output hold time can be read as DDR timing (DD) from the rising or falling edge of the reference clock (KH or KL) until the output went invalid (AX or DX). For example,  $t_{DDKHAS}$  symbolizes DDR timing (DD) for the time  $t_{MCK}$  memory clock reference (K) goes from the high (H) state until outputs (A) are setup (S) or output valid time. Also,  $t_{DDKLDX}$  symbolizes DDR timing (DD) for the time  $t_{MCK}$  memory clock reference (K) goes low (L) until data outputs (D) are invalid (X) or data output hold time.
2. All MCK/MCK referenced measurements are made from the crossing of the two signals  $\pm 0.1$  V.
3. ADDR/CMD includes all DDR SDRAM output signals except MCK/MCK, MCS, and MDQ/MDM/MDQS.
4. Note that  $t_{DDKMH}$  follows the symbol conventions described in note 1. For example,  $t_{DDKMH}$  describes the DDR timing (DD) from the rising edge of the MCK[n] clock (KH) until the MDQS signal is valid (MH).  $t_{DDKMH}$  can be modified through control of the DQSS override bits in the TIMING\_CFG\_2 register. This is typically set to the same delay as the clock adjust in the CLK\_CNTL register. The timing parameters listed in the table assume that these 2 parameters have been set to the same adjustment value. See the *MPC8313E PowerQUICC™ II Pro Host Processor Reference Manual* for a description and understanding of the timing modifications enabled by use of these bits.
5. Determined by maximum possible skew between a data strobe (MDQS) and any corresponding bit of data (MDQ), ECC (MECC), or data mask (MDM). The data strobe should be centered inside of the data eye at the pins of the microprocessor.
6. All outputs are referenced to the rising edge of MCK[n] at the pins of the microprocessor. Note that  $t_{DDKHMP}$  follows the symbol conventions described in note 1.

**NOTE**

For the ADDR/CMD setup and hold specifications in [Table 20](#), it is assumed that the clock control register is set to adjust the memory clocks by 1/2 applied cycle.

[Figure 4](#) shows the DDR SDRAM output timing for the MCK to MDQS skew measurement ( $t_{DDKMH}$ ).

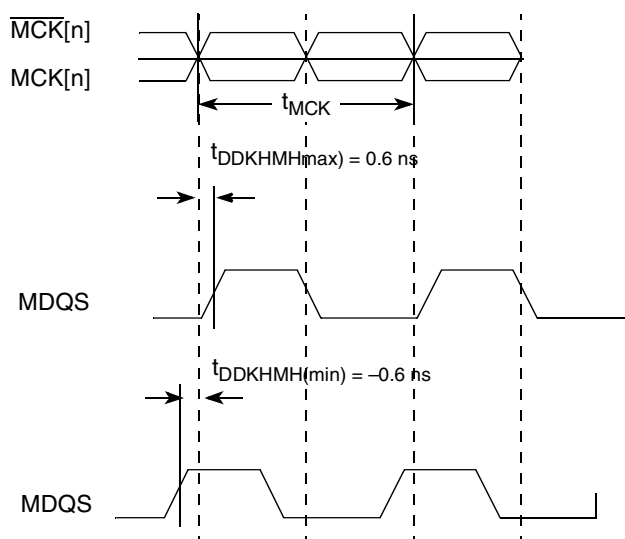
**Figure 4. Timing Diagram for  $t_{DDKMH}$**

Figure 5 shows the DDR and DDR2 SDRAM output timing diagram.

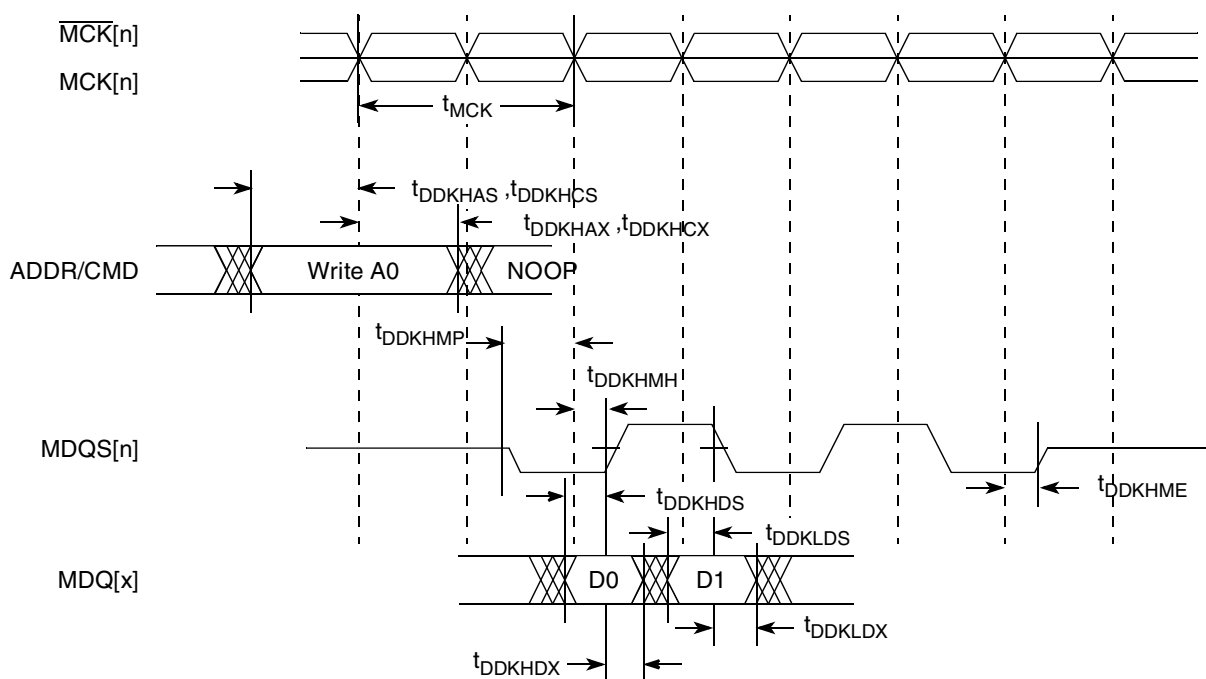


Figure 5. DDR and DDR2 SDRAM Output Timing Diagram

Figure 6 provides the AC test load for the DDR bus.

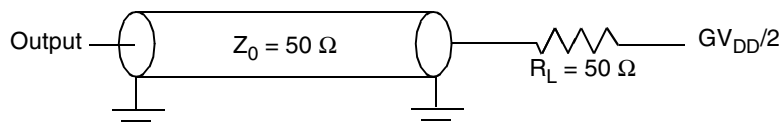


Figure 6. DDR AC Test Load

## 7 DUART

This section describes the DC and AC electrical specifications for the DUART interface.

### 7.1 DUART DC Electrical Characteristics

Table 21 provides the DC electrical characteristics for the DUART interface.

**Table 21. DUART DC Electrical Characteristics**

| Parameter                                         | Symbol   | Min             | Max             | Unit    |
|---------------------------------------------------|----------|-----------------|-----------------|---------|
| High-level input voltage                          | $V_{IH}$ | 2.0             | $NV_{DD} + 0.3$ | V       |
| Low-level input voltage $NV_{DD}$                 | $V_{IL}$ | -0.3            | 0.8             | V       |
| High-level output voltage, $I_{OH} = -100\ \mu A$ | $V_{OH}$ | $NV_{DD} - 0.2$ | —               | V       |
| Low-level output voltage, $I_{OL} = 100\ \mu A$   | $V_{OL}$ | —               | 0.2             | V       |
| Input current ( $0\ V \leq V_{IN} \leq NV_{DD}$ ) | $I_{IN}$ | —               | $\pm 5$         | $\mu A$ |

### 7.2 DUART AC Electrical Specifications

Table 22 provides the AC timing parameters for the DUART interface.

**Table 22. DUART AC Timing Specifications**

| Parameter         | Value       | Unit | Notes |
|-------------------|-------------|------|-------|
| Minimum baud rate | 256         | baud | —     |
| Maximum baud rate | > 1,000,000 | baud | 1     |
| Oversample rate   | 16          | —    | 2     |

**Notes:**

1. Actual attainable baud rate is limited by the latency of interrupt processing.
2. The middle of a start bit is detected as the 8<sup>th</sup> sampled 0 after the 1-to-0 transition of the start bit. Subsequent bit values are sampled each 16<sup>th</sup> sample.

## 8 Ethernet: Three-Speed Ethernet, MII Management

This section provides the AC and DC electrical characteristics for three-speed, 10/100/1000, and MII management.

### 8.1 Enhanced Three-Speed Ethernet Controller (eTSEC) (10/100/1000 Mbps)—MII/RMII/RGMII/SGMII/RTBI Electrical Characteristics

The electrical characteristics specified here apply to all the media independent interface (MII), reduced gigabit media independent interface (RGMII), serial gigabit media independent interface (SGMII), and reduced ten-bit interface (RTBI) signals except management data input/output (MDIO) and management data clock (MDC). The MII interface is defined for 3.3 V, while the RMII, RGMII, SGMII, and RTBI

interfaces can be operated at 3.3 V or 2.5 V. The RGMII and RTBI interfaces follow the Hewlett-Packard reduced pin-count interface for Gigabit Ethernet Physical Layer Device Specification Version 1.2a (9/22/2000). The electrical characteristics for MDIO and MDC are specified in [Section 8.4, “Ethernet Management Interface Electrical Characteristics.”](#)

### 8.1.1 TSEC DC Electrical Characteristics

All RGMII, SGMII, RMII, and RTBI drivers and receivers comply with the DC parametric attributes specified in [Table 23](#) and [Table 24](#). The potential applied to the input of a MII, RGMII, SGMII, or RTBI receiver may exceed the potential of the receiver’s power supply (that is, a RGMII driver powered from a 3.6-V supply driving  $V_{OH}$  into a RGMII receiver powered from a 2.5-V supply). Tolerance for dissimilar RGMII driver and receiver supply potentials is implicit in these specifications. The RGMII and RTBI signals are based on a 2.5-V CMOS interface voltage as defined by JEDEC EIA/JESD8-5.

**Table 23. MII/RGMII/RTBI (When Operating at 3.3V) DC Electrical Characteristics**

| Parameter            | Symbol                               | Conditions                                                            |                                              | Min  | Max                                                      | Unit |
|----------------------|--------------------------------------|-----------------------------------------------------------------------|----------------------------------------------|------|----------------------------------------------------------|------|
| Supply voltage 3.3 V | LV <sub>DDA</sub> /LV <sub>DDB</sub> | —                                                                     |                                              | 2.97 | 3.63                                                     | V    |
| Output high voltage  | V <sub>OH</sub>                      | I <sub>OH</sub> = -4.0 mA                                             | LV <sub>DDA</sub> or LV <sub>DDB</sub> = Min | 2.40 | LV <sub>DDA</sub> + 0.3<br>or<br>LV <sub>DDB</sub> + 0.3 | V    |
| Output low voltage   | V <sub>OL</sub>                      | I <sub>OL</sub> = 4.0 mA                                              | LV <sub>DDA</sub> or LV <sub>DDB</sub> = Min | VSS  | 0.50                                                     | V    |
| Input high voltage   | V <sub>IH</sub>                      | —                                                                     | —                                            | 2.0  | LV <sub>DDA</sub> + 0.3<br>or<br>LV <sub>DDB</sub> + 0.3 | V    |
| Input low voltage    | V <sub>IL</sub>                      | —                                                                     | —                                            | -0.3 | 0.90                                                     | V    |
| Input high current   | I <sub>IH</sub>                      | V <sub>IN</sub> <sup>1</sup> = LV <sub>DDA</sub> or LV <sub>DDB</sub> |                                              | —    | 40                                                       | μA   |
| Input low current    | I <sub>IL</sub>                      | V <sub>IN</sub> <sup>1</sup> = VSS                                    |                                              | -600 | —                                                        | μA   |

**Note:**

1. The symbol V<sub>IN</sub><sup>1</sup> in this case, represents the LV<sub>IN</sub> symbol referenced in [Table 1](#) and [Table 2](#).

**Table 24. RGMII/RTBI (When Operating at 2.5 V) DC Electrical Characteristics**

| Parameters           | Symbol                               | Conditions                                                            |                                              | Min       | Max                                                      | Unit |
|----------------------|--------------------------------------|-----------------------------------------------------------------------|----------------------------------------------|-----------|----------------------------------------------------------|------|
| Supply voltage 2.5 V | LV <sub>DDA</sub> /LV <sub>DDB</sub> | —                                                                     |                                              | 2.37      | 2.63                                                     | V    |
| Output high voltage  | V <sub>OH</sub>                      | I <sub>OH</sub> = −1.0 mA                                             | LV <sub>DDA</sub> or LV <sub>DDB</sub> = Min | 2.00      | LV <sub>DDA</sub> + 0.3<br>or<br>LV <sub>DDB</sub> + 0.3 | V    |
| Output low voltage   | V <sub>OL</sub>                      | I <sub>OL</sub> = 1.0 mA                                              | LV <sub>DDA</sub> or LV <sub>DDB</sub> = Min | VSS − 0.3 | 0.40                                                     | V    |
| Input high voltage   | V <sub>IH</sub>                      | —                                                                     | LV <sub>DDA</sub> or LV <sub>DDB</sub> = Min | 1.7       | LV <sub>DDA</sub> + 0.3<br>or<br>LV <sub>DDB</sub> + 0.3 | V    |
| Input low voltage    | V <sub>IL</sub>                      | —                                                                     | LV <sub>DDA</sub> or LV <sub>DDB</sub> = Min | −0.3      | 0.70                                                     | V    |
| Input high current   | I <sub>IH</sub>                      | V <sub>IN</sub> <sup>1</sup> = LV <sub>DDA</sub> or LV <sub>DDB</sub> |                                              | —         | 10                                                       | μA   |
| Input low current    | I <sub>IL</sub>                      | V <sub>IN</sub> <sup>1</sup> = VSS                                    |                                              | −15       | —                                                        | μA   |

**Note:**

1. Note that the symbol V<sub>IN</sub>, in this case, represents the LV<sub>IN</sub> symbol referenced in [Table 1](#) and [Table 2](#).

## 8.2 MII, RGMII, SGMII, and RTBI AC Timing Specifications

The AC timing specifications for MII, RMII, RGMII, SGMII, and RTBI are presented in this section.

### 8.2.1 MII AC Timing Specifications

This section describes the MII transmit and receive AC timing specifications.

#### 8.2.1.1 MII Transmit AC Timing Specifications

[Table 25](#) provides the MII transmit AC timing specifications.

**Table 25. MII Transmit AC Timing Specifications**

At recommended operating conditions with LV<sub>DDA</sub>/LV<sub>DDB</sub> /NV<sub>DD</sub> of 3.3 V ± 10%.

| Parameter/Condition                             | Symbol <sup>1</sup>                 | Min | Typ | Max | Unit |
|-------------------------------------------------|-------------------------------------|-----|-----|-----|------|
| TX_CLK clock period 10 Mbps                     | t <sub>MTX</sub>                    | —   | 400 | —   | ns   |
| TX_CLK clock period 100 Mbps                    | t <sub>MTX</sub>                    | —   | 40  | —   | ns   |
| TX_CLK duty cycle                               | t <sub>MTXH</sub> /t <sub>MTX</sub> | 35  | —   | 65  | %    |
| TX_CLK to MII data TXD[3:0], TX_ER, TX_EN delay | t <sub>MTKHDX</sub>                 | 1   | 5   | 15  | ns   |

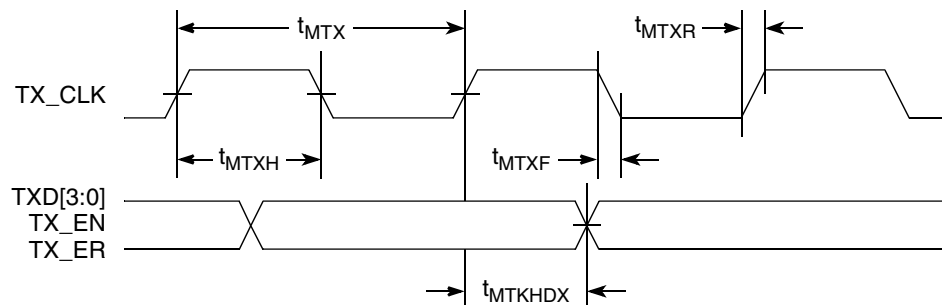
**Table 25. MII Transmit AC Timing Specifications (continued)**At recommended operating conditions with  $LV_{DDA}/LV_{ddb}/NV_{DD}$  of 3.3 V  $\pm$  10%.

| Parameter/Condition                                                 | Symbol <sup>1</sup> | Min | Typ | Max | Unit |
|---------------------------------------------------------------------|---------------------|-----|-----|-----|------|
| TX_CLK data clock rise $V_{IL}(\text{min})$ to $V_{IH}(\text{max})$ | $t_{MTXR}$          | 1.0 | —   | 4.0 | ns   |
| TX_CLK data clock fall $V_{IH}(\text{max})$ to $V_{IL}(\text{min})$ | $t_{MTXF}$          | 1.0 | —   | 4.0 | ns   |

**Note:**

1. The symbols used for timing specifications herein follow the pattern of  $t_{(\text{first two letters of functional block})(\text{signal})(\text{state})(\text{reference})(\text{state})}$  for inputs and  $t_{(\text{first two letters of functional block})(\text{reference})(\text{state})(\text{signal})(\text{state})}$  for outputs. For example,  $t_{MTKHDX}$  symbolizes MII transmit timing (MT) for the time  $t_{MTX}$  clock reference (K) going high (H) until data outputs (D) are invalid (X). Note that, in general, the clock reference symbol representation is based on two to three letters representing the clock of a particular functional. For example, the subscript of  $t_{MTX}$  represents the MII(M) transmit (TX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

Figure 7 shows the MII transmit AC timing diagram.

**Figure 7. MII Transmit AC Timing Diagram**

### 8.2.1.2 MII Receive AC Timing Specifications

Table 26 provides the MII receive AC timing specifications.

**Table 26. MII Receive AC Timing Specifications**At recommended operating conditions with  $LV_{DDA}/LV_{ddb}/NV_{DD}$  of 3.3 V  $\pm$  10%.

| Parameter/Condition                         | Symbol <sup>1</sup> | Min  | Typ | Max | Unit |
|---------------------------------------------|---------------------|------|-----|-----|------|
| RX_CLK clock period 10 Mbps                 | $t_{MRX}$           | —    | 400 | —   | ns   |
| RX_CLK clock period 100 Mbps                | $t_{MRX}$           | —    | 40  | —   | ns   |
| RX_CLK duty cycle                           | $t_{MRXH}/t_{MRX}$  | 35   | —   | 65  | %    |
| RXD[3:0], RX_DV, RX_ER setup time to RX_CLK | $t_{MRDVKH}$        | 10.0 | —   | —   | ns   |
| RXD[3:0], RX_DV, RX_ER hold time to RX_CLK  | $t_{MRDXKH}$        | 10.0 | —   | —   | ns   |

**Table 26. MII Receive AC Timing Specifications (continued)**At recommended operating conditions with  $LV_{DDA}/LV_{ddb}/NV_{DD}$  of  $3.3\text{ V} \pm 10\%$ .

| Parameter/Condition                                                 | Symbol <sup>1</sup> | Min | Typ | Max | Unit |
|---------------------------------------------------------------------|---------------------|-----|-----|-----|------|
| RX_CLK clock rise $V_{IL}(\text{min})$ to $V_{IH}(\text{max})$      | $t_{MRXR}$          | 1.0 | —   | 4.0 | ns   |
| RX_CLK clock fall time $V_{IH}(\text{max})$ to $V_{IL}(\text{min})$ | $t_{MRXF}$          | 1.0 | —   | 4.0 | ns   |

**Note:**

1. The symbols used for timing specifications herein follow the pattern of  $t_{(\text{first two letters of functional block})(\text{signal})(\text{state})(\text{reference})(\text{state})}$  for inputs and  $t_{(\text{first two letters of functional block})(\text{reference})(\text{state})(\text{signal})(\text{state})}$  for outputs. For example,  $t_{MRDVKH}$  symbolizes MII receive timing (MR) with respect to the time data input signals (D) reach the valid state (V) relative to the  $t_{MRX}$  clock reference (K) going to the high (H) state or setup time. Also,  $t_{MRDXKL}$  symbolizes MII receive timing (GR) with respect to the time data input signals (D) went invalid (X) relative to the  $t_{MRX}$  clock reference (K) going to the low (L) state or hold time. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For example, the subscript of  $t_{MRX}$  represents the MII (M) receive (RX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

Figure 8 provides the AC test load for TSEC.

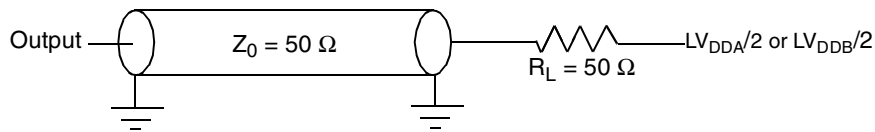
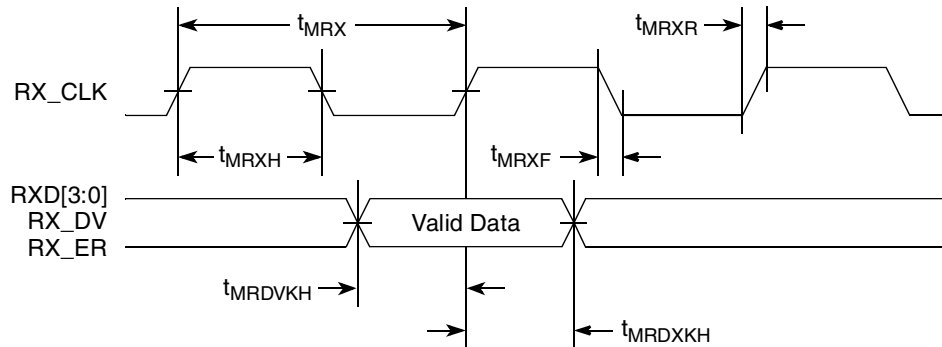
**Figure 8. TSEC AC Test Load**

Figure 9 shows the MII receive AC timing diagram.

**Figure 9. MII Receive AC Timing Diagram RMII AC Timing Specifications**

### 8.2.1.3 RMII Transmit AC Timing Specifications

This section describes the RMII transmit and receive AC timing specifications.

Table 27 provides the RMII transmit AC timing specifications.

**Table 27. RMII Transmit AC Timing Specifications**

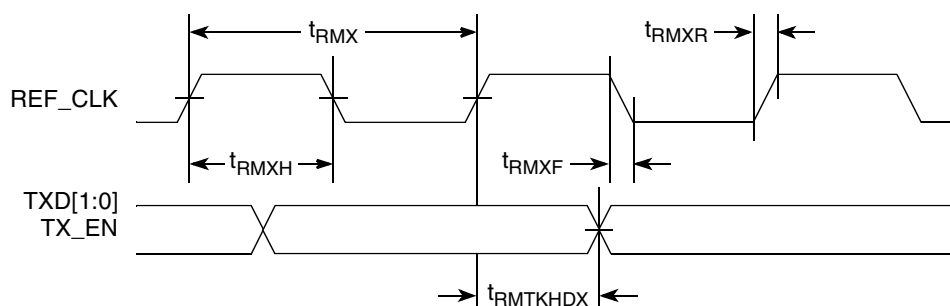
At recommended operating conditions with  $NV_{DD}$  of 3.3 V  $\pm$  10%.

| Parameter/Condition                                                  | Symbol <sup>1</sup> | Min | Typical | Max | Unit |
|----------------------------------------------------------------------|---------------------|-----|---------|-----|------|
| REF_CLK clock                                                        | $t_{RMX}$           | —   | 20      | —   | ns   |
| REF_CLK duty cycle                                                   | $t_{RMXH}/t_{RMX}$  | 35  | —       | 65  | %    |
| REF_CLK to RMII data TXD[1:0], TX_EN delay                           | $t_{RMTKHDx}$       | 2   | —       | 10  | ns   |
| REF_CLK data clock rise $V_{IL}(\text{min})$ to $V_{IH}(\text{max})$ | $t_{RMXR}$          | 1.0 | —       | 4.0 | ns   |
| REF_CLK data clock fall $V_{IH}(\text{max})$ to $V_{IL}(\text{min})$ | $t_{RMXF}$          | 1.0 | —       | 4.0 | ns   |

**Note:**

- The symbols used for timing specifications herein follow the pattern of  $t_{(\text{first three letters of functional block})(\text{signal})(\text{state})}$  for inputs and  $t_{(\text{first two letters of functional block})(\text{reference})(\text{state})(\text{signal})(\text{state})}$  for outputs. For example,  $t_{RMTKHDx}$  symbolizes RMII transmit timing (RMT) for the time  $t_{RMX}$  clock reference (K) going high (H) until data outputs (D) are invalid (X). Note that, in general, the clock reference symbol representation is based on two to three letters representing the clock of a particular functional. For example, the subscript of  $t_{RMX}$  represents the RMII(RM) reference (X) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

Figure 10 shows the RMII transmit AC timing diagram.



**Figure 10. RMII Transmit AC Timing Diagram**

### 8.2.1.4 RMII Receive AC Timing Specifications

Table 28 provides the RMII receive AC timing specifications.

**Table 28. RMII Receive AC Timing Specifications**

At recommended operating conditions with  $NV_{DD}$  of 3.3 V  $\pm$  10%.

| Parameter/Condition                           | Symbol <sup>1</sup> | Min | Typical | Max | Unit |
|-----------------------------------------------|---------------------|-----|---------|-----|------|
| REF_CLK clock period                          | $t_{RMX}$           | —   | 20      | —   | ns   |
| REF_CLK duty cycle                            | $t_{RMXH}/t_{RMX}$  | 35  | —       | 65  | %    |
| RXD[1:0], CRS_DV, RX_ER setup time to REF_CLK | $t_{RMRDVKH}$       | 4.0 | —       | —   | ns   |
| RXD[1:0], CRS_DV, RX_ER hold time to REF_CLK  | $t_{RMRDXKH}$       | 2.0 | —       | —   | ns   |

**Table 28. RMII Receive AC Timing Specifications (continued)**At recommended operating conditions with  $NV_{DD}$  of  $3.3\text{ V} \pm 10\%$ .

| Parameter/Condition                                                  | Symbol <sup>1</sup> | Min | Typical | Max | Unit |
|----------------------------------------------------------------------|---------------------|-----|---------|-----|------|
| REF_CLK clock rise $V_{IL}(\text{min})$ to $V_{IH}(\text{max})$      | $t_{\text{RMXR}}$   | 1.0 | —       | 4.0 | ns   |
| REF_CLK clock fall time $V_{IH}(\text{max})$ to $V_{IL}(\text{min})$ | $t_{\text{RMXF}}$   | 1.0 | —       | 4.0 | ns   |

**Note:**

1. The symbols used for timing specifications herein follow the pattern of  $t_{(\text{first three letters of functional block})(\text{signal})(\text{state})}$  (reference)(state) for inputs and  $t_{(\text{first two letters of functional block})(\text{reference})(\text{state})(\text{signal})(\text{state})}$  for outputs. For example,  $t_{\text{RMRDVKH}}$  symbolizes RMII receive timing (RMR) with respect to the time data input signals (D) reach the valid state (V) relative to the  $t_{\text{RMX}}$  clock reference (K) going to the high (H) state or setup time. Also,  $t_{\text{RMRDXKL}}$  symbolizes RMII receive timing (RMR) with respect to the time data input signals (D) went invalid (X) relative to the  $t_{\text{RMX}}$  clock reference (K) going to the low (L) state or hold time. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For example, the subscript of  $t_{\text{RMX}}$  represents the RMII (RM) reference (X) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

Figure 11 provides the AC test load.

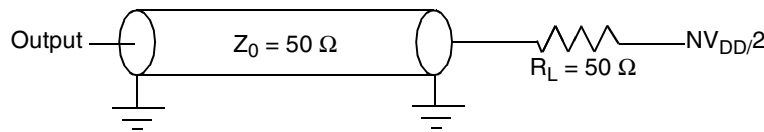
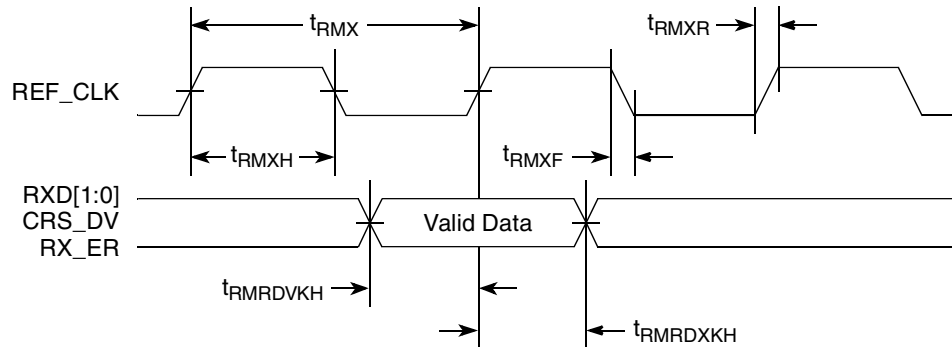
**Figure 11. AC Test Load**

Figure 12 shows the RMII receive AC timing diagram.

**Figure 12. RMII Receive AC Timing Diagram**

## 8.2.2 RGMII and RTBI AC Timing Specifications

Table 29 presents the RGMII and RTBI AC timing specifications.

**Table 29. RGMII and RTBI AC Timing Specifications**At recommended operating conditions with  $LV_{DDA}/LV_{ddb}$  of  $2.5\text{ V} \pm 5\%$ .

| Parameter/Condition                                 | Symbol <sup>1</sup> | Min  | Typ | Max | Unit |
|-----------------------------------------------------|---------------------|------|-----|-----|------|
| Data to clock output skew (at transmitter)          | $t_{\text{SKRGT}}$  | -0.5 | —   | 0.5 | ns   |
| Data to clock input skew (at receiver) <sup>2</sup> | $t_{\text{SKRGT}}$  | 1.0  | —   | 2.8 | ns   |
| Clock cycle duration <sup>3</sup>                   | $t_{\text{RGT}}$    | 7.2  | 8.0 | 8.8 | ns   |

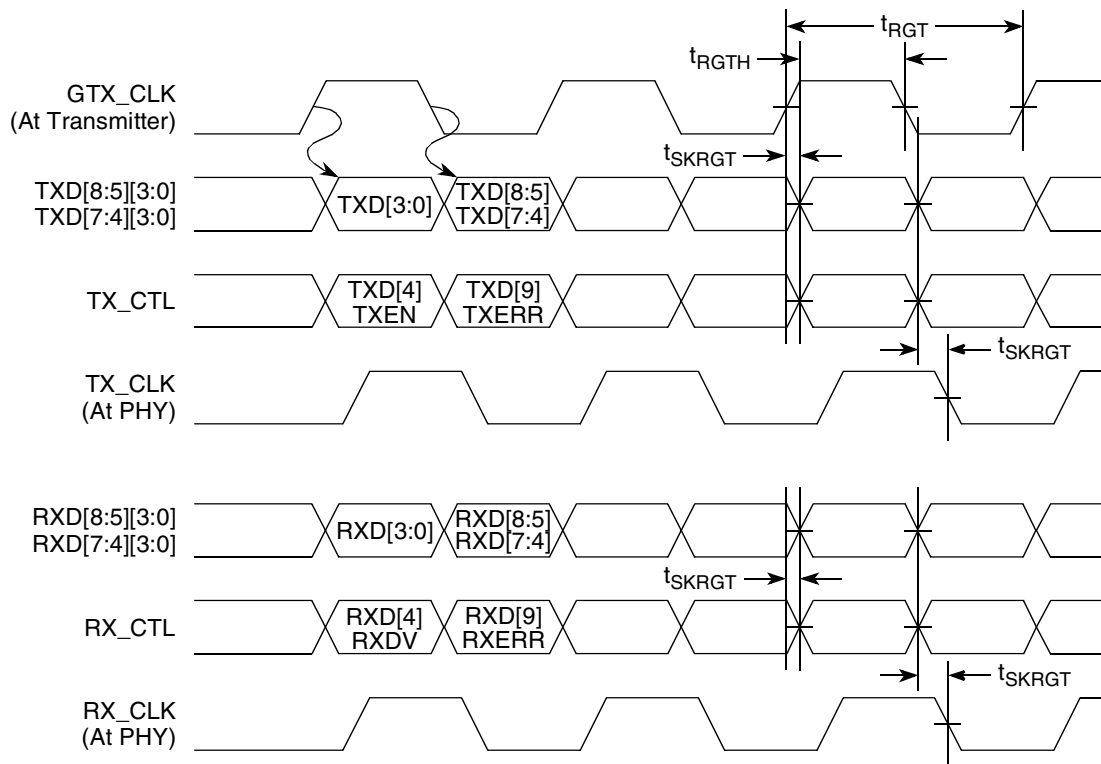
**Table 29. RGMII and RTBI AC Timing Specifications (continued)**At recommended operating conditions with  $LV_{DDA}/LV_{ddb}$  of  $2.5\text{ V} \pm 5\%$ .

|                                                        |                      |    |     |      |    |
|--------------------------------------------------------|----------------------|----|-----|------|----|
| Duty cycle for 1000Base-T <sup>4, 5</sup>              | $t_{RGTH}/t_{RGT}$   | 45 | 50  | 55   | %  |
| Duty cycle for 10BASE-T and 100BASE-TX <sup>3, 5</sup> | $t_{RGTH}/t_{RGT}$   | 40 | 50  | 60   | %  |
| Rise time (20%–80%)                                    | $t_{RGTR}$           | —  | —   | 0.75 | ns |
| Fall time (20%–80%)                                    | $t_{RGTF}$           | —  | —   | 0.75 | ns |
| GTX_CLK125 reference clock period                      | $t_{G12}^6$          | —  | 8.0 | —    | ns |
| GTX_CLK125 reference clock duty cycle                  | $t_{G125H}/t_{G125}$ | 47 | —   | 53   | %  |

**Notes:**

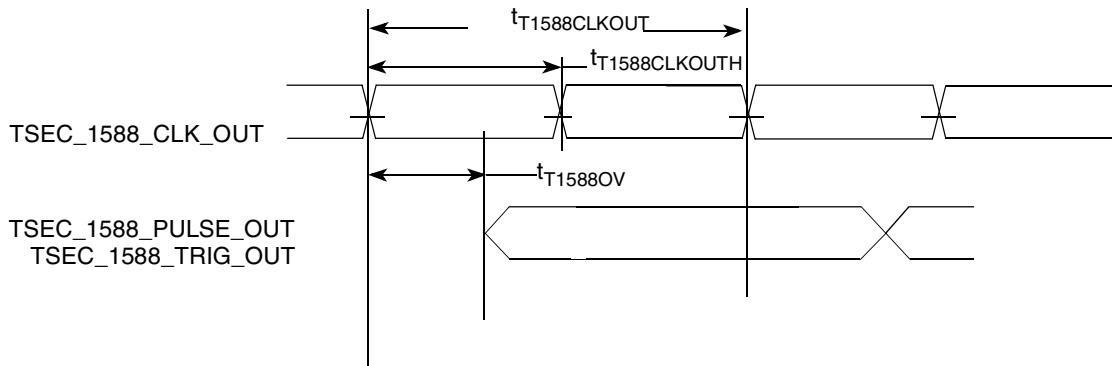
- Note that, in general, the clock reference symbol representation for this section is based on the symbols RGT to represent RGMII and RTBI timing. For example, the subscript of  $t_{RGT}$  represents the RTBI (T) receive (RX) clock. Note also that the notation for rise (R) and fall (F) times follows the clock symbol that is being represented. For symbols representing skews, the subscript is skew (SK) followed by the clock that is being skewed (RGT).
- This implies that PC board design requires clocks to be routed such that an additional trace delay of greater than 1.5 ns is added to the associated clock signal.
- For 10 and 100 Mbps,  $t_{RGT}$  scales to  $400\text{ ns} \pm 40\text{ ns}$  and  $40\text{ ns} \pm 4\text{ ns}$ , respectively.
- Duty cycle may be stretched/shrunk during speed changes or while transitioning to a received packet's clock domains as long as the minimum duty cycle is not violated and stretching occurs for no more than three  $t_{RGT}$  of the lowest speed transitioned between.
- Duty cycle reference is  $LV_{DDA}/2$  or  $LV_{ddb}/2$ .
- This symbol is used to represent the external GTX\_CLK125 and does not follow the original symbol naming convention.

Figure 13 shows the RGMII and RTBI AC timing and multiplexing diagrams.

**Figure 13. RGMII and RTBI AC Timing and Multiplexing Diagrams**

### 8.3 eTSEC IEEE 1588 AC Specifications

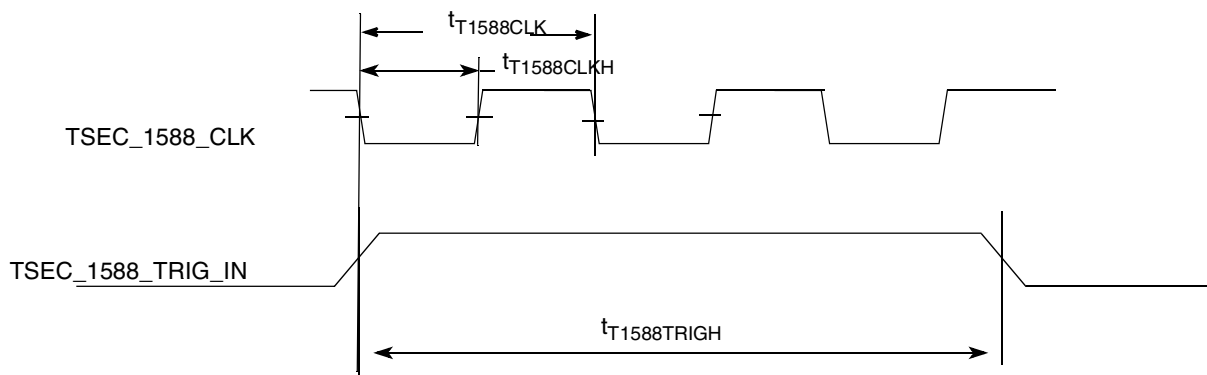
Figure 14 provides the data and command output timing diagram.



<sup>1</sup> The output delay is count starting rising edge if  $t_{T1588CLKOUT}$  is non-inverting. Otherwise, it is count starting falling edge.

**Figure 14. eTSEC IEEE 1588 Output AC Timing**

Figure 15 provides the data and command input timing diagram.



**Figure 15. eTSEC IEEE 1588 Input AC Timing**

The IEEE 1588 AC timing specifications are in Table 30.

**Table 30. eTSEC IEEE 1588 AC Timing Specifications**

At recommended operating conditions with  $L/TV_{DD}$  of 3.3 V  $\pm$  5%.

| Parameter/Condition                | Symbol                       | Min                    | Typ | Max                    | Unit | Note |
|------------------------------------|------------------------------|------------------------|-----|------------------------|------|------|
| TSEC_1588_CLK clock period         | $t_{T1588CLK}$               | 3.8                    | —   | $T_{RX\_CLK} \times 9$ | ns   | 1, 3 |
| TSEC_1588_CLK duty cycle           | $t_{T1588CLKH}/t_{T1588CLK}$ | 40                     | 50  | 60                     | %    | —    |
| TSEC_1588_CLK peak-to-peak jitter  | $t_{T1588CLKINJ}$            | —                      | —   | 250                    | ps   | —    |
| Rise time eTSEC_1588_CLK (20%–80%) | $t_{T1588CLKINR}$            | 1.0                    | —   | 2.0                    | ns   | —    |
| Fall time eTSEC_1588_CLK (80%–20%) | $t_{T1588CLKINF}$            | 1.0                    | —   | 2.0                    | ns   | —    |
| TSEC_1588_CLK_OUT clock period     | $t_{T1588CLKOUT}$            | $2 \cdot t_{T1588CLK}$ | —   | —                      | ns   | —    |

**Table 30. eTSEC IEEE 1588 AC Timing Specifications (continued)**At recommended operating conditions with  $L/TV_{DD}$  of 3.3 V  $\pm$  5%.

| Parameter/Condition           | Symbol                                  | Min                         | Typ | Max | Unit | Note |
|-------------------------------|-----------------------------------------|-----------------------------|-----|-----|------|------|
| TSEC_1588_CLK_OUT duty cycle  | $t_{T1588CLKOTH}$<br>$/t_{T1588CLKOUT}$ | 30                          | 50  | 70  | %    | —    |
| TSEC_1588_PULSE_OUT           | $t_{T1588OV}$                           | 0.5                         | —   | 3.0 | ns   | —    |
| TSEC_1588_TRIG_IN pulse width | $t_{T1588TRIGH}$                        | $2 \cdot t_{T1588CLK\_MAX}$ | —   | —   | ns   | 2    |

**Note:**

1.  $T_{RX\_CLK}$  is the max clock period of eTSEC receiving clock selected by TMR\_CTRL[CKSEL]. See the *MPC8313E PowerQUICC™ II Pro Integrated Processor Reference Manual* for a description of TMR\_CTRL registers.
2. It need to be at least two times of clock period of clock selected by TMR\_CTRL[CKSEL]. See the *MPC8313E PowerQUICC™ II Pro Integrated Processor Reference Manual* for a description of TMR\_CTRL registers.
3. The maximum value of  $t_{T1588CLK}$  is not only defined by the value of  $T_{RX\_CLK}$ , but also defined by the recovered clock. For example, for 10/100/1000 Mbps modes, the maximum value of  $t_{T1588CLK}$  is 3600, 280, and 56 ns, respectively.

## 8.4 Ethernet Management Interface Electrical Characteristics

The electrical characteristics specified here apply to MII management interface signals MDIO (management data input/output) and MDC (management data clock). The electrical characteristics for MII, RMII, RGMII, SGMII, and RTBI are specified in [Section 8.1, “Enhanced Three-Speed Ethernet Controller \(eTSEC\) \(10/100/1000 Mbps\)—MII/RMII/RGMII/SGMII/RTBI Electrical Characteristics.”](#)

### 8.4.1 MII Management DC Electrical Characteristics

The MDC and MDIO are defined to operate at a supply voltage of 2.5 V or 3.3 V. [Table 31](#) and [Table 32](#) provide the DC electrical characteristics for MDIO and MDC.

**Table 31. MII Management DC Electrical Characteristics When Powered at 2.5 V**

| Parameter              | Symbol              | Conditions                          |                                       | Min            | Max                                        | Unit          |
|------------------------|---------------------|-------------------------------------|---------------------------------------|----------------|--------------------------------------------|---------------|
| Supply voltage (2.5 V) | $NV_{DDA}/NV_{DDB}$ | —                                   |                                       | 2.37           | 2.63                                       | V             |
| Output high voltage    | $V_{OH}$            | $I_{OH} = -1.0$ mA                  | $NV_{DDA}$ or $NV_{DDB} = \text{Min}$ | 2.00           | $NV_{DDA} + 0.3$<br>or<br>$NV_{DDB} + 0.3$ | V             |
| Output low voltage     | $V_{OL}$            | $I_{OL} = 1.0$ mA                   | $NV_{DDA}$ or $NV_{DDB} = \text{Min}$ | $V_{SS} - 0.3$ | 0.40                                       | V             |
| Input high voltage     | $V_{IH}$            | —                                   | $NV_{DDA}$ or $NV_{DDB} = \text{Min}$ | 1.7            | —                                          | V             |
| Input low voltage      | $V_{IL}$            | —                                   | $NV_{DDA}$ or $NV_{DDB} = \text{Min}$ | -0.3           | 0.70                                       | V             |
| Input high current     | $I_{IH}$            | $V_{IN}^1 = NV_{DDA}$ or $NV_{DDB}$ |                                       | —              | 10                                         | $\mu\text{A}$ |
| Input low current      | $I_{IL}$            | $V_{IN} = NV_{DDA}$ or $NV_{DDB}$   |                                       | -15            | —                                          | $\mu\text{A}$ |

**Note:**

1. Note that the symbol  $V_{IN}$ , in this case, represents the  $LV_{IN}$  symbol referenced in [Table 1](#) and [Table 2](#).

**Table 32. MII Management DC Electrical Characteristics When Powered at 3.3 V**

| Parameter              | Symbol                               | Conditions                                   |                                              | Min             | Max                                                      | Unit |
|------------------------|--------------------------------------|----------------------------------------------|----------------------------------------------|-----------------|----------------------------------------------------------|------|
| Supply voltage (3.3 V) | NV <sub>DDA</sub> /NV <sub>DDB</sub> | —                                            |                                              | 2.97            | 3.63                                                     | V    |
| Output high voltage    | V <sub>OH</sub>                      | I <sub>OH</sub> = -1.0 mA                    | NV <sub>DDA</sub> or NV <sub>DDB</sub> = Min | 2.10            | NV <sub>DDA</sub> + 0.3<br>or<br>NV <sub>DDB</sub> + 0.3 | V    |
| Output low voltage     | V <sub>OL</sub>                      | I <sub>OL</sub> = 1.0 mA                     | LV <sub>DDA</sub> or LV <sub>DDB</sub> = Min | V <sub>SS</sub> | 0.50                                                     | V    |
| Input high voltage     | V <sub>IH</sub>                      | —                                            |                                              | 2.0             | —                                                        | V    |
| Input low voltage      | V <sub>IL</sub>                      | —                                            |                                              | —               | 0.80                                                     | V    |
| Input high current     | I <sub>IH</sub>                      | NV <sub>DDA</sub> or NV <sub>DDB</sub> = Max | V <sub>IN</sub> <sup>1</sup> = 2.1 V         | —               | 40                                                       | μA   |
| Input low current      | I <sub>IL</sub>                      | NV <sub>DDA</sub> or NV <sub>DDB</sub> = Max | V <sub>IN</sub> = 0.5 V                      | -600            | —                                                        | μA   |

**Note:**

1. Note that the symbol V<sub>IN</sub>, in this case, represents the LV<sub>IN</sub> symbol referenced in [Table 1](#) and [Table 2](#).

## 8.4.2 MII Management AC Electrical Specifications

[Table 33](#) provides the MII management AC timing specifications.

**Table 33. MII Management AC Timing Specifications**

At recommended operating conditions with LV<sub>DDA</sub>/LV<sub>DDB</sub> is 3.3 V ± 10% or 2.5 V ± 5%

| Parameter/Condition        | Symbol <sup>1</sup> | Min | Typ | Max | Unit | Notes |
|----------------------------|---------------------|-----|-----|-----|------|-------|
| MDC frequency              | f <sub>MDC</sub>    | —   | 2.5 | —   | MHz  | 2     |
| MDC period                 | t <sub>MDC</sub>    | —   | 400 | —   | ns   | —     |
| MDC clock pulse width high | t <sub>MDCH</sub>   | 32  | —   | —   | ns   | —     |
| MDC to MDIO delay          | t <sub>MDKHDX</sub> | 10  | —   | 170 | ns   | —     |
| MDIO to MDC setup time     | t <sub>MDDVKH</sub> | 5   | —   | —   | ns   | —     |
| MDIO to MDC hold time      | t <sub>MDDXKH</sub> | 0   | —   | —   | ns   | —     |
| MDC rise time              | t <sub>MDCR</sub>   | —   | —   | 10  | ns   | —     |
| MDC fall time              | t <sub>MDHF</sub>   | —   | —   | 10  | ns   | —     |

**Notes:**

1. The symbols used for timing specifications herein follow the pattern of t<sub>(first two letters of functional block)(signal)(state) (reference)(state)</sub> for inputs and t<sub>(first two letters of functional block)(reference)(state)(signal)(state)</sub> for outputs. For example, t<sub>MDKHDX</sub> symbolizes management data timing (MD) for the time t<sub>MDC</sub> from clock reference (K) high (H) until data outputs (D) are invalid (X) or data hold time. Also, t<sub>MDDVKH</sub> symbolizes management data timing (MD) with respect to the time data input signals (D) reach the valid state (V) relative to the t<sub>MDC</sub> clock reference (K) going to the high (H) state or setup time. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

Figure 16 shows the MII management AC timing diagram.

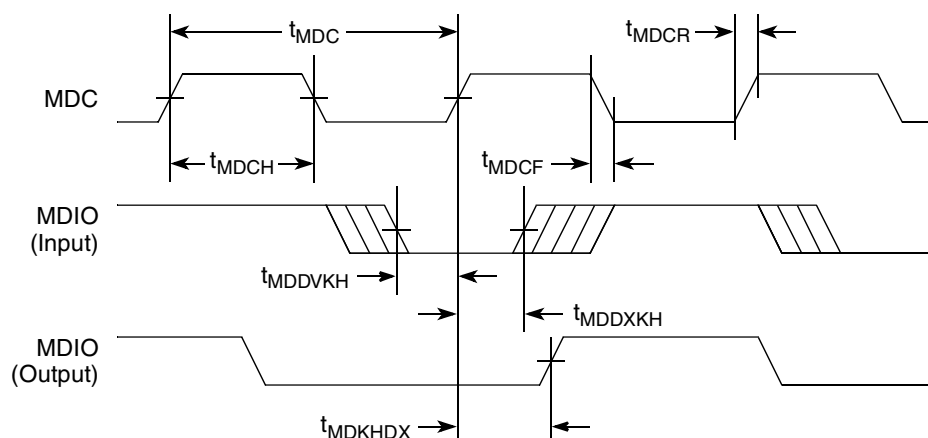


Figure 16. MII Management Interface Timing Diagram

### 8.4.3 SGMII DC Electrical Characteristics

The SGMII Solution in the MPC8313 is designed for use in a 4-wire, AC-Coupled SGMII link. Table 34 and Table 35 describe the SGMII AC-Coupled DC electrical characteristics. Transmitter characteristics are measured at the transmitter outputs, SD\_TX and SD\_TX\_B, as depicted in Figure 17.

Table 34. DC Transmitter Electrical Characteristics

| Parameter                              | Symbol            | Min                              | Max                              | Unit     | Notes                              |
|----------------------------------------|-------------------|----------------------------------|----------------------------------|----------|------------------------------------|
| Output high voltage                    | $V_{OH}$          | —                                | $0.7 \cdot X_{PADVDD}^1$         | mV       | Does not align to DC-coupled SGMII |
| Output low voltage                     | $V_{OL}$          | $0.3 \cdot X_{PADVDD}$           | —                                | mV       |                                    |
| Output ringing                         | $V_{RING}$        | —                                | 10                               | %        | —                                  |
| Output differential voltage            | $ V_{OD} $        | $(X_{PADVDD}/2)/1.7$             | $(X_{PADVDD}/2)/1.3$             | mV       | —                                  |
| Output offset voltage                  | $V_{OS}$          | $(X_{PADVDD}/2) - 50 \text{ mV}$ | $(X_{PADVDD}/2) + 50 \text{ mV}$ | mV       | Does not align to DC-coupled SGMII |
| Output impedance (single ended)        | $R_O$             | 40                               | 60                               | $\Omega$ | —                                  |
| Mismatch in a pair                     | $\Delta R_O$      | —                                | 10                               | %        | —                                  |
| Change in $V_{OD}$ between “0” and “1” | $\Delta  V_{OD} $ | —                                | 25                               | mV       | —                                  |
| Change in $V_{OS}$ between “0” and “1” | $\Delta V_{OS}$   | —                                | 25                               | mV       | —                                  |
| Output current on short to GND         | $I_{SA}, I_{SB}$  | —                                | 40                               | mA       | —                                  |

<sup>1</sup>  $X_{PADVDD}$  refers to the SGMII transmitter output supply voltage.

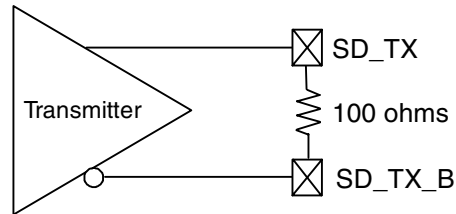


Figure 17. Transmitter Reference Circuit

Table 35. DC Receiver Electrical Characteristics

| Parameter                             | Symbol           | Min      | Max      | Unit | Notes                                    |
|---------------------------------------|------------------|----------|----------|------|------------------------------------------|
| DC input voltage range                | —                | —        | —        | —    | Input must be externally ac-coupled.     |
| Input differential voltage            | Vrx_diffpp       | 100      | 1200     | mV   | Peak to peak input differential voltage. |
| Loss of signal threshold              | Vl <sub>os</sub> | 30       | 100      | mV   | —                                        |
| Input AC common mode voltage          | Vcm_acpp         | —        | 100      | mV   | Peak to peak ac common mode voltage.     |
| Receiver differential input impedance | Zrx_diff         | 80       | 120      | Ω    | —                                        |
| Receiver common mode input impedance  | Zrx_cm           | 20       | 35       | Ω    | —                                        |
| Common mode input voltage             | Vcm              | xcorevss | xcorevss | V    | On-chip termination to xcorevss.         |

### 8.4.3.1 SGMII Transmit AC Timing Specifications

Table 36 provides the SGMII transmit AC timing targets. A source synchronous clock is not provided.

Table 36. SGMII Transmit AC Timing Specifications

| Parameter                           | Symbol            | Min | Max  | Unit   | Notes      |
|-------------------------------------|-------------------|-----|------|--------|------------|
| Deterministic Jitter                | J <sub>D</sub>    | —   | 0.17 | UI p-p | —          |
| Total Jitter                        | J <sub>T</sub>    | —   | 0.35 | UI p-p | —          |
| Unit Interval                       | U <sub>I</sub>    | 800 | 800  | ps     | +/- 100ppm |
| V <sub>OD</sub> fall time (80%–20%) | t <sub>fall</sub> | 50  | 120  | ps     | —          |
| V <sub>OD</sub> rise time (20%–80%) | t <sub>rise</sub> | 50  | 120  | ps     | —          |

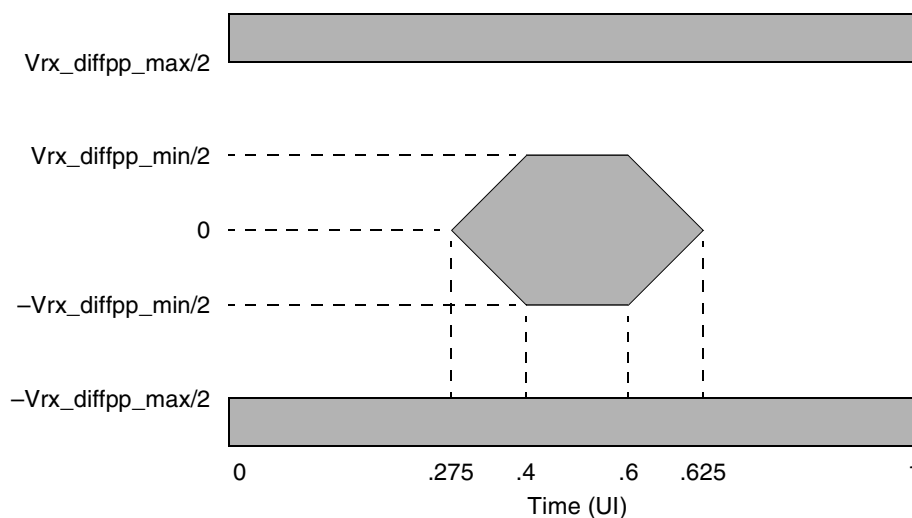
Source synchronous clock is not supported

### 8.4.3.2 SGMII Receive AC Timing Specifications

Table 37 provides the SGMII transmit AC timing targets. A source synchronous clock is not supported.

**Table 37. SGMII Receiver AC Timing Specifications**

| Parameter                                          | Symbol    | Min  | Max        | Unit   | Notes                |
|----------------------------------------------------|-----------|------|------------|--------|----------------------|
| Deterministic Jitter Tolerance                     | $J_D$     | 0.37 | —          | UI p-p | Measured at receiver |
| Combined Deterministic and Random Jitter Tolerance | $J_{DR}$  | 0.55 | —          | UI p-p | Measured at receiver |
| Sinusoidal Jitter Tolerance                        | $J_{sin}$ | 0.1  | —          | UI p-p | Measured at receiver |
| Total Jitter Tolerance                             | $J_T$     | 0.65 | —          | UI p-p | Measured at receiver |
| Bit Error Ratio                                    | BER       | —    | $10^{-12}$ |        | —                    |
| Unit Interval                                      | UI        | 800  | 800        | ps     | +/- 100ppm           |



**Figure 18. Receive Input Compliance Mask**

## 9 USB

### 9.1 USB Dual-Role Controllers

This section provides the AC and DC electrical specifications for the USB interface.

#### 9.1.1 USB DC Electrical Characteristics

Table 38 provides the DC electrical characteristics for the USB interface.

**Table 38. USB DC Electrical Characteristics**

| Parameter                                        | Symbol   | Min              | Max              | Unit    |
|--------------------------------------------------|----------|------------------|------------------|---------|
| High-level input voltage                         | $V_{IH}$ | 2.0              | $LV_{DDB} + 0.3$ | V       |
| Low-level input voltage                          | $V_{IL}$ | -0.3             | 0.8              | V       |
| Input current                                    | $I_{IN}$ | —                | $\pm 5$          | $\mu A$ |
| High-level output voltage, $I_{OH} = -100 \mu A$ | $V_{OH}$ | $LV_{DDB} - 0.2$ | —                | V       |
| Low-level output voltage, $I_{OL} = 100 \mu A$   | $V_{OL}$ | —                | 0.2              | V       |

#### 9.1.2 USB AC Electrical Specifications

Table 39 describes the general timing parameters of the USB interface.

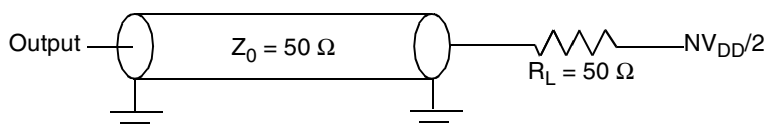
**Table 39. USB General Timing Parameters (ULPI Mode Only)**

| Parameter                                | Symbol <sup>1</sup> | Min | Max | Unit | Notes |
|------------------------------------------|---------------------|-----|-----|------|-------|
| USB clock cycle time                     | $t_{USCK}$          | 15  | —   | ns   | —     |
| Input setup to USB clock - all inputs    | $t_{USIVKH}$        | 4   | —   | ns   | —     |
| input hold to USB clock - all inputs     | $t_{USIXKH}$        | 1   | —   | ns   | —     |
| USB clock to output valid - all outputs  | $t_{USKHOV}$        | —   | 7   | ns   | —     |
| Output hold from USB clock - all outputs | $t_{USKHOX}$        | 2   | —   | ns   | —     |

**Note:**

1. The symbols used for timing specifications herein follow the pattern of  $t_{(First\ two\ letters\ of\ functional\ block)(signal)(state)\ (reference)(state)}$  for inputs and  $t_{(First\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$  for outputs. For example,  $t_{USIXKH}$  symbolizes USB timing (USB) for the input (I) to go invalid (X) with respect to the time the USB clock reference (K) goes high (H). Also,  $t_{USKHOX}$  symbolizes us timing (USB) for the USB clock reference (K) to go high (H), with respect to the output (O) going invalid (X) or output hold time.

Figure 19 and Figure 20 provide the AC test load and signals for the USB, respectively.



**Figure 19. USB AC Test Load**

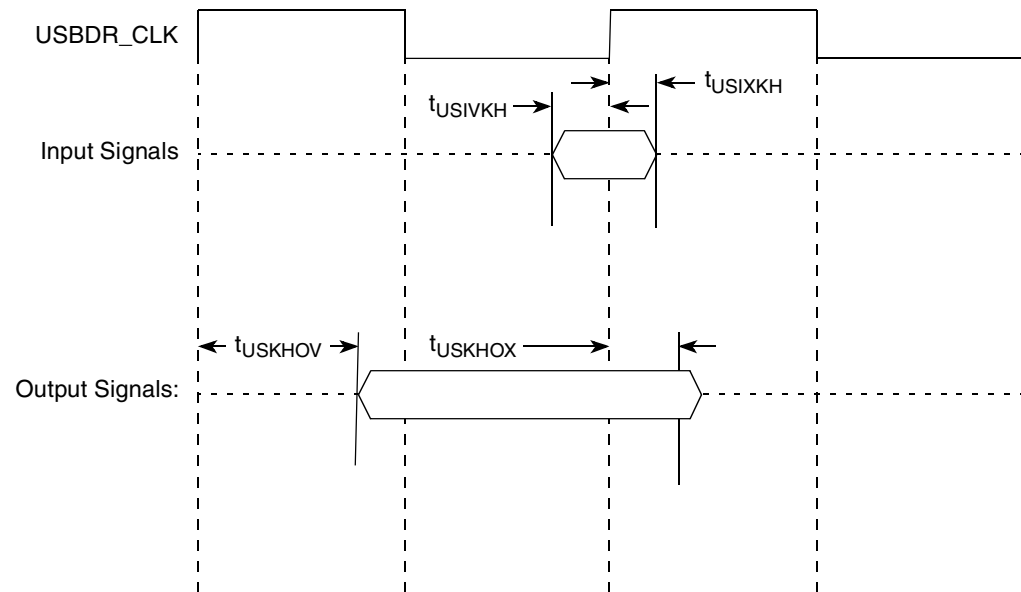


Figure 20. USB Signals

9.2 On-Chip USB PHY

This section describes the DC and AC electrical specifications for the on-chip USB PHY of the MPC8313E. See chapter 7 in the USB Specifications Rev 2.0 for more information.

Table 40 provides the USB clock input (USB\_CLK\_IN) DC timing specifications.

Table 40. USB\_CLK\_IN DC Electrical Characteristics

| Parameter          | Symbol   | Min  | Max             | Unit |
|--------------------|----------|------|-----------------|------|
| Input high voltage | $V_{IH}$ | 2.7  | $NV_{DD} + 0.3$ | V    |
| Input low voltage  | $V_{IL}$ | -0.3 | 0.4             | V    |

Table 41 provides the USB clock input (USB\_CLK\_IN) AC timing specifications.

Table 41. USB\_CLK\_IN AC Timing Specifications

| Parameter/Condition                    | Conditions                                                                            | Symbol             | Min   | Typical | Max  | Unit |
|----------------------------------------|---------------------------------------------------------------------------------------|--------------------|-------|---------|------|------|
| Frequency range                        | —                                                                                     | $f_{USB\_CLK\_IN}$ | —     | 24      | —    | MHz  |
| Clock frequency tolerance              | —                                                                                     | $t_{CLK\_TOL}$     | -0.05 | 0       | 0.05 | %    |
| Reference clock duty cycle             | Measured at 1.6 V                                                                     | $t_{CLK\_DUTY}$    | 40    | 50      | 60   | %    |
| Total input jitter/Time interval error | Peak to peak value measured with a second order high-pass filter of 500 kHz bandwidth | $t_{CLK\_PJ}$      | —     | —       | 200  | ps   |

## 10 Local Bus

This section describes the DC and AC electrical specifications for the local bus interface.

### 10.1 Local Bus DC Electrical Characteristics

Table 42 provides the DC electrical characteristics for the local bus interface.

**Table 42. Local Bus DC Electrical Characteristics at 3.3 V**

| Parameter                                                               | Symbol   | Min             | Max             | Unit    |
|-------------------------------------------------------------------------|----------|-----------------|-----------------|---------|
| High-level input voltage                                                | $V_{IH}$ | 2               | $LV_{DD} + 0.3$ | V       |
| Low-level input voltage                                                 | $V_{IL}$ | -0.3            | 0.8             | V       |
| Input current, ( $V_{IN}^1 = 0$ V or $V_{IN} = LV_{DD}$ )               | $I_{IN}$ | —               | $\pm 5$         | $\mu$ A |
| High-level output voltage, ( $LV_{DD} = \text{min}$ , $I_{OH} = -2$ mA) | $V_{OH}$ | $LV_{DD} - 0.2$ | —               | V       |
| Low-level output voltage, ( $LV_{DD} = \text{min}$ , $I_{OH} = 2$ mA)   | $V_{OL}$ | —               | 0.2             | V       |

### 10.2 Local Bus AC Electrical Specifications

Table 43 describes the general timing parameters of the local bus interface.

**Table 43. Local Bus General Timing Parameters**

| Parameter                                                   | Symbol <sup>1</sup> | Min  | Max | Unit | Notes |
|-------------------------------------------------------------|---------------------|------|-----|------|-------|
| Local bus cycle time                                        | $t_{LBK}$           | 15   | —   | ns   | 2     |
| Input setup to local bus clock                              | $t_{LBIVKH}$        | 7    | —   | ns   | 3, 4  |
| Input hold from local bus clock                             | $t_{LBIXKH}$        | 1.0  | —   | ns   | 3, 4  |
| LALE output fall to LAD output transition (LATCH hold time) | $t_{LBOTOT1}$       | 1.5  | —   | ns   | 5     |
| LALE output fall to LAD output transition (LATCH hold time) | $t_{LBOTOT2}$       | 3    | —   | ns   | 6     |
| LALE output fall to LAD output transition (LATCH hold time) | $t_{LBOTOT3}$       | 2.5  | —   | ns   | 7     |
| LALE output rise to LCLK negative edge                      | $t_{LALEHOV}$       | —    | 3.0 | ns   | —     |
| LALE output fall to LCLK negative edge                      | $t_{LALETOT1}$      | -1.5 | —   | ns   | 5     |
| LALE output fall to LCLK negative edge                      | $t_{LALETOT2}$      | -5.0 | —   | ns   | 6     |
| LALE output fall to LCLK negative edge                      | $t_{LALETOT3}$      | -4.5 | —   | ns   | 7     |

Table 43. Local Bus General Timing Parameters (continued)

| Parameter                                        | Symbol <sup>1</sup> | Min | Max | Unit | Notes |
|--------------------------------------------------|---------------------|-----|-----|------|-------|
| Local bus clock to output valid                  | $t_{LBKHOV}$        | —   | 3   | ns   | 3     |
| Local bus clock to output high impedance for LAD | $t_{LBKHOZ}$        | —   | 4   | ns   | 8     |

**Notes:**

1. The symbols used for timing specifications herein follow the pattern of  $t_{(First\ two\ letters\ of\ functional\ block)(signal)(state)\ (reference)(state)}$  for inputs and  $t_{(First\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$  for outputs. For example,  $t_{LBIXKH1}$  symbolizes local bus timing (LB) for the input (I) to go invalid (X) with respect to the time the  $t_{LBK}$  clock reference (K) goes high (H), in this case for clock one(1).
2. All timings are in reference to falling edge of LCLK0 (for all outputs and for  $\overline{LGTA}$  and LUPWAIT inputs) or rising edge of LCLK0 (for all other inputs).
3. All signals are measured from  $NV_{DD}/2$  of the rising/falling edge of LCLK0 to  $0.4 \times NV_{DD}$  of the signal in question for 3.3-V signaling levels.
4. Input timings are measured at the pin.
5.  $t_{LBOTOT1}$  and  $t_{LALETOT1}$  should be used when RCWH[LALE] is not set and the load on LALE output pin is at least 10pF less than the load on LAD output pins.
6.  $t_{LBOTOT2}$  and  $t_{LALETOT2}$  should be used when RCWH[LALE] is set and the load on LALE output pin is at least 10pF less than the load on LAD output pins.
7.  $t_{LBOTOT3}$  and  $t_{LALETOT3}$  should be used when RCWH[LALE] is set and the load on LALE output pin equals to the load on LAD output pins.
8. For purposes of active/float timing measurements, the Hi-Z or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.

Figure 21 provides the AC test load for the local bus.

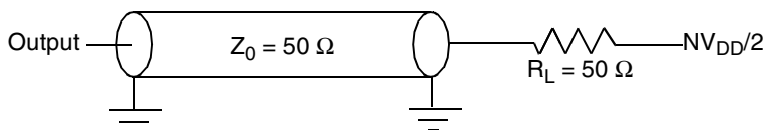


Figure 21. Local Bus AC Test Load

Figure 22 through Figure 25 show the local bus signals.

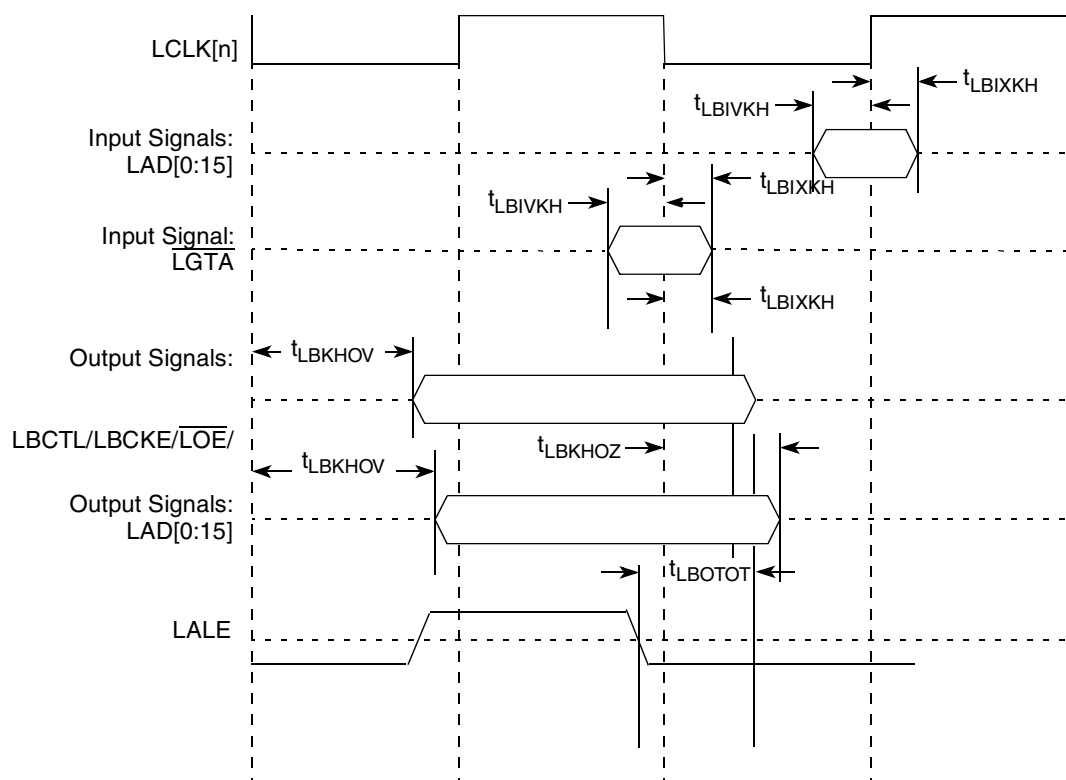
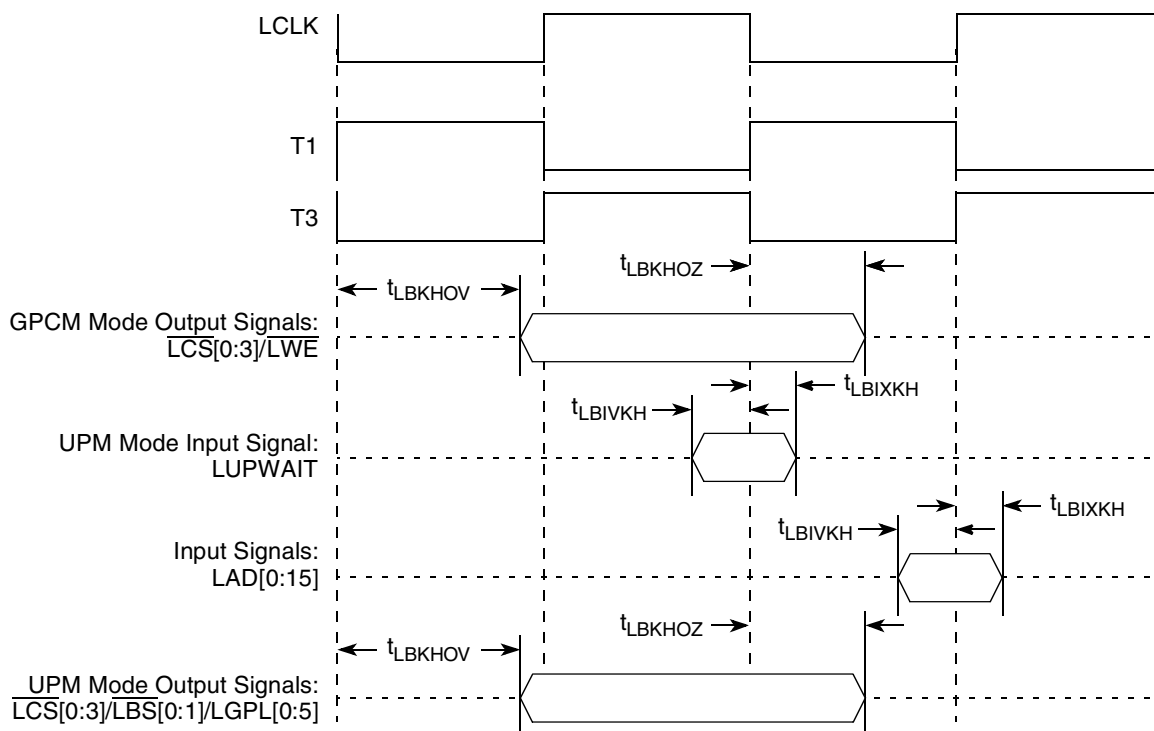
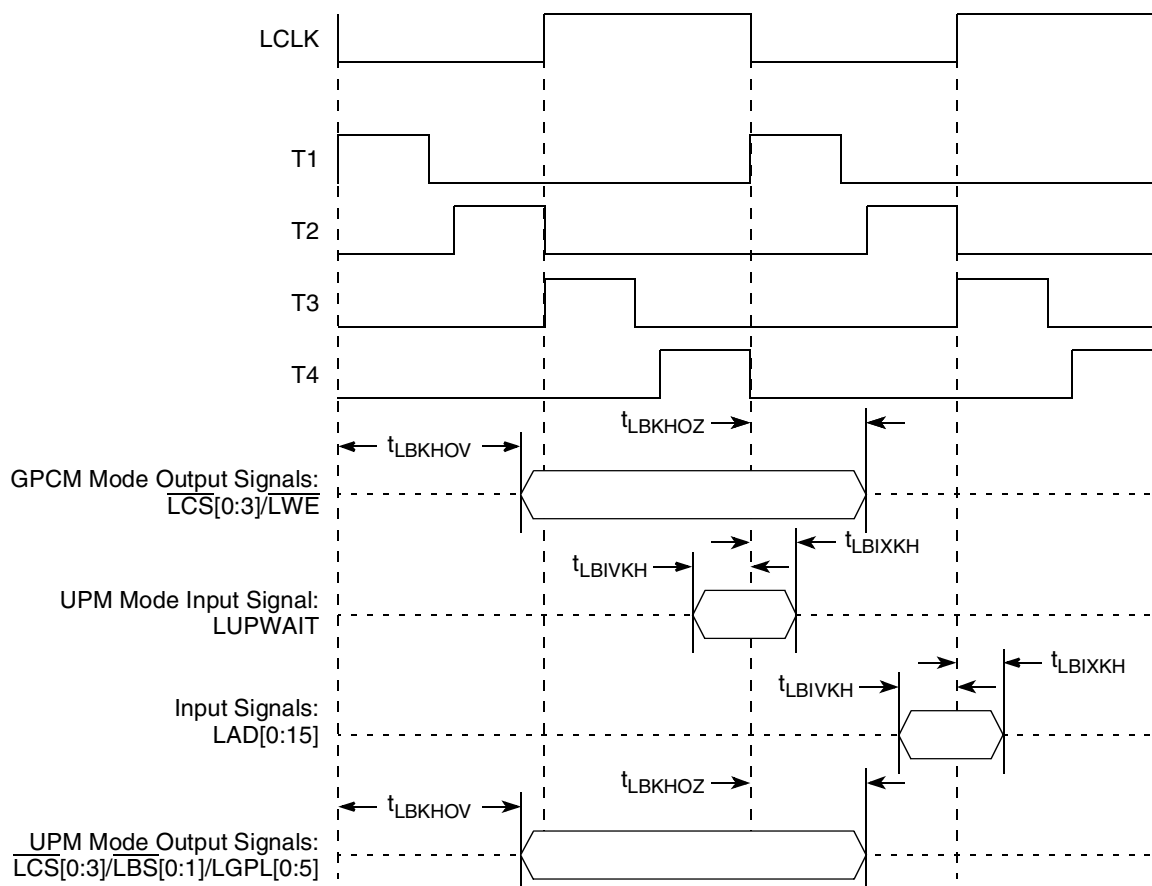


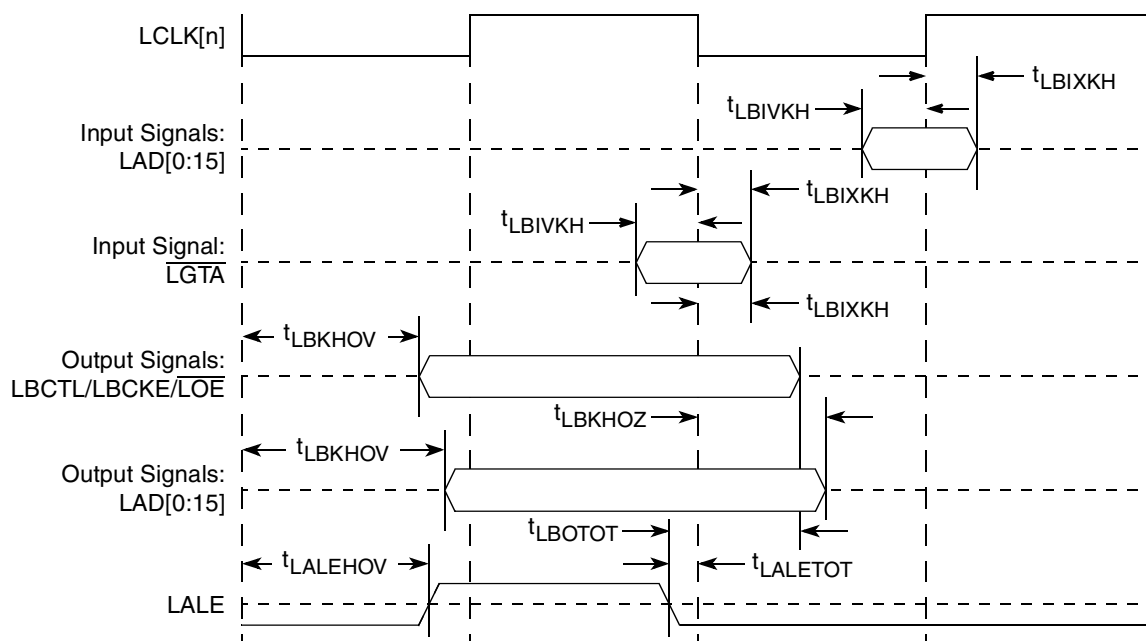
Figure 22. Local Bus Signals, Non-Special Signals Only



**Figure 23. Local Bus Signals, GPCM/UPM Signals for LCCR[CLKDIV] = 2**



**Figure 24. Local Bus Signals, GPCM/UPM Signals for LCCR[CLKDIV] = 4**



**Figure 25. Local Bus Signals, LALE with Respect to LCLK**

## 11 JTAG

This section describes the DC and AC electrical specifications for the IEEE Std 1149.1™ (JTAG) interface.

### 11.1 JTAG DC Electrical Characteristics

Table 44 provides the DC electrical characteristics for the IEEE 1149.1 (JTAG) interface.

**Table 44. JTAG Interface DC Electrical Characteristics**

| Characteristic      | Symbol   | Condition          | Min  | Max             | Unit |
|---------------------|----------|--------------------|------|-----------------|------|
| Input high voltage  | $V_{IH}$ | —                  | 2.1  | $NV_{DD} + 0.3$ | V    |
| Input low voltage   | $V_{IL}$ | —                  | −0.3 | 0.8             | V    |
| Input current       | $I_{IN}$ | —                  |      | ±5              | μA   |
| Output high voltage | $V_{OH}$ | $I_{OH} = -8.0$ mA | 2.4  | —               | V    |
| Output low voltage  | $V_{OL}$ | $I_{OL} = 8.0$ mA  | —    | 0.5             | V    |
| Output low voltage  | $V_{OL}$ | $I_{OL} = 3.2$ mA  | —    | 0.4             | V    |

### 11.2 JTAG AC Timing Specifications

This section describes the AC electrical specifications for the IEEE Std. 1149.1 (JTAG) interface.

Table 45 provides the JTAG AC timing specifications as defined in Figure 27 through Figure 30.

**Table 45. JTAG AC Timing Specifications (Independent of SYS\_CLK\_IN)<sup>1</sup>**

At recommended operating conditions (see Table 2).

| Parameter                                            | Symbol <sup>2</sup>          | Min      | Max      | Unit | Notes |
|------------------------------------------------------|------------------------------|----------|----------|------|-------|
| JTAG external clock frequency of operation           | $f_{JTG}$                    | 0        | 33.3     | MHz  | —     |
| JTAG external clock cycle time                       | $t_{JTG}$                    | 30       | —        | ns   | —     |
| JTAG external clock pulse width measured at 1.4 V    | $t_{JTKHKL}$                 | 15       | —        | ns   | —     |
| JTAG external clock rise and fall times              | $t_{JTGR}$ & $t_{JTGF}$      | 0        | 2        | ns   | —     |
| $\overline{TRST}$ assert time                        | $t_{TRST}$                   | 25       | —        | ns   | 3     |
| Input setup times:<br>Boundary-scan data<br>TMS, TDI | $t_{JTDVKH}$<br>$t_{JTIVKH}$ | 4<br>4   | —<br>—   | ns   | 4     |
| Input hold times:<br>Boundary-scan data<br>TMS, TDI  | $t_{JTDXKH}$<br>$t_{JTIXKH}$ | 10<br>10 | —<br>—   | ns   | 4     |
| Valid times:<br>Boundary-scan data<br>TDO            | $t_{JTKLDV}$<br>$t_{JTKLOV}$ | 2<br>2   | 11<br>11 | ns   | 5     |

**Table 45. JTAG AC Timing Specifications (Independent of SYS\_CLK\_IN) <sup>1</sup> (continued)**

At recommended operating conditions (see Table 2).

| Parameter                                     | Symbol <sup>2</sup> | Min | Max | Unit | Notes |
|-----------------------------------------------|---------------------|-----|-----|------|-------|
| Output hold times:                            |                     |     |     |      |       |
| Boundary-scan data                            | $t_{JTKLDX}$        | 2   | —   | ns   | 5     |
| TDO                                           | $t_{JTKLOX}$        | 2   | —   |      |       |
| JTAG external clock to output high impedance: |                     |     |     |      |       |
| Boundary-scan data                            | $t_{JTKLDZ}$        | 2   | 19  | ns   | 5, 6  |
| TDO                                           | $t_{JTKLOZ}$        | 2   | 9   |      |       |

**Notes:**

1. All outputs are measured from the midpoint voltage of the falling/rising edge of  $t_{TCLK}$  to the midpoint of the signal in question. The output timings are measured at the pins. All output timings assume a purely resistive 50- $\Omega$  load (see Figure 19). Time-of-flight delays must be added for trace lengths, vias, and connectors in the system.
2. The symbols used for timing specifications herein follow the pattern of  $t_{(first\ two\ letters\ of\ functional\ block)(signal)(state)\ (reference)(state)}$  for inputs and  $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$  for outputs. For example,  $t_{JTDVKH}$  symbolizes JTAG device timing (JT) with respect to the time data input signals (D) reaching the valid state (V) relative to the  $t_{JTG}$  clock reference (K) going to the high (H) state or setup time. Also,  $t_{JTDXKH}$  symbolizes JTAG timing (JT) with respect to the time data input signals (D) went invalid (X) relative to the  $t_{JTG}$  clock reference (K) going to the high (H) state. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
3.  $\overline{TRST}$  is an asynchronous level sensitive signal. The setup time is for test purposes only.
4. Non-JTAG signal input timing with respect to  $t_{TCLK}$ .
5. Non-JTAG signal output timing with respect to  $t_{TCLK}$ .
6. Guaranteed by design and characterization.

Figure 26 provides the AC test load for TDO and the boundary-scan outputs.

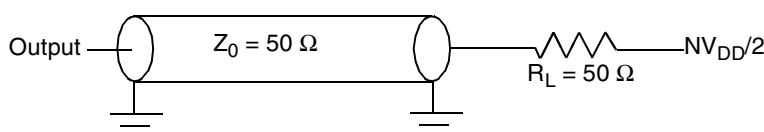
**Figure 26. AC Test Load for the JTAG Interface**

Figure 27 provides the JTAG clock input timing diagram.

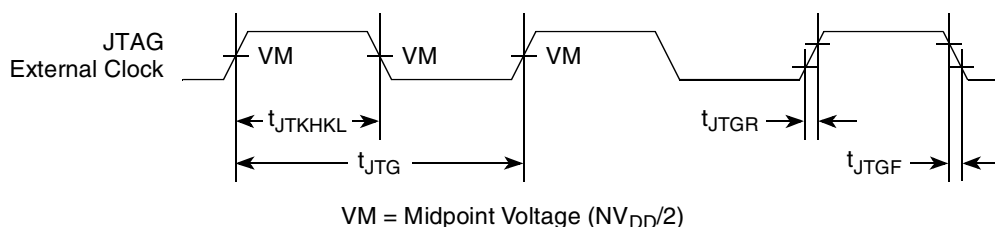
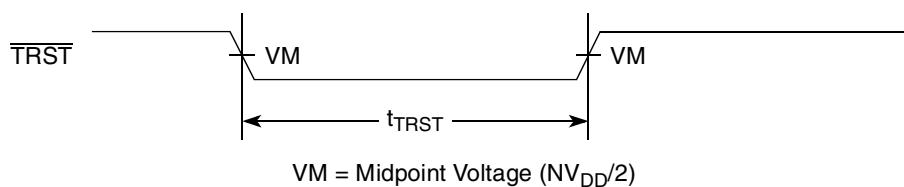
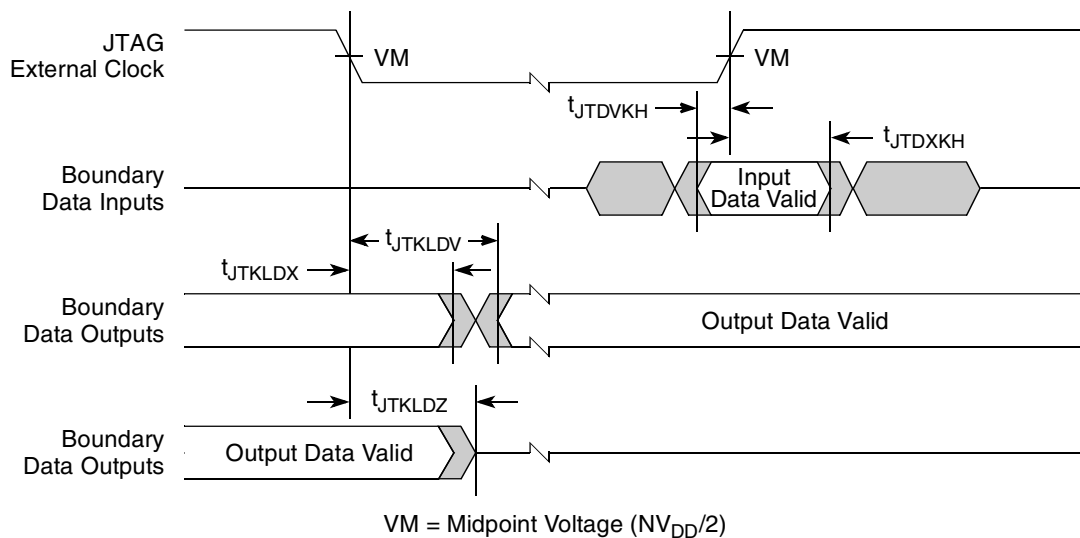
**Figure 27. JTAG Clock Input Timing Diagram**

Figure 28 provides the  $\overline{\text{TRST}}$  timing diagram.



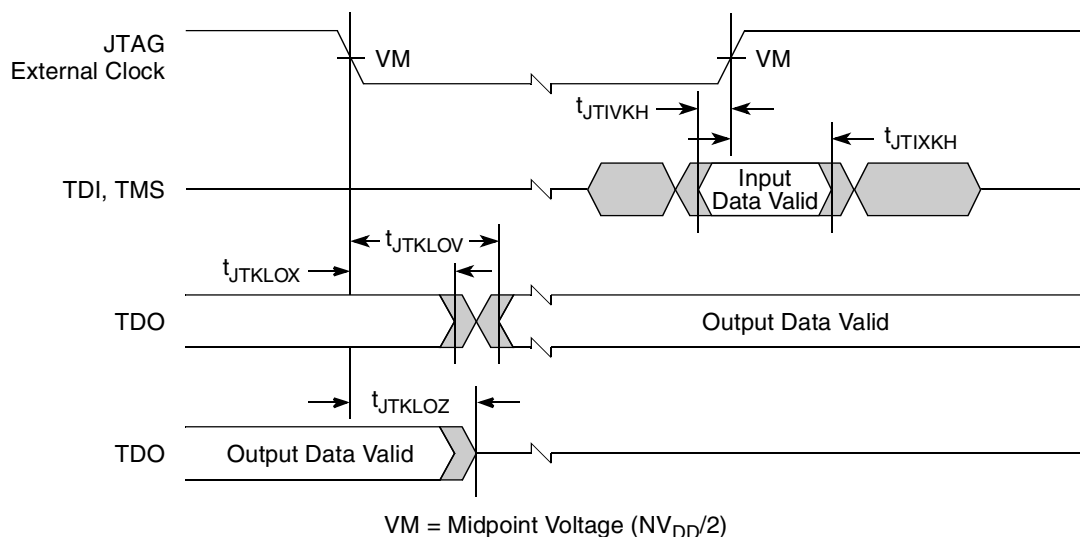
**Figure 28.  $\overline{\text{TRST}}$  Timing Diagram**

Figure 29 provides the boundary-scan timing diagram.



**Figure 29. Boundary-Scan Timing Diagram**

Figure 30 provides the test access port timing diagram.



**Figure 30. Test Access Port Timing Diagram**

## 12 I<sup>2</sup>C

This section describes the DC and AC electrical characteristics for the I<sup>2</sup>C interface.

### 12.1 I<sup>2</sup>C DC Electrical Characteristics

Table 46 provides the DC electrical characteristics for the I<sup>2</sup>C interface.

**Table 46. I<sup>2</sup>C DC Electrical Characteristics**

At recommended operating conditions with NV<sub>DD</sub> of 3.3 V ± 10%.

| Parameter                                                                                                     | Symbol              | Min                       | Max                    | Unit | Notes |
|---------------------------------------------------------------------------------------------------------------|---------------------|---------------------------|------------------------|------|-------|
| Input high voltage level                                                                                      | V <sub>IH</sub>     | 0.7 × NV <sub>DD</sub>    | NV <sub>DD</sub> + 0.3 | V    | —     |
| Input low voltage level                                                                                       | V <sub>IL</sub>     | −0.3                      | 0.3 × NV <sub>DD</sub> | V    | —     |
| Low level output voltage                                                                                      | V <sub>OL</sub>     | 0                         | 0.2 × NV <sub>DD</sub> | V    | 1     |
| Output fall time from V <sub>IH</sub> (min) to V <sub>IL</sub> (max) with a bus capacitance from 10 to 400 pF | t <sub>I2CLKV</sub> | 20 + 0.1 × C <sub>B</sub> | 250                    | ns   | 2     |
| Pulse width of spikes which must be suppressed by the input filter                                            | t <sub>I2KHKL</sub> | 0                         | 50                     | ns   | 3     |
| Capacitance for each I/O pin                                                                                  | C <sub>I</sub>      | —                         | 10                     | pF   | —     |
| Input current, (0 V ≤ V <sub>IN</sub> ≤ NV <sub>DD</sub> )                                                    | I <sub>IN</sub>     | —                         | ± 5                    | μA   | 4     |

**Notes:**

1. Output voltage (open drain or open collector) condition = 3 mA sink current.
2. C<sub>B</sub> = capacitance of one bus line in pF.
3. Refer to the *MPC8313E PowerQUICC™ II Pro Integrated Host Processor Reference Manual* for information on the digital filter used.
4. I/O pins obstruct the SDA and SCL lines if NV<sub>DD</sub> is switched off.

### 12.2 I<sup>2</sup>C AC Electrical Specifications

Table 47 provides the AC timing parameters for the I<sup>2</sup>C interface.

**Table 47. I<sup>2</sup>C AC Electrical Specifications**

All values refer to V<sub>IH</sub> (min) and V<sub>IL</sub> (max) levels (see Table 46).

| Parameter                                                                                    | Symbol <sup>1</sup> | Min            | Max              | Unit |
|----------------------------------------------------------------------------------------------|---------------------|----------------|------------------|------|
| SCL clock frequency                                                                          | f <sub>I2C</sub>    | 0              | 400              | kHz  |
| Low period of the SCL clock                                                                  | t <sub>I2CL</sub>   | 1.3            | —                | μs   |
| High period of the SCL clock                                                                 | t <sub>I2CH</sub>   | 0.6            | —                | μs   |
| Setup time for a repeated START condition                                                    | t <sub>I2SVKH</sub> | 0.6            | —                | μs   |
| Hold time (repeated) START condition (after this period, the first clock pulse is generated) | t <sub>I2SXKL</sub> | 0.6            | —                | μs   |
| Data setup time                                                                              | t <sub>I2DVKH</sub> | 100            | —                | ns   |
| Data hold time:                                                                              | t <sub>I2DXKL</sub> | —              | —                | μs   |
| CBUS compatible masters<br>I <sup>2</sup> C bus devices                                      |                     | 0 <sup>2</sup> | 0.9 <sup>3</sup> |      |

**Table 47. I<sup>2</sup>C AC Electrical Specifications (continued)**

All values refer to  $V_{IH}$  (min) and  $V_{IL}$  (max) levels (see Table 46).

| Parameter                                                                       | Symbol <sup>1</sup> | Min                  | Max | Unit |
|---------------------------------------------------------------------------------|---------------------|----------------------|-----|------|
| Fall time of both SDA and SCL signals <sup>5</sup>                              | $t_{I2CF}$          | —                    | 300 | ns   |
| Setup time for STOP condition                                                   | $t_{I2PVKH}$        | 0.6                  | —   | μs   |
| Bus free time between a STOP and START condition                                | $t_{I2KHDX}$        | 1.3                  | —   | μs   |
| Noise margin at the LOW level for each connected device (including hysteresis)  | $V_{NL}$            | $0.1 \times NV_{DD}$ | —   | V    |
| Noise margin at the HIGH level for each connected device (including hysteresis) | $V_{NH}$            | $0.2 \times NV_{DD}$ | —   | V    |

**Notes:**

1. The symbols used for timing specifications herein follow the pattern of  $t_{(first\ two\ letters\ of\ functional\ block)(signal)(state)\ (reference)(state)}$  for inputs and  $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$  for outputs. For example,  $t_{I2DVKH}$  symbolizes I<sup>2</sup>C timing (I2) with respect to the time data input signals (D) reach the valid state (V) relative to the  $t_{I2C}$  clock reference (K) going to the high (H) state or setup time. Also,  $t_{I2SXKL}$  symbolizes I<sup>2</sup>C timing (I2) for the time that the data with respect to the start condition (S) went invalid (X) relative to the  $t_{I2C}$  clock reference (K) going to the low (L) state or hold time. Also,  $t_{I2PVKH}$  symbolizes I<sup>2</sup>C timing (I2) for the time that the data with respect to the stop condition (P) reaching the valid state (V) relative to the  $t_{I2C}$  clock reference (K) going to the high (H) state or setup time. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
2. The MPC8313E provides a hold time of at least 300 ns for the SDA signal (referred to the  $V_{IHmin}$  of the SCL signal) to bridge the undefined region of the falling edge of SCL.
3. The maximum  $t_{I2DVKH}$  has only to be met if the device does not stretch the LOW period ( $t_{I2CL}$ ) of the SCL signal.
4.  $C_B$  = capacitance of one bus line in pF.
5. The MPC8313E does not follow the "I<sup>2</sup>C-BUS Specifications" version 2.1 regarding the  $t_{I2CF}$  AC parameter.

Figure 31 provides the AC test load for the I<sup>2</sup>C.

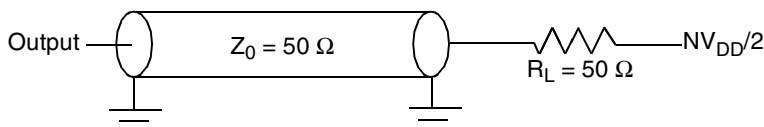
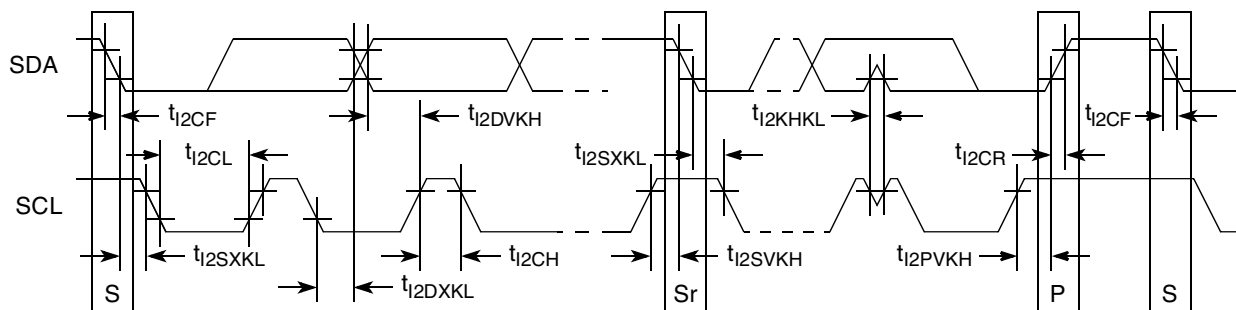
**Figure 31. I<sup>2</sup>C AC Test Load**

Figure 32 shows the AC timing diagram for the I<sup>2</sup>C bus.

**Figure 32. I<sup>2</sup>C Bus AC Timing Diagram**

## 13 PCI

This section describes the DC and AC electrical specifications for the PCI bus.

### 13.1 PCI DC Electrical Characteristics

Table 48 provides the DC electrical characteristics for the PCI interface.

**Table 48. PCI DC Electrical Characteristics <sup>1</sup>**

| Parameter                 | Symbol   | Test Condition                                                            | Min                  | Max                  | Unit          |
|---------------------------|----------|---------------------------------------------------------------------------|----------------------|----------------------|---------------|
| High-level input voltage  | $V_{IH}$ | $V_{OUT} \geq V_{OH} \text{ (min) or } V_{OUT} \leq V_{OL} \text{ (max)}$ | $0.5 \times NV_{DD}$ | $NV_{DD} + 0.3$      | V             |
| Low-level input voltage   | $V_{IL}$ |                                                                           | -0.5                 | $0.3 \times NV_{DD}$ | V             |
| High-level output voltage | $V_{OH}$ | $NV_{DD} = \text{min}, I_{OH} = -100 \mu\text{A}$                         | $0.9 \times NV_{DD}$ | —                    | V             |
| Low-level output voltage  | $V_{OL}$ | $NV_{DD} = \text{min}, I_{OL} = 100 \mu\text{A}$                          | —                    | $0.1 \times NV_{DD}$ | V             |
| Input current             | $I_{IN}$ | $0 \text{ V} \leq V_{IN} \leq NV_{DD}$                                    | —                    | $\pm 5$              | $\mu\text{A}$ |

**Note:**

- Note that the symbol  $V_{IN}$ , in this case, represents the  $OV_{IN}$  symbol referenced in Table 1 and Table 2.

### 13.2 PCI AC Electrical Specifications

This section describes the general AC timing parameters of the PCI bus. Note that the PCI\_CLK or PCI\_SYNC\_IN signal is used as the PCI input clock depending on whether the MPC8313E is configured as a host or agent device.

Table 49 shows the PCI AC timing specifications at 66 MHz.

**Table 49. PCI AC Timing Specifications at 66 MHz**

| Parameter                      | Symbol <sup>1</sup> | Min | Max | Unit | Notes |
|--------------------------------|---------------------|-----|-----|------|-------|
| Clock to output valid          | $t_{PCKHOV}$        | —   | 6.0 | ns   | 2     |
| Output hold from Clock         | $t_{PCKHOX}$        | 1   | —   | ns   | 2     |
| Clock to output high impedance | $t_{PCKHOZ}$        | —   | 14  | ns   | 2, 3  |
| Input setup to Clock           | $t_{PCIVKH}$        | 3.0 | —   | ns   | 2, 4  |
| Input hold from Clock          | $t_{PCIXKH}$        | 0   | —   | ns   | 2, 4  |

**Notes:**

- Note that the symbols used for timing specifications herein follow the pattern of  $t_{\text{(first two letters of functional block)(signal)(state) (reference)(state) for inputs and } t_{\text{(first two letters of functional block)(reference)(state)(signal)(state) for outputs. For example, } t_{PCIVKH}$  symbolizes PCI timing (PC) with respect to the time the input signals (I) reach the valid state (V) relative to the PCI\_SYNC\_IN clock,  $t_{SYS}$ , reference (K) going to the high (H) state or setup time. Also,  $t_{PCRHFV}$  symbolizes PCI timing (PC) with respect to the time hard reset (R) went high (H) relative to the frame signal (F) going to the valid (V) state.
- See the timing measurement conditions in the *PCI 2.3 Local Bus Specifications*.
- For purposes of active/float timing measurements, the Hi-Z or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
- Input timings are measured at the pin.

Table 50 shows the PCI AC Timing Specifications at 33 MHz.

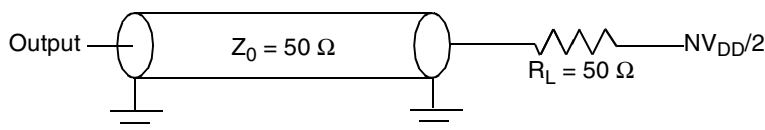
**Table 50. PCI AC Timing Specifications at 33 MHz**

| Parameter                      | Symbol <sup>1</sup> | Min | Max | Unit | Notes |
|--------------------------------|---------------------|-----|-----|------|-------|
| Clock to output valid          | $t_{PCKHOV}$        | —   | 11  | ns   | 2     |
| Output hold from Clock         | $t_{PCKHOX}$        | 2   | —   | ns   | 2     |
| Clock to output high impedance | $t_{PCKHOZ}$        | —   | 14  | ns   | 2, 3  |
| Input setup to Clock           | $t_{PCIVKH}$        | 3.0 | —   | ns   | 2, 4  |
| Input hold from Clock          | $t_{PCIXKH}$        | 0   | —   | ns   | 2, 4  |

**Notes:**

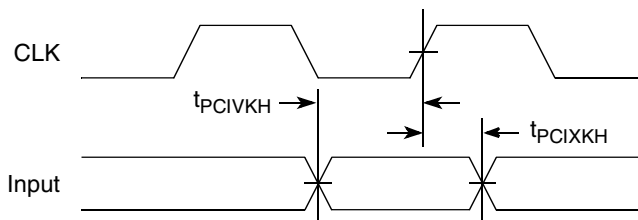
- Note that the symbols used for timing specifications herein follow the pattern of  $t_{(first\ two\ letters\ of\ functional\ block)(signal)(state)}$  for inputs and  $t_{(first\ two\ letters\ of\ functional\ block)(reference)(state)(signal)(state)}$  for outputs. For example,  $t_{PCIVKH}$  symbolizes PCI timing (PC) with respect to the time the input signals (I) reach the valid state (V) relative to the PCI\_SYNC\_IN clock,  $t_{SYS}$ , reference (K) going to the high (H) state or setup time. Also,  $t_{PCRHFV}$  symbolizes PCI timing (PC) with respect to the time hard reset (R) went high (H) relative to the frame signal (F) going to the valid (V) state.
- See the timing measurement conditions in the *PCI 2.3 Local Bus Specifications*.
- For purposes of active/float timing measurements, the Hi-Z or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
- Input timings are measured at the pin.

Figure 33 provides the AC test load for PCI.



**Figure 33. PCI AC Test Load**

Figure 34 shows the PCI input AC timing conditions.



**Figure 34. PCI Input AC Timing Measurement Conditions**

Figure 35 shows the PCI output AC timing conditions.

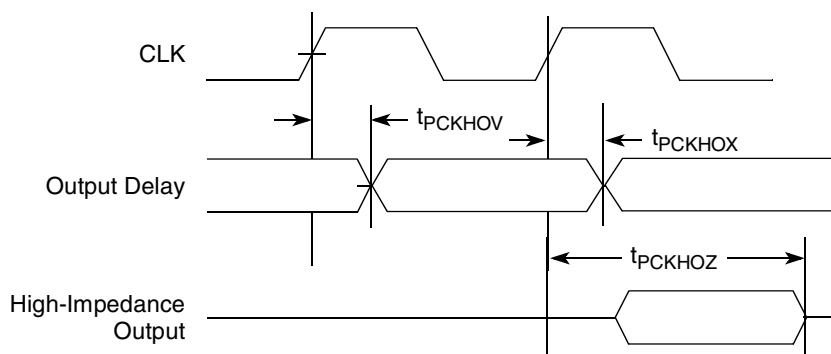


Figure 35. PCI Output AC Timing Measurement Condition

## 14 Timers

This section describes the DC and AC electrical specifications for the timers.

### 14.1 Timers DC Electrical Characteristics

Table 51 provides the DC electrical characteristics for the MPC8313E timers pins, including TIN,  $\overline{TOUT}$ , TGATE, and RTC\_CLK.

Table 51. Timers DC Electrical Characteristics

| Characteristic      | Symbol   | Condition                              | Min  | Max             | Unit          |
|---------------------|----------|----------------------------------------|------|-----------------|---------------|
| Output high voltage | $V_{OH}$ | $I_{OH} = -8.0 \text{ mA}$             | 2.4  | —               | V             |
| Output low voltage  | $V_{OL}$ | $I_{OL} = 8.0 \text{ mA}$              | —    | 0.5             | V             |
| Output low voltage  | $V_{OL}$ | $I_{OL} = 3.2 \text{ mA}$              | —    | 0.4             | V             |
| Input high voltage  | $V_{IH}$ | —                                      | 2.1  | $NV_{DD} + 0.3$ | V             |
| Input low voltage   | $V_{IL}$ | —                                      | -0.3 | 0.8             | V             |
| Input current       | $I_{IN}$ | $0 \text{ V} \leq V_{IN} \leq NV_{DD}$ | —    | $\pm 5$         | $\mu\text{A}$ |

### 14.2 Timers AC Timing Specifications

Table 52 provides the Timers input and output AC timing specifications.

Table 52. Timers Input AC Timing Specifications <sup>1</sup>

| Characteristic                    | Symbol <sup>2</sup> | Min | Unit |
|-----------------------------------|---------------------|-----|------|
| Timers inputs—minimum pulse width | $t_{TIWID}$         | 20  | ns   |

**Notes:**

- Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of SYS\_CLK\_IN. Timings are measured at the pin.
- Timers inputs and outputs are asynchronous to any visible clock. Timers outputs should be synchronized before use by any external synchronous logic. Timers inputs are required to be valid for at least  $t_{TIWID}$  ns to ensure proper operation

Figure 36 provides the AC test load for the Timers.

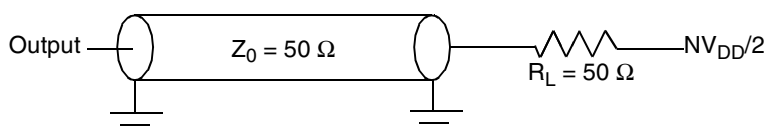


Figure 36. Timers AC Test Load

## 15 GPIO

This section describes the DC and AC electrical specifications for the GPIO.

### 15.1 GPIO DC Electrical Characteristics

Table 53 provides the DC electrical characteristics for the GPIO when the GPIO pins are operating from a 3.3-V supply.

Table 53. GPIO (When Operating at 3.3V ) DC Electrical Characteristics <sup>1</sup>

| Characteristic      | Symbol   | Condition                              | Min  | Max             | Unit          |
|---------------------|----------|----------------------------------------|------|-----------------|---------------|
| Output high voltage | $V_{OH}$ | $I_{OH} = -8.0 \text{ mA}$             | 2.4  | —               | V             |
| Output low voltage  | $V_{OL}$ | $I_{OL} = 8.0 \text{ mA}$              | —    | 0.5             | V             |
| Output low voltage  | $V_{OL}$ | $I_{OL} = 3.2 \text{ mA}$              | —    | 0.4             | V             |
| Input high voltage  | $V_{IH}$ | —                                      | 2.0  | $NV_{DD} + 0.3$ | V             |
| Input low voltage   | $V_{IL}$ | —                                      | -0.3 | 0.8             | V             |
| Input current       | $I_{IN}$ | $0 \text{ V} \leq V_{IN} \leq NV_{DD}$ | —    | $\pm 5$         | $\mu\text{A}$ |

<sup>1</sup> This specification only applies to GPIO pins that are operating from a 3.3-V supply. See Table 60 for the power supply listed for the individual GPIO signal.

Table 54 provides the DC electrical characteristics for the GPIO when the GPIO pins are operating from a 2.5-V supply.

Table 54. GPIO (When Operating at 2.5 V) DC Electrical Characteristics <sup>1</sup>

| Parameters           | Symbol    | Conditions                 |                        | Min            | Max             | Unit          |
|----------------------|-----------|----------------------------|------------------------|----------------|-----------------|---------------|
| Supply voltage 2.5 V | $NV_{DD}$ | —                          |                        | 2.37           | 2.63            | V             |
| Output high voltage  | $V_{OH}$  | $I_{OH} = -1.0 \text{ mA}$ | $NV_{DD} = \text{Min}$ | 2.00           | $NV_{DD} + 0.3$ | V             |
| Output low voltage   | $V_{OL}$  | $I_{OL} = 1.0 \text{ mA}$  | $NV_{DD} = \text{Min}$ | $V_{SS} - 0.3$ | 0.40            | V             |
| Input high voltage   | $V_{IH}$  | —                          | $NV_{DD} = \text{Min}$ | 1.7            | $NV_{DD} + 0.3$ | V             |
| Input low voltage    | $V_{IL}$  | —                          | $NV_{DD} = \text{Min}$ | -0.3           | 0.70            | V             |
| Input high current   | $I_{IH}$  | $V_{IN} = NV_{DD}$         |                        | —              | 10              | $\mu\text{A}$ |
| Input low current    | $I_{IL}$  | $V_{IN} = V_{SS}$          |                        | -15            | —               | $\mu\text{A}$ |

<sup>1</sup> This specification only applies to GPIO pins that are operating from a 2.5-V supply. See Table 60 for the power supply listed for the individual GPIO signal.

## 15.2 GPIO AC Timing Specifications

Table 55 provides the GPIO input and output AC timing specifications.

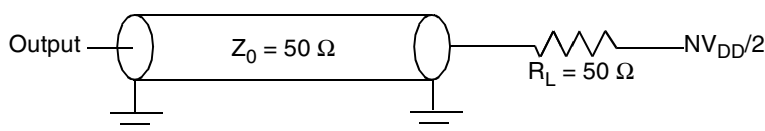
**Table 55. GPIO Input AC Timing Specifications <sup>1</sup>**

| Characteristic                  | Symbol <sup>2</sup> | Min | Unit |
|---------------------------------|---------------------|-----|------|
| GPIO inputs—minimum pulse width | $t_{PIWID}$         | 20  | ns   |

**Notes:**

1. Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of SYS\_CLKIN. Timings are measured at the pin.
2. GPIO inputs and outputs are asynchronous to any visible clock. GPIO outputs should be synchronized before use by any external synchronous logic. GPIO inputs are required to be valid for at least  $t_{PIWID}$  ns to ensure proper operation.

Figure 37 provides the AC test load for the GPIO.



**Figure 37. GPIO AC Test Load**

## 16 IPIC

This section describes the DC and AC electrical specifications for the external interrupt pins.

### 16.1 IPIC DC Electrical Characteristics

Table 56 provides the DC electrical characteristics for the external interrupt pins.

**Table 56. IPIC DC Electrical Characteristics**

| Characteristic     | Symbol   | Condition                 | Min  | Max             | Unit |
|--------------------|----------|---------------------------|------|-----------------|------|
| Input high voltage | $V_{IH}$ | —                         | 2.1  | $NV_{DD} + 0.3$ | V    |
| Input low voltage  | $V_{IL}$ | —                         | −0.3 | 0.8             | V    |
| Input current      | $I_{IN}$ | —                         | —    | ±5              | μA   |
| Output low voltage | $V_{OL}$ | $I_{OL} = 8.0 \text{ mA}$ | —    | 0.5             | V    |
| Output low voltage | $V_{OL}$ | $I_{OL} = 3.2 \text{ mA}$ | —    | 0.4             | V    |

## 16.2 IPIC AC Timing Specifications

Table 57 provides the IPIC input and output AC timing specifications.

**Table 57. IPIC Input AC Timing Specifications <sup>1</sup>**

| Characteristic                  | Symbol <sup>2</sup> | Min | Unit |
|---------------------------------|---------------------|-----|------|
| IPIC inputs—minimum pulse width | $t_{PIWID}$         | 20  | ns   |

**Notes:**

1. Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of SYS\_CLK\_IN. Timings are measured at the pin.
2. IPIC inputs and outputs are asynchronous to any visible clock. IPIC outputs should be synchronized before use by any external synchronous logic. IPIC inputs are required to be valid for at least  $t_{PIWID}$  ns to ensure proper operation when working in edge triggered mode.

## 17 SPI

This section describes the DC and AC electrical specifications for the SPI of the MPC8313E

### 17.1 SPI DC Electrical Characteristics

Table 58 provides the DC electrical characteristics for the MPC8313E SPI.

**Table 58. SPI DC Electrical Characteristics**

| Characteristic      | Symbol   | Condition                              | Min  | Max             | Unit          |
|---------------------|----------|----------------------------------------|------|-----------------|---------------|
| Output high voltage | $V_{OH}$ | $I_{OH} = -6.0 \text{ mA}$             | 2.4  | —               | V             |
| Output low voltage  | $V_{OL}$ | $I_{OL} = 6.0 \text{ mA}$              | —    | 0.5             | V             |
| Output low voltage  | $V_{OL}$ | $I_{OL} = 3.2 \text{ mA}$              | —    | 0.4             | V             |
| Input high voltage  | $V_{IH}$ | —                                      | 2.1  | $NV_{DD} + 0.3$ | V             |
| Input low voltage   | $V_{IL}$ | —                                      | -0.3 | 0.8             | V             |
| Input current       | $I_{IN}$ | $0 \text{ V} \leq V_{IN} \leq NV_{DD}$ | —    | $\pm 5$         | $\mu\text{A}$ |

### 17.2 SPI AC Timing Specifications

Table 59 and provide the SPI input and output AC timing specifications.

**Table 59. SPI AC Timing Specifications <sup>1</sup>**

| Characteristic                                           | Symbol <sup>2</sup> | Min | Max | Unit |
|----------------------------------------------------------|---------------------|-----|-----|------|
| SPI outputs—Master mode (internal clock) delay           | $t_{NIKHOV}$        | 0.5 | 6   | ns   |
| SPI outputs—Slave mode (external clock) delay            | $t_{NEKHOV}$        | 2   | 8   | ns   |
| SPI inputs—Master mode (internal clock) input setup time | $t_{NIIVKH}$        | 6   | —   | ns   |
| SPI inputs—Master mode (internal clock) input hold time  | $t_{NIIXKH}$        | 0   | —   | ns   |
| SPI inputs—Slave mode (external clock) input setup time  | $t_{NEIVKH}$        | 4   | —   | ns   |

**Table 59. SPI AC Timing Specifications <sup>1</sup>**

| Characteristic                                         | Symbol <sup>2</sup> | Min | Max | Unit |
|--------------------------------------------------------|---------------------|-----|-----|------|
| SPI inputs—Slave mode (external clock) input hold time | $t_{NEIXKH}$        | 2   | —   | ns   |

**Notes:**

- Output specifications are measured from the 50% level of the rising edge of SYS\_CLK\_IN to the 50% level of the signal. Timings are measured at the pin.
- The symbols used for timing specifications follow the pattern of  $t_{(\text{first two letters of functional block})(\text{signal})(\text{state})(\text{reference})(\text{state})}$  for inputs and  $t_{(\text{first two letters of functional block})(\text{reference})(\text{state})(\text{signal})(\text{state})}$  for outputs. For example,  $t_{NIKH OV}$  symbolizes the NMSI outputs internal timing (NI) for the time  $t_{SPI}$  memory clock reference (K) goes from the high state (H) until outputs (O) are valid (V).

Figure 38 provides the AC test load for the SPI.

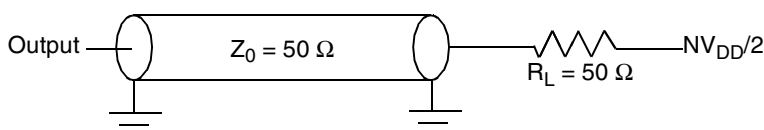
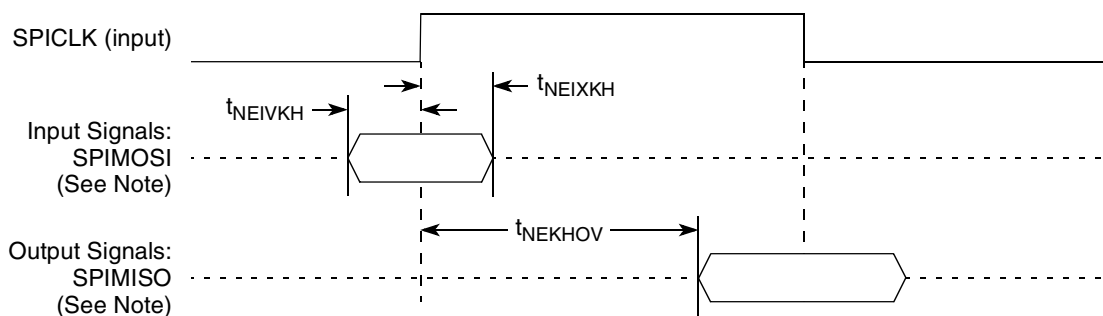
**Figure 38. SPI AC Test Load**

Figure 39 through Figure 40 represent the AC timing from Table 59. Note that although the specifications generally reference the rising edge of the clock, these AC timing diagrams also apply when the falling edge is the active edge.

Figure 39 shows the SPI timing in Slave mode (external clock).



**Note:** The clock edge is selectable on SPI.

**Figure 39. SPI AC Timing in Slave Mode (External Clock) Diagram**

Figure 40 shows the SPI timing in Master mode (internal clock).

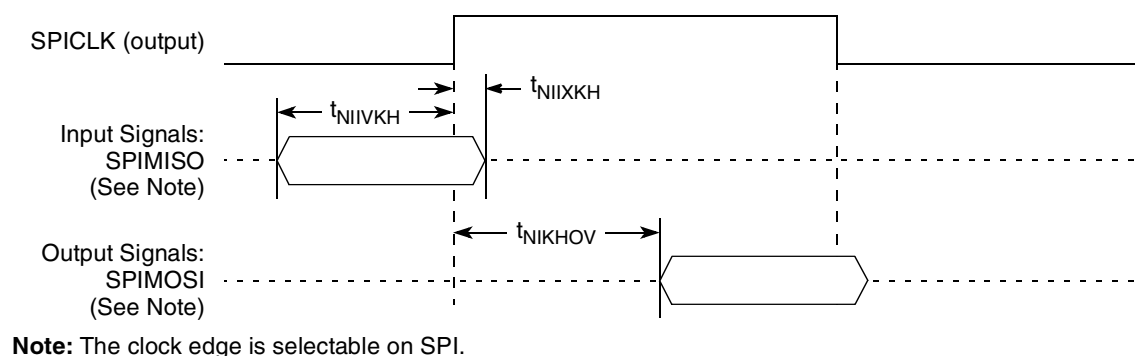


Figure 40. SPI AC Timing in Master Mode (Internal Clock) Diagram

## 18 Package and Pin Listings

This section details package parameters, pin assignments, and dimensions. The MPC8313E is available in a thermally enhanced plastic ball grid array (TEPBGAII), see [Section 18.1, “Package Parameters for the MPC8313E TEPBGAII,”](#) and [Section 18.2, “Mechanical Dimensions of the MPC8313E TEPBGAII,”](#) for information on the TEPBGAII.

### 18.1 Package Parameters for the MPC8313E TEPBGAII

The package parameters are as provided in the following list. The package type is 27 mm × 27 mm, 516 TEPBGAII.

|                         |                                 |
|-------------------------|---------------------------------|
| Package outline         | 27 mm × 27 mm                   |
| Interconnects           | 516                             |
| Pitch                   | 1.00 mm                         |
| Module height (typical) | 2.25 mm                         |
| Solder Balls            | 95.5 Sn/0.5 Cu/4Ag (VR package) |
| Ball diameter (typical) | 0.6 mm                          |

[illegible]

1. All dimensions are in millimeters.
2. Dimensions and tolerances per ASME Y14.5M-1994.

3. Maximum solder ball diameter measured parallel to datum A.
4. Datum A, the seating plane, is determined by the spherical crowns of the solder balls.
5. Package code 5368 is to account for PGE and the built-in heat spreader.

## 18.3 Pinout Listings

Table 60 provides the pin-out listing for the MPC8313E, TEPBGAI package.

**Table 60. MPC8313E TEPBGAI Pinout Listing**

| Signal                                 | Package Pin Number | Pin Type | Power Supply     | Notes |
|----------------------------------------|--------------------|----------|------------------|-------|
| <b>DDR Memory Controller Interface</b> |                    |          |                  |       |
| MEMC_MDQ[0]                            | A8                 | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[1]                            | A9                 | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[2]                            | C10                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[3]                            | C9                 | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[4]                            | E9                 | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[5]                            | E11                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[6]                            | E10                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[7]                            | C8                 | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[8]                            | E8                 | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[9]                            | A6                 | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[10]                           | B6                 | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[11]                           | C6                 | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[12]                           | C7                 | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[13]                           | D7                 | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[14]                           | D6                 | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[15]                           | A5                 | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[16]                           | A19                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[17]                           | D18                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[18]                           | A17                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[19]                           | E17                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[20]                           | E16                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[21]                           | C18                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[22]                           | D19                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[23]                           | C19                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[24]                           | E19                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[25]                           | A22                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[26]                           | C21                | IO       | GV <sub>DD</sub> | —     |

Table 60. MPC8313E TEPBGAI Pinout Listing (continued)

| Signal       | Package Pin Number | Pin Type | Power Supply     | Notes |
|--------------|--------------------|----------|------------------|-------|
| MEMC_MDQ[27] | C20                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[28] | A21                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[29] | A20                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[30] | C22                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQ[31] | B22                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDM0    | B7                 | O        | GV <sub>DD</sub> | —     |
| MEMC_MDM1    | E6                 | O        | GV <sub>DD</sub> | —     |
| MEMC_MDM2    | E18                | O        | GV <sub>DD</sub> | —     |
| MEMC_MDM3    | E20                | O        | GV <sub>DD</sub> | —     |
| MEMC_MDQS[0] | A7                 | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQS[1] | E7                 | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQS[2] | B19                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MDQS[3] | A23                | IO       | GV <sub>DD</sub> | —     |
| MEMC_MBA[0]  | D15                | O        | GV <sub>DD</sub> | —     |
| MEMC_MBA[1]  | A18                | O        | GV <sub>DD</sub> | —     |
| MEMC_MBA[2]  | A15                | O        | GV <sub>DD</sub> | —     |
| MEMC_MA0     | E12                | O        | GV <sub>DD</sub> | —     |
| MEMC_MA1     | D11                | O        | GV <sub>DD</sub> | —     |
| MEMC_MA2     | B11                | O        | GV <sub>DD</sub> | —     |
| MEMC_MA3     | A11                | O        | GV <sub>DD</sub> | —     |
| MEMC_MA4     | A12                | O        | GV <sub>DD</sub> | —     |
| MEMC_MA5     | E13                | O        | GV <sub>DD</sub> | —     |
| MEMC_MA6     | C12                | O        | GV <sub>DD</sub> | —     |
| MEMC_MA7     | E14                | O        | GV <sub>DD</sub> | —     |
| MEMC_MA8     | B15                | O        | GV <sub>DD</sub> | —     |
| MEMC_MA9     | C17                | O        | GV <sub>DD</sub> | —     |
| MEMC_MA10    | C13                | O        | GV <sub>DD</sub> | —     |
| MEMC_MA11    | A16                | O        | GV <sub>DD</sub> | —     |
| MEMC_MA12    | C15                | O        | GV <sub>DD</sub> | —     |
| MEMC_MA13    | C16                | O        | GV <sub>DD</sub> | —     |
| MEMC_MA14    | E15                | O        | GV <sub>DD</sub> | —     |
| MEMC_MWE     | B18                | O        | GV <sub>DD</sub> | —     |
| MEMC_MRAS    | C11                | O        | GV <sub>DD</sub> | —     |
| MEMC_MCAS    | B10                | O        | GV <sub>DD</sub> | —     |

Table 60. MPC8313E TEPBGAI Pinout Listing (continued)

| Signal                                | Package Pin Number | Pin Type | Power Supply     | Notes |
|---------------------------------------|--------------------|----------|------------------|-------|
| MEMC_MCS[0]                           | D10                | O        | GV <sub>DD</sub> | —     |
| MEMC_MCS[1]                           | A10                | O        | GV <sub>DD</sub> | —     |
| MEMC_MCKE                             | B14                | O        | GV <sub>DD</sub> | 3     |
| MEMC_MCK                              | A13                | O        | GV <sub>DD</sub> | —     |
| $\overline{\text{MEMC\_MCK}}$         | A14                | O        | GV <sub>DD</sub> | —     |
| MEMC_MODT[0]                          | B23                | O        | GV <sub>DD</sub> | —     |
| MEMC_MODT[1]                          | C23                | O        | GV <sub>DD</sub> | —     |
| <b>Local Bus Controller Interface</b> |                    |          |                  |       |
| LAD0                                  | K25                | IO       | LV <sub>DD</sub> | —     |
| LAD1                                  | K24                | IO       | LV <sub>DD</sub> | —     |
| LAD2                                  | K23                | IO       | LV <sub>DD</sub> | —     |
| LAD3                                  | K22                | IO       | LV <sub>DD</sub> | —     |
| LAD4                                  | J25                | IO       | LV <sub>DD</sub> | —     |
| LAD5                                  | J24                | IO       | LV <sub>DD</sub> | —     |
| LAD6                                  | J23                | IO       | LV <sub>DD</sub> | —     |
| LAD7                                  | J22                | IO       | LV <sub>DD</sub> | —     |
| LAD8                                  | H24                | IO       | LV <sub>DD</sub> | —     |
| LAD9                                  | F26                | IO       | LV <sub>DD</sub> | —     |
| LAD10                                 | G24                | IO       | LV <sub>DD</sub> | —     |
| LAD11                                 | F25                | IO       | LV <sub>DD</sub> | —     |
| LAD12                                 | E25                | IO       | LV <sub>DD</sub> | —     |
| LAD13                                 | F24                | IO       | LV <sub>DD</sub> | —     |
| LAD14                                 | G22                | IO       | LV <sub>DD</sub> | —     |
| LAD15                                 | F23                | IO       | LV <sub>DD</sub> | —     |
| LA16                                  | AC25               | O        | LV <sub>DD</sub> | —     |
| LA17                                  | AC26               | O        | LV <sub>DD</sub> | —     |
| LA18                                  | AB22               | O        | LV <sub>DD</sub> | —     |
| LA19                                  | AB23               | O        | LV <sub>DD</sub> | —     |
| LA20                                  | AB24               | O        | LV <sub>DD</sub> | —     |
| LA21                                  | AB25               | O        | LV <sub>DD</sub> | —     |
| LA22                                  | AB26               | O        | LV <sub>DD</sub> | —     |
| LA23                                  | E22                | O        | LV <sub>DD</sub> | —     |
| LA24                                  | E23                | O        | LV <sub>DD</sub> | —     |

Table 60. MPC8313E TEPBGAI Pinout Listing (continued)

| Signal                       | Package Pin Number | Pin Type | Power Supply     | Notes |
|------------------------------|--------------------|----------|------------------|-------|
| LA25                         | D22                | O        | LV <sub>DD</sub> | —     |
| $\overline{\text{LCS}}[0]$   | D23                | O        | LV <sub>DD</sub> | —     |
| $\overline{\text{LCS}}[1]$   | J26                | O        | LV <sub>DD</sub> | —     |
| $\overline{\text{LCS}}[2]$   | F22                | O        | LV <sub>DD</sub> | —     |
| $\overline{\text{LCS}}[3]$   | D26                | O        | LV <sub>DD</sub> | —     |
| $\overline{\text{LWE}}[0]$   | E24                | O        | LV <sub>DD</sub> | —     |
| $\overline{\text{LWE}}[1]$   | H26                | O        | LV <sub>DD</sub> | —     |
| LBCTL                        | L22                | O        | LV <sub>DD</sub> | —     |
| LALE/M1LALE/M2LALE           | E26                | O        | LV <sub>DD</sub> | —     |
| LGPL0                        | AA23               | O        | LV <sub>DD</sub> | —     |
| LGPL1                        | AA24               | O        | LV <sub>DD</sub> | —     |
| LGPL2                        | AA25               | O        | LV <sub>DD</sub> | —     |
| LGPL3                        | AA26               | O        | LV <sub>DD</sub> | —     |
| LGPL4                        | Y22                | IO       | LV <sub>DD</sub> | —     |
| LGPL5                        | E21                | O        | LV <sub>DD</sub> | —     |
| LCLK0                        | H22                | O        | LV <sub>DD</sub> | —     |
| LCLK1                        | G26                | O        | LV <sub>DD</sub> | —     |
| LA0/GPIO[0]                  | AC24               | IO       | LV <sub>DD</sub> | —     |
| LA1/GPIO[1]                  | Y24                | IO       | LV <sub>DD</sub> | —     |
| LA2/GPIO[2]                  | Y26                | IO       | LV <sub>DD</sub> | —     |
| LA3/GPIO[3]                  | W22                | IO       | LV <sub>DD</sub> | —     |
| LA4/GPIO[4]                  | W24                | IO       | LV <sub>DD</sub> | —     |
| LA5/GPIO[5]                  | W26                | IO       | LV <sub>DD</sub> | —     |
| LA6/GPIO[6]                  | V22                | IO       | LV <sub>DD</sub> | —     |
| LA7/GPIO[7]/TSEC_TMR_TRIG2   | V23                | IO       | LV <sub>DD</sub> | 8     |
| LA8/GPIO[13]/TSEC_TMR_ALARM1 | V24                | IO       | LV <sub>DD</sub> | 8     |
| LA9/GPIO[14]/TSEC_TMR_PP3    | V25                | IO       | LV <sub>DD</sub> | 8     |
| LA10/TSEC_TMR_CLK            | V26                | O        | LV <sub>DD</sub> | 8     |
| LA11/TSEC_TMR_GCLK           | U22                | O        | LV <sub>DD</sub> | 8     |
| LA12/TSEC_TMR_PP1            | AD24               | O        | LV <sub>DD</sub> | 8     |
| LA13/TSEC_TMR_PP2            | L25                | O        | LV <sub>DD</sub> | 8     |
| LA14/TSEC_TMR_TRIG1          | L24                | O        | LV <sub>DD</sub> | 8     |
| LA15/TSEC_TMR_ALARM2         | K26                | O        | LV <sub>DD</sub> | 8     |
| DUART                        |                    |          |                  |       |

Table 60. MPC8313E TEPBGAI Pinout Listing (continued)

| Signal                                                            | Package Pin Number | Pin Type | Power Supply     | Notes |
|-------------------------------------------------------------------|--------------------|----------|------------------|-------|
| UART_SOUT1/MSRCID0                                                | N2                 | O        | NV <sub>DD</sub> | —     |
| UART_SIN1/MSRCID1                                                 | M5                 | IO       | NV <sub>DD</sub> | —     |
| UART_CTS[1]/GPIO[8]/MSRCID2                                       | M1                 | IO       | NV <sub>DD</sub> | —     |
| UART_RTS[1]/GPIO[9]/MSRCID3                                       | K1                 | IO       | NV <sub>DD</sub> | —     |
| UART_SOUT2/MSRCID4/TSEC_TMR_CLK                                   | M3                 | O        | NV <sub>DD</sub> | 8     |
| UART_SIN2/MDVAL/TSEC_TMR_GCLK                                     | L1                 | IO       | NV <sub>DD</sub> | 8     |
| UART_CTS[2]/TSEC_TMR_PP1                                          | L5                 | IO       | NV <sub>DD</sub> | 8     |
| UART_RTS[2]/TSEC_TMR_PP2                                          | L3                 | IO       | NV <sub>DD</sub> | 8     |
| <b>I<sup>2</sup>C interface</b>                                   |                    |          |                  |       |
| IIC1_SDA/ $\overline{\text{CKSTOP\_OUT}}$ /TSEC_TMR_TRIG1         | J4                 | IO       | NV <sub>DD</sub> | 2, 8  |
| IIC1_SCL/ $\overline{\text{CKSTOP\_IN}}$ /TSEC_TMR_ALARM2         | J2                 | IO       | NV <sub>DD</sub> | 2, 8  |
| IIC2_SDA/PMC_PWR_OK/GPIO[10]                                      | J3                 | IO       | NV <sub>DD</sub> | 2     |
| IIC2_SCL/GPIO[11]                                                 | H5                 | IO       | NV <sub>DD</sub> | 2     |
| <b>Interrupts</b>                                                 |                    |          |                  |       |
| $\overline{\text{MCP\_OUT}}$                                      | G5                 | O        | NV <sub>DD</sub> | 2     |
| $\overline{\text{IRQ}}[0]/\text{MCP\_IN}$                         | K5                 | I        | NV <sub>DD</sub> | —     |
| $\overline{\text{IRQ}}[1]$                                        | K4                 | I        | NV <sub>DD</sub> | —     |
| $\overline{\text{IRQ}}[2]$                                        | K2                 | I        | NV <sub>DD</sub> | —     |
| $\overline{\text{IRQ}}[3]/\overline{\text{CKSTOP\_OUT}}$          | K3                 | IO       | NV <sub>DD</sub> | —     |
| $\overline{\text{IRQ}}[4]/\overline{\text{CKSTOP\_IN}}$ /GPIO[12] | J1                 | IO       | NV <sub>DD</sub> | —     |
| <b>Configuration</b>                                              |                    |          |                  |       |
| $\overline{\text{CFG\_CLKIN\_DIV}}$                               | D5                 | I        | NV <sub>DD</sub> | —     |
| EXT_PWR_CTRL                                                      | J5                 | O        | NV <sub>DD</sub> | —     |
| CFG_LBIU_MUX_EN                                                   | R24                | I        | NV <sub>DD</sub> | —     |
| <b>JTAG</b>                                                       |                    |          |                  |       |
| TCK                                                               | E1                 | I        | NV <sub>DD</sub> | —     |
| TDI                                                               | E2                 | I        | NV <sub>DD</sub> | 4     |
| TDO                                                               | E3                 | O        | NV <sub>DD</sub> | 3     |
| TMS                                                               | E4                 | I        | NV <sub>DD</sub> | 4     |
| $\overline{\text{TRST}}$                                          | E5                 | I        | NV <sub>DD</sub> | 4     |
| <b>TEST</b>                                                       |                    |          |                  |       |
| TEST_MODE                                                         | F4                 | I        | NV <sub>DD</sub> | 6     |
| <b>DEBUG</b>                                                      |                    |          |                  |       |

Table 60. MPC8313E TEPBGAI Pinout Listing (continued)

| Signal                              | Package Pin Number | Pin Type | Power Supply     | Notes |
|-------------------------------------|--------------------|----------|------------------|-------|
| $\overline{\text{QUIESCE}}$         | F5                 | O        | NV <sub>DD</sub> | —     |
| <b>System Control</b>               |                    |          |                  |       |
| $\overline{\text{HRESET}}$          | F2                 | IO       | NV <sub>DD</sub> | 1     |
| $\overline{\text{PORESET}}$         | F3                 | I        | NV <sub>DD</sub> | —     |
| $\overline{\text{SRESET}}$          | F1                 | I        | NV <sub>DD</sub> | —     |
| <b>Clocks</b>                       |                    |          |                  |       |
| SYS_CR_CLK_IN                       | U26                | I        | NV <sub>DD</sub> | —     |
| SYS_CR_CLK_OUT                      | U25                | O        | NV <sub>DD</sub> | —     |
| SYS_CLK_IN                          | U23                | I        | NV <sub>DD</sub> | —     |
| USB_CR_CLK_IN                       | T26                | I        | NV <sub>DD</sub> | —     |
| USB_CR_CLK_OUT                      | R26                | O        | NV <sub>DD</sub> | —     |
| USB_CLK_IN                          | T22                | I        | NV <sub>DD</sub> | —     |
| PCI_SYNC_OUT                        | U24                | O        | NV <sub>DD</sub> | 3     |
| RTC_PIT_CLOCK                       | R22                | I        | NV <sub>DD</sub> | —     |
| PCI_SYNC_IN                         | T24                | I        | NV <sub>DD</sub> | —     |
| <b>MISC</b>                         |                    |          |                  |       |
| THERM0                              | N1                 | I        | NV <sub>DD</sub> | 7     |
| THERM1                              | N3                 | I        | NV <sub>DD</sub> | 7     |
| <b>PCI</b>                          |                    |          |                  |       |
| $\overline{\text{PCI\_INTA}}$       | AF7                | O        | NV <sub>DD</sub> | —     |
| $\overline{\text{PCI\_RESET\_OUT}}$ | AB11               | O        | NV <sub>DD</sub> | —     |
| PCI_AD[0]                           | AB20               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[1]                           | AF23               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[2]                           | AF22               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[3]                           | AB19               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[4]                           | AE22               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[5]                           | AF21               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[6]                           | AD19               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[7]                           | AD20               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[8]                           | AC18               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[9]                           | AD18               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[10]                          | AB18               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[11]                          | AE19               | IO       | NV <sub>DD</sub> | —     |

Table 60. MPC8313E TEPBGAI Pinout Listing (continued)

| Signal                            | Package Pin Number | Pin Type | Power Supply     | Notes |
|-----------------------------------|--------------------|----------|------------------|-------|
| PCI_AD[12]                        | AB17               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[13]                        | AE18               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[14]                        | AD17               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[15]                        | AF19               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[16]                        | AB14               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[17]                        | AF15               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[18]                        | AD14               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[19]                        | AE14               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[20]                        | AF12               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[21]                        | AE11               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[22]                        | AD12               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[23]                        | AB13               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[24]                        | AF9                | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[25]                        | AD11               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[26]                        | AE10               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[27]                        | AB12               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[28]                        | AD10               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[29]                        | AC10               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[30]                        | AF10               | IO       | NV <sub>DD</sub> | —     |
| PCI_AD[31]                        | AF8                | IO       | NV <sub>DD</sub> | —     |
| PCI_C/ $\overline{\text{BE}}$ [0] | AC19               | IO       | NV <sub>DD</sub> | —     |
| PCI_C/ $\overline{\text{BE}}$ [1] | AB15               | IO       | NV <sub>DD</sub> | —     |
| PCI_C/ $\overline{\text{BE}}$ [2] | AF14               | IO       | NV <sub>DD</sub> | —     |
| PCI_C/ $\overline{\text{BE}}$ [3] | AF11               | IO       | NV <sub>DD</sub> | —     |
| PCI_PAR                           | AD16               | IO       | NV <sub>DD</sub> | —     |
| PCI_FRAME                         | AF16               | IO       | NV <sub>DD</sub> | 5     |
| PCI_TRDY                          | AD13               | IO       | NV <sub>DD</sub> | 5     |
| PCI_IRDY                          | AC15               | IO       | NV <sub>DD</sub> | 5     |
| PCI_STOP                          | AF13               | IO       | NV <sub>DD</sub> | 5     |
| PCI_DEVSEL                        | AC14               | IO       | NV <sub>DD</sub> | 5     |
| PCI_IDSEL                         | AF20               | I        | NV <sub>DD</sub> | —     |
| PCI_SERR                          | AE15               | IO       | NV <sub>DD</sub> | 5     |
| PCI_PERR                          | AD15               | IO       | NV <sub>DD</sub> | 5     |
| PCI_REQ0                          | AB10               | IO       | NV <sub>DD</sub> | —     |

Table 60. MPC8313E TEPBGAI Pinout Listing (continued)

| Signal                                     | Package Pin Number | Pin Type | Power Supply      | Notes |
|--------------------------------------------|--------------------|----------|-------------------|-------|
| PCI_REQ1/CPCI_HS_ES                        | AD9                | I        | NV <sub>DD</sub>  | —     |
| PCI_REQ2                                   | AD8                | I        | NV <sub>DD</sub>  | —     |
| PCI_GNT0                                   | AC11               | IO       | NV <sub>DD</sub>  | —     |
| PCI_GNT1/CPCI_HS_LED                       | AE7                | O        | NV <sub>DD</sub>  | —     |
| PCI_GNT2/CPCI_HS_ENUM                      | AD7                | O        | NV <sub>DD</sub>  | —     |
| M66EN                                      | AD21               | I        | NV <sub>DD</sub>  | —     |
| PCI_CLK0                                   | AF17               | O        | NV <sub>DD</sub>  | —     |
| PCI_CLK1                                   | AB16               | O        | NV <sub>DD</sub>  | —     |
| PCI_CLK2                                   | AF18               | O        | NV <sub>DD</sub>  | —     |
| PCI_PME                                    | AD22               | IO       | NV <sub>DD</sub>  | —     |
| <b>ETSEC1/_USBULPI</b>                     |                    |          |                   |       |
| TSEC1_COL/USBD_R_TXDRXD0                   | AD2                | IO       | LV <sub>DDB</sub> | —     |
| TSEC1_CRS/USBD_R_TXDRXD1                   | AC3                | IO       | LV <sub>DDB</sub> | —     |
| TSEC1_GTX_CLK/USBD_R_TXDRXD2               | AF3                | IO       | LV <sub>DDB</sub> | 3     |
| TSEC1_RX_CLK/USBD_R_TXDRXD3                | AE3                | IO       | LV <sub>DDB</sub> | —     |
| TSEC1_RX_DV/USBD_R_TXDRXD4                 | AD3                | IO       | LV <sub>DDB</sub> | —     |
| TSEC1_RXD[3]/USBD_R_TXDRXD5                | AC6                | IO       | LV <sub>DDB</sub> | —     |
| TSEC1_RXD[2]/USBD_R_TXDRXD6                | AF4                | IO       | LV <sub>DDB</sub> | —     |
| TSEC1_RXD[1]/USBD_R_TXDRXD7                | AB6                | IO       | LV <sub>DDB</sub> | —     |
| TSEC1_RXD[0]/USBD_R_NXT/TSEC_1588_TRIG1    | AB5                | I        | LV <sub>DDB</sub> | —     |
| TSEC1_RX_ER/USBD_R_DIR/TSEC_1588_TRIG2     | AD4                | I        | LV <sub>DDB</sub> | —     |
| TSEC1_TX_CLK/USBD_R_CLK/TSEC_1588_CLK      | AF5                | I        | LV <sub>DDB</sub> | —     |
| TSEC1_TXD[3]/TSEC_1588_GCLK                | AE6                | O        | LV <sub>DDB</sub> | —     |
| TSEC1_TXD[2]/TSEC_1588_PP1                 | AC7                | O        | LV <sub>DDB</sub> | —     |
| TSEC1_TXD[1]/TSEC_1588_PP2                 | AD6                | O        | LV <sub>DDB</sub> | —     |
| TSEC1_TXD[0]/USBD_R_STP/TSEC_1588_PP3      | AD5                | O        | LV <sub>DDB</sub> | —     |
| TSEC1_TX_EN/TSEC_1588_ALARM1               | AB7                | O        | LV <sub>DDB</sub> | —     |
| TSEC1_TX_ER/TSEC_1588_ALARM2               | AB8                | O        | LV <sub>DDB</sub> | —     |
| TSEC1_GTX_CLK125                           | AE1                | I        | LV <sub>DDB</sub> | —     |
| TSEC1_MDC/LB_POR_CFG_BOOT_ECC_DIS          | AF6                | O        | NV <sub>DD</sub>  | —     |
| TSEC1_MDIO                                 | AB9                | IO       | NV <sub>DD</sub>  | 2     |
| <b>ETSEC2</b>                              |                    |          |                   |       |
| TSEC2_COL/GTM1_TIN4/GTM2_TIN3/GPIO[15]     | AB4                | IO       | LV <sub>DDA</sub> | —     |
| TSEC2_CRS/GTM1_TGATE4/GTM2_TGATE3/GPIO[16] | AB3                | IO       | LV <sub>DDA</sub> | —     |

Table 60. MPC8313E TEPBGAI Pinout Listing (continued)

| Signal                                       | Package Pin Number | Pin Type | Power Supply        | Notes |
|----------------------------------------------|--------------------|----------|---------------------|-------|
| TSEC2_GTX_CLK/GTM1_TOUT4/GTM2_TOUT3/GPIO[17] | AC1                | IO       | LV <sub>DDA</sub>   | —     |
| TSEC2_RX_CLK/GTM1_TIN2/GTM2_TIN1/GPIO[18]    | AC2                | IO       | LV <sub>DDA</sub>   | —     |
| TSEC2_RX_DV/GTM1_TGATE2/GTM2_TGATE1/GPIO[19] | AA3                | IO       | LV <sub>DDA</sub>   | —     |
| TSEC2_RXD[3]/GPIO[20]                        | Y5                 | IO       | LV <sub>DDA</sub>   | —     |
| TSEC2_RXD[2]/GPIO[21]                        | AA4                | IO       | LV <sub>DDA</sub>   | —     |
| TSEC2_RXD[1]/GPIO[22]                        | AB2                | IO       | LV <sub>DDA</sub>   | —     |
| TSEC2_RXD[0]/GPIO[23]                        | AA5                | IO       | LV <sub>DDA</sub>   | —     |
| TSEC2_RX_ER/GTM1_TOUT2/GTM2_TOUT1/GPIO[24]   | AA2                | IO       | LV <sub>DDA</sub>   | —     |
| TSEC2_TX_CLK/GPIO[25]                        | AB1                | IO       | LV <sub>DDA</sub>   | —     |
| TSEC2_TXD[3]/CFG_RESET_SOURCE[0]             | W3                 | IO       | LV <sub>DDA</sub>   | —     |
| TSEC2_TXD[2]/CFG_RESET_SOURCE[1]             | Y1                 | IO       | LV <sub>DDA</sub>   | —     |
| TSEC2_TXD[1]/CFG_RESET_SOURCE[2]             | W5                 | IO       | LV <sub>DDA</sub>   | —     |
| TSEC2_TXD[0]/CFG_RESET_SOURCE[3]             | Y3                 | IO       | LV <sub>DDA</sub>   | —     |
| TSEC2_TX_EN/GPIO[26]                         | AA1                | IO       | LV <sub>DDA</sub>   | —     |
| TSEC2_TX_ER/GPIO[27]                         | W1                 | IO       | LV <sub>DDA</sub>   | —     |
| SGMII PHY                                    |                    |          |                     | —     |
| TXA                                          | U3                 | O        |                     | —     |
| $\overline{\text{TXA}}$                      | V3                 | O        |                     | —     |
| RXA                                          | U1                 | I        |                     | —     |
| $\overline{\text{RXA}}$                      | V1                 | I        |                     | —     |
| TXB                                          | P4                 | O        |                     | —     |
| $\overline{\text{TXB}}$                      | N4                 | O        |                     | —     |
| RXB                                          | R1                 | I        |                     | —     |
| $\overline{\text{RXB}}$                      | P1                 | I        |                     | —     |
| SD_IMP_CAL_RX                                | V5                 | I        | 200 $\Omega$ to GND | —     |
| $\overline{\text{SD\_REF\_CLK}}$             | T5                 | I        |                     | —     |
| SD_REF_CLK                                   | T4                 | I        |                     | —     |
| SD_PLL_TPD                                   | T2                 | O        |                     | —     |
| SD_IMP_CAL_TX                                | N5                 | I        | 100 $\Omega$ to GND | —     |
| SDAVDD                                       | R5                 | IO       |                     | —     |
| SD_PLL_TPA_ANA                               | R4                 | O        |                     | —     |
| SDAVSS                                       | R3                 | IO       |                     | —     |

Table 60. MPC8313E TEPBGAI Pinout Listing (continued)

| Signal                                         | Package Pin Number                                                        | Pin Type                                               | Power Supply     | Notes |
|------------------------------------------------|---------------------------------------------------------------------------|--------------------------------------------------------|------------------|-------|
| <b>USB PHY</b>                                 |                                                                           |                                                        |                  |       |
| USB_DP                                         | P26                                                                       | IO                                                     |                  | —     |
| USB_DM                                         | N26                                                                       | IO                                                     |                  | —     |
| USB_VBUS                                       | P24                                                                       | IO                                                     |                  | —     |
| USB_TPA                                        | L26                                                                       | IO                                                     |                  | —     |
| USB_RBIAS                                      | M24                                                                       | IO                                                     |                  | —     |
| USB_PLL_PWR3                                   | M26                                                                       | IO                                                     |                  | —     |
| USB_PLL_GND                                    | N24                                                                       | IO                                                     |                  | —     |
| USB_PLL_PWR1                                   | N25                                                                       | IO                                                     |                  | —     |
| USB_VSSA_BIAS                                  | M25                                                                       | IO                                                     |                  | —     |
| USB_VDDA_BIAS                                  | M22                                                                       | IO                                                     |                  | —     |
| USB_VSSA                                       | N22                                                                       | IO                                                     |                  | —     |
| USB_VDDA                                       | P22                                                                       | IO                                                     |                  | —     |
| <b>GTM/USB</b>                                 |                                                                           |                                                        |                  |       |
| USBDR_DRIVE_VBUS/GTM1_TIN1/GTM2_TIN2/LSRCID0   | AD23                                                                      | IO                                                     | NV <sub>DD</sub> | —     |
| USBDR_PWRFAULT/GTM1_TGATE1/GTM2_TGATE2/LSRCID1 | AE23                                                                      | IO                                                     | NV <sub>DD</sub> | —     |
| USBDR_PCTL0/GTM1_TOUT1/LSRCID2                 | AC22                                                                      | O                                                      | NV <sub>DD</sub> | —     |
| USBDR_PCTL1/LBC_PM_REF_10/LSRCID3              | AB21                                                                      | O                                                      | NV <sub>DD</sub> | —     |
| <b>SPI</b>                                     |                                                                           |                                                        |                  |       |
| SPIMOSI/GTM1_TIN3/GTM2_TIN4/GPIO[28]           | H1                                                                        | IO                                                     | NV <sub>DD</sub> | —     |
| SPIMISO/GTM1_TGATE3/GTM2_TGATE4/GPIO[29]/LDVAL | H3                                                                        | IO                                                     | NV <sub>DD</sub> | —     |
| SPICLK/GTM1_TOUT3/GPIO[30]                     | G1                                                                        | IO                                                     | NV <sub>DD</sub> | —     |
| SPISEL/GPIO[31]                                | G3                                                                        | IO                                                     | NV <sub>DD</sub> | —     |
| <b>Power and Ground Supplies</b>               |                                                                           |                                                        |                  |       |
| AV <sub>DD1</sub>                              | F14                                                                       | Power for e300 core APLL (1.0 V)                       | —                | —     |
| AV <sub>DD2</sub>                              | P21                                                                       | Power for system APLL (1.0 V)                          | —                | —     |
| GV <sub>DD</sub>                               | A2,A3,A4,A24,A25,B3,B4,B5,B12,B13,B20,B21,B24,B25,B26,D1,D2,D8,D9,D16,D17 | Power for DDR1 and DDR2 DRAM I/O voltage (1.8 V/2.5 V) | —                | —     |

Table 60. MPC8313E TEPBGAI Pinout Listing (continued)

| Signal            | Package Pin Number                                                                                                         | Pin Type                                         | Power Supply | Notes |
|-------------------|----------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------|--------------|-------|
| LV <sub>DD</sub>  | D24,D25,G23,H23,R23,<br>T23,W25,Y25,<br>AA22,AC23                                                                          | Power for<br>local bus<br>(3.3 V)                | —            | —     |
| LV <sub>DDA</sub> | W2,Y2                                                                                                                      | Power for<br>eTSEC2<br>(2.5 V, 3.3 V)            | —            | —     |
| LV <sub>DDB</sub> | AC8,AC9,AE4,AE5                                                                                                            | Power for<br>eTSEC1<br>/USB DR<br>(2.5 V, 3.3 V) | —            | —     |
| MV <sub>REF</sub> | C14,D14                                                                                                                    | Reference<br>voltage signal<br>for DDR           | —            | —     |
| NV <sub>DD</sub>  | G4,H4,L2,M2,AC16,<br>AC17,AD25,AD26,AE12,<br>AE13,AE20,AE21,AE24,<br>AE25,AE26,AF24,<br>AF25                               | Standard I/O<br>voltage<br>(3.3 V)               | —            | —     |
| V <sub>DD</sub>   | K11,K12,K13,K14,K15,K<br>16,L10,L17,M10,M17,<br>N10,N17,U12,U13, ,                                                         | Power for<br>core (1.0 V)                        | —            | —     |
| V <sub>DDC</sub>  | F6,F10,F19,K6,K10,K17,<br>K21,P6,P10,P17,R10,<br>R17,T10,T17,U10,U11,<br>U14,U15,U16,U17,W6,<br>W21,AA6,AA10,AA14,<br>AA19 | Internal core<br>logic constant<br>power (1.0 V) | —            | —     |

Table 60. MPC8313E TEPBGAI Pinout Listing (continued)

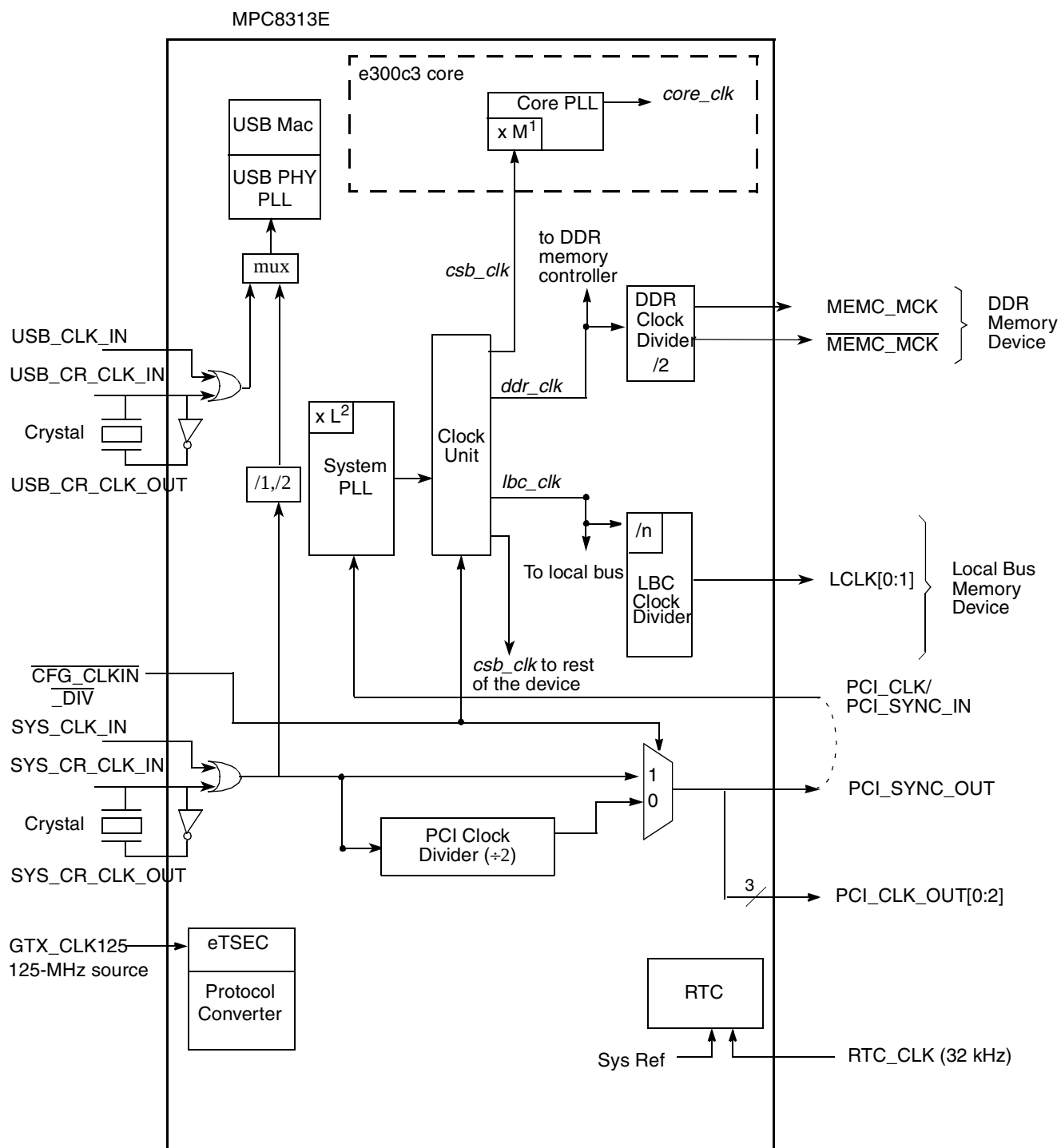
| Signal   | Package Pin Number                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              | Pin Type                                            | Power Supply | Notes |
|----------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------|--------------|-------|
| VSS      | B1,B2,B8,B9,B16,B17,<br>C1,C2,C3,C4,C5,C24,<br>C25,C26,D3,D4,D12,<br>D13,D20,D21,F8,F11,<br>F13,F16,F17,F21,G2,<br>G25,H2,H6,H21,H25,<br>L4,L6,L11,L12,L13,L14,<br>L15,L16,L21,L23,M4,<br>M11,M12,M13,M14,<br>M15,M16,M23,<br>N6,N11,N12,N13,<br>N14,N15,N16,N21,N23,<br>P11,P12,P13,P14,P15,<br>P16,P23,P25,R11,R12,<br>R13,R14,R15,R16,R25,<br>T6,T11,T12,T13,T14,<br>T15,T16,T21,T25,U5,<br>U6,U21,W4,W23,Y4,<br>Y23,AA8,AA11,AA13,<br>AA16,AA17,AA21,AC4,<br>AC5,AC12,AC13,AC20,<br>AC21,AD1,AE2,AE8,<br>AE9,AE16,AE17,AF2, | —                                                   | —            | —     |
| XCOREVDD | T1, U2, V2                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      | Core power<br>for SerDes<br>transceivers<br>(1.0 V) | —            | —     |
| XCOREVSS | P2, R2, T3                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      | —                                                   | —            | —     |
| XPADVDD  | P5, U4                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          | Pad power<br>for SerDes<br>transceivers<br>(1.0 V)  | —            | —     |
| XPADVSS  | P3, V4                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          | —                                                   | —            | —     |

**Notes:**

1. This pin is an open drain signal. A weak pull-up resistor (1 k $\Omega$ ) should be placed on this pin to NV<sub>DD</sub>.
2. This pin is an open drain signal. A weak pull-up resistor (2–10 k $\Omega$ ) should be placed on this pin to NV<sub>DD</sub>.
3. This output is actively driven during reset rather than being three-stated during reset.
4. These JTAG pins have weak internal pull-up P-FETs that are always enabled.
5. This pin should have a weak pull up if the chip is in PCI host mode. Follow PCI specifications recommendation.
6. This pin must always be tied to VSS.
7. Internal thermally sensitive resistor, resistor value varies linearly with temperature. Useful for determining the junction temperature.
8. CFG\_LBIU\_MUX\_EN must be asserted during power-on reset to select timer functionality.

# 19 Clocking

Figure 42 shows the internal distribution of clocks within the MPC8313E.



<sup>1</sup> Multiplication factor M = 1, 1.5, 2, 2.5, and 3. Value is decided by RCWLR[COREPLL].

<sup>2</sup> Multiplication factor L = 2, 3, 4, 5 and 6. Value is decided by RCWLR[SPMF].

**Figure 42. MPC8313E Clock Subsystem**

The primary clock source for the MPC8313E can be one of two inputs, SYS\_CLK\_IN or PCI\_CLK, depending on whether the device is configured in PCI host or PCI agent mode. When the device is configured as a PCI host device, SYS\_CLK\_IN is its primary input clock. SYS\_CLK\_IN feeds the PCI clock divider ( $\div 2$ ) and the multiplexors for PCI\_SYNC\_OUT and PCI\_CLK\_OUT. The CFG\_CLKIN\_DIV configuration input selects whether SYS\_CLK\_IN or SYS\_CLK\_IN/2 is driven out on the PCI\_SYNC\_OUT signal. The OCCR[PCICOE $n$ ] parameters select whether the PCI\_SYNC\_OUT is driven out on the PCI\_CLK\_OUT $n$  signals.

PCI\_SYNC\_OUT is connected externally to PCI\_SYNC\_IN to allow the internal clock subsystem to synchronize to the system PCI clocks. PCI\_SYNC\_OUT must be connected properly to PCI\_SYNC\_IN, with equal delay to all PCI agent devices in the system, to allow the device to function. When the device is configured as a PCI agent device, PCI\_CLK is the primary input clock. When the device is configured as a PCI agent device the SYS\_CLK\_IN signal should be tied to VSS.

As shown in Figure 42, the primary clock input (frequency) is multiplied up by the system phase-locked loop (PLL) and the clock unit to create the coherent system bus clock (*csb\_clk*), the internal clock for the DDR controller (*ddr\_clk*), and the internal clock for the local bus interface unit (*lbc\_clk*).

The *csb\_clk* frequency is derived from a complex set of factors that can be simplified into the following equation:

$$csb\_clk = \{PCI\_SYNC\_IN \times (1 + \sim CFG\_CLKIN\_DIV)\} \times SPMF$$

In PCI host mode,  $PCI\_SYNC\_IN \times (1 + \sim CFG\_CLKIN\_DIV)$  is the SYS\_CLK\_IN frequency.

The *csb\_clk* serves as the clock input to the e300 core. A second PLL inside the e300 core multiplies up the *csb\_clk* frequency to create the internal clock for the e300 core (*core\_clk*). The system and core PLL multipliers are selected by the SPMF and COREPLL fields in the reset configuration word low (RCWL) which is loaded at power-on reset or by one of the hard-coded reset options. See Chapter 4, “Reset, Clocking, and Initialization,” in the *MPC8313E PowerQUICC II Pro Integrated Host Processor Reference Manual* for more information on the clock subsystem.

The internal *ddr\_clk* frequency is determined by the following equation:

$$ddr\_clk = csb\_clk \times (1 + RCWL[DDRCM])$$

Note that *ddr\_clk* is not the external memory bus frequency; *ddr\_clk* passes through the DDR clock divider ( $\div 2$ ) to create the differential DDR memory bus clock outputs (MCK and  $\overline{MCK}$ ). However, the data rate is the same frequency as *ddr\_clk*.

The internal *lbc\_clk* frequency is determined by the following equation:

$$lbc\_clk = csb\_clk \times (1 + RCWL[LBCM])$$

Note that *lbc\_clk* is not the external local bus frequency; *lbc\_clk* passes through the a LBC clock divider to create the external local bus clock outputs (LCLK[0:1]). The LBC clock divider ratio is controlled by LCCR[CLKDIV].

In addition, some of the internal units may be required to be shut off or operate at lower frequency than the *csb\_clk* frequency. Those units have a default clock ratio that can be configured by a memory mapped register after the device comes out of reset. Table 61 specifies which units have a configurable clock frequency.

**Table 61. Configurable Clock Units**

| Unit                         | Default Frequency | Options                                                    |
|------------------------------|-------------------|------------------------------------------------------------|
| TSEC1                        | <i>csb_clk</i>    | Off, <i>csb_clk</i> , <i>csb_clk</i> /2, <i>csb_clk</i> /3 |
| TSEC2                        | <i>csb_clk</i>    | Off, <i>csb_clk</i> , <i>csb_clk</i> /2, <i>csb_clk</i> /3 |
| Security Core, I2C, SAP, TPR | <i>csb_clk</i>    | Off, <i>csb_clk</i> , <i>csb_clk</i> /2, <i>csb_clk</i> /3 |
| USB DR                       | <i>csb_clk</i>    | Off, <i>csb_clk</i> , <i>csb_clk</i> /2, <i>csb_clk</i> /3 |
| PCI and DMA complex          | <i>csb_clk</i>    | Off, <i>csb_clk</i>                                        |

[Table 62](#) provides the operating frequencies for the MPC8313E TEPBGA II under recommended operating conditions (see [Table 2](#)).

**Table 62. Operating Frequencies for TEPBGA II**

| Characteristic <sup>1</sup>                           | Max Operating Frequency | Unit |
|-------------------------------------------------------|-------------------------|------|
| e300 core frequency ( <i>core_clk</i> )               | 333                     | MHz  |
| Coherent system bus frequency ( <i>csb_clk</i> )      | 167                     | MHz  |
| DDR1/2 memory bus frequency (MCK) <sup>2</sup>        | 167                     | MHz  |
| Local bus frequency (LCLK <sub>n</sub> ) <sup>3</sup> | 66                      | MHz  |
| PCI input frequency (SYS_CLK_IN or PCI_CLK)           | 66                      | MHz  |

**Notes:**

1. The SYS\_CLK\_IN frequency, RCWL[SPMF], and RCWL[COREPLL] settings must be chosen such that the resulting *csb\_clk*, MCK, LCLK[0:1], and *core\_clk* frequencies do not exceed their respective maximum or minimum operating frequencies. The value of SCCR[ENCCM] and SCCR[USBDRCM] must be programmed such that the maximum internal operating frequency of the Security core and USB modules do not exceed their respective value listed in this table.
2. The DDR data rate is 2x the DDR memory bus frequency.
3. The local bus frequency is 1/2, 1/4, or 1/8 of the *lbc\_clk* frequency (depending on LCCR[CLKDIV]) which is in turn 1x or 2x the *csb\_clk* frequency (depending on RCWL[LBCM]).

## 19.1 System PLL Configuration

The system PLL is controlled by the RCWL[SPMF] parameter. Table 63 shows the multiplication factor encodings for the system PLL.

**Table 63. System PLL Multiplication Factors**

| RCWL[SPMF] | System PLL Multiplication Factor |
|------------|----------------------------------|
| 0000       | Reserved                         |
| 0001       | Reserved                         |
| 0010       | $\times 2$                       |
| 0011       | $\times 3$                       |
| 0100       | $\times 4$                       |
| 0101       | $\times 5$                       |
| 0110       | $\times 6$                       |
| 0111–1111  | Reserved                         |

As described in Section 19, “Clocking,” The LBCM, DDRCM, and SPMF parameters in the reset configuration word low and the CFG\_CLKIN\_DIV configuration input signal select the ratio between the primary clock input (SYS\_CLK\_IN or PCI\_SYNC\_IN) and the internal coherent system bus clock (*csb\_clk*). Table 64 shows the expected frequency values for the CSB frequency for select *csb\_clk* to SYS\_CLK\_IN/PCI\_SYNC\_IN ratios.

**Table 64. CSB Frequency Options**

| CFG_CLKIN_DIV at reset <sup>1</sup> | SPMF | <i>csb_clk</i> :Input Clock Ratio <sup>2</sup> | Input Clock Frequency (MHz) <sup>2</sup> |     |       |       |
|-------------------------------------|------|------------------------------------------------|------------------------------------------|-----|-------|-------|
|                                     |      |                                                | 24                                       | 25  | 33.33 | 66.67 |
|                                     |      |                                                | <i>csb_clk</i> Frequency (MHz)           |     |       |       |
| High                                | 0010 | 2 : 1                                          |                                          |     |       | 133   |
| High                                | 0011 | 3 : 1                                          |                                          |     | 100   |       |
| High                                | 0100 | 4 : 1                                          |                                          | 100 | 133   |       |
| High                                | 0101 | 5 : 1                                          | 120                                      | 125 | 167   |       |
| High                                | 0110 | 6 : 1                                          | 144                                      | 150 |       |       |
| Low                                 | 0010 | 2 : 1                                          |                                          |     |       | 133   |
| Low                                 | 0011 | 3 : 1                                          |                                          |     | 100   |       |
| Low                                 | 0100 | 4 : 1                                          |                                          | 100 | 133   |       |

Table 64. CSB Frequency Options (continued)

| CFG_CLKIN_DIV at reset <sup>1</sup> | SPMF | csb_clk : Input Clock Ratio <sup>2</sup> | Input Clock Frequency (MHz) <sup>2</sup> |     |       |       |
|-------------------------------------|------|------------------------------------------|------------------------------------------|-----|-------|-------|
|                                     |      |                                          | 24                                       | 25  | 33.33 | 66.67 |
|                                     |      |                                          | csb_clk Frequency (MHz)                  |     |       |       |
| Low                                 | 0101 | 5 : 1                                    | 120                                      | 125 | 167   |       |
| Low                                 | 0110 | 6 : 1                                    | 144                                      | 150 |       |       |

<sup>1</sup> CFG\_CLKIN\_DIV select the ratio between SYS\_CLK\_IN and PCI\_SYNC\_OUT.

<sup>2</sup> SYS\_CLK\_IN is the input clock in host mode; PCI\_CLK is the input clock in agent mode.

## 19.2 Core PLL Configuration

RCWL[COREPLL] selects the ratio between the internal coherent system bus clock (*csb\_clk*) and the e300 core clock (*core\_clk*). Table 65 shows the encodings for RCWL[COREPLL]. COREPLL values that are not listed in Table 65 should be considered as reserved.

### NOTE

Core VCO frequency = Core frequency × VCO divider. The VCO divider, which is determined by RCWL[COREPLL], must be set properly so that the core VCO frequency is in the range of 400–800 MHz.

Table 65. e300 Core PLL Configuration

| RCWL[COREPLL] |      |   | core_clk : csb_clk Ratio <sup>1</sup>                          | VCO divider (vcod) <sup>2</sup>                                |
|---------------|------|---|----------------------------------------------------------------|----------------------------------------------------------------|
| 0–1           | 2–5  | 6 |                                                                |                                                                |
| nn            | 0000 | 0 | PLL bypassed<br>(PLL off, <i>csb_clk</i> clocks core directly) | PLL bypassed<br>(PLL off, <i>csb_clk</i> clocks core directly) |
| 11            | nnnn | n | n/a                                                            | n/a                                                            |
| 00            | 0001 | 0 | 1:1                                                            | 2                                                              |
| 01            | 0001 | 0 | 1:1                                                            | 4                                                              |
| 10            | 0001 | 0 | 1:1                                                            | 8                                                              |
| 00            | 0001 | 1 | 1.5:1                                                          | 2                                                              |
| 01            | 0001 | 1 | 1.5:1                                                          | 4                                                              |
| 10            | 0001 | 1 | 1.5:1                                                          | 8                                                              |
| 00            | 0010 | 0 | 2:1                                                            | 2                                                              |
| 01            | 0010 | 0 | 2:1                                                            | 4                                                              |
| 10            | 0010 | 0 | 2:1                                                            | 8                                                              |
| 00            | 0010 | 1 | 2.5:1                                                          | 2                                                              |
| 01            | 0010 | 1 | 2.5:1                                                          | 4                                                              |
| 10            | 0010 | 1 | 2.5:1                                                          | 8                                                              |

Table 65. e300 Core PLL Configuration (continued)

| RCWL[COREPLL] |      |   | core_clk : csb_clk Ratio <sup>1</sup> | VCO divider (vcod) <sup>2</sup> |
|---------------|------|---|---------------------------------------|---------------------------------|
| 0–1           | 2–5  | 6 |                                       |                                 |
| 00            | 0011 | 0 | 3:1                                   | 2                               |
| 01            | 0011 | 0 | 3:1                                   | 4                               |
| 10            | 0011 | 0 | 3:1                                   | 8                               |

<sup>1</sup> For core\_clk:csb\_clk ratios of 2.5:1 and 3:1, the core\_clk must not exceed its maximum operating frequency of 333 MHz.

<sup>2</sup> Core VCO frequency = Core frequency × VCO divider. Note that VCO divider has to be set properly so that the core VCO frequency is in the range of 400–800 MHz.

## 19.3 Example Clock Frequency Combinations

Table 66 shows several possible frequency combinations that can be selected based on the indicated input reference frequencies, with RCWLR[LBCM] = 0 and RCWLR[DDRCM] = 1, such that the LBC operates with a frequency equal to the frequency of csb\_clk and the DDR controller operates at twice the frequency of csb\_clk.

Table 66. System Clock Frequencies

|                        |                   |                   |                  |                               |                  | LBC(lbc_clk) |       |      |                         | e300 Core(core_clk) |       |     |       |     |
|------------------------|-------------------|-------------------|------------------|-------------------------------|------------------|--------------|-------|------|-------------------------|---------------------|-------|-----|-------|-----|
| SYS_CLK_IN/<br>PCI_CLK | SPMF <sup>1</sup> | vcod <sup>2</sup> | vco <sup>3</sup> | CSB<br>(csb_clk) <sup>4</sup> | DDR<br>(ddr_clk) | /2           | /4    | /8   | USB<br>ref <sup>5</sup> | × 1                 | × 1.5 | × 2 | × 2.5 | × 3 |
| 25.0                   | 6                 | 2                 | 600.0            | 150.0                         | 300.0            | —            | 37.5  | 18.8 | Note <sup>6</sup>       | 150.0               | 225   | 300 | 375   | —   |
| 25.0                   | 5                 | 2                 | 500.0            | 125.0                         | 250.0            | 62.5         | 31.25 | 15.6 | Note 6                  | 125.0               | 188   | 250 | 313   | 375 |
| 33.3                   | 5                 | 2                 | 666.0            | 166.5                         | 333.0            | —            | 41.63 | 20.8 | Note 6                  | 166.5               | 250   | 333 | —     | —   |
| 33.3                   | 4                 | 2                 | 532.8            | 133.2                         | 266.4            | 66.6         | 33.3  | 16.7 | Note 6                  | 133.2               | 200   | 266 | 333   | 400 |
| 48.0                   | 3                 | 2                 | 576.0            | 144.0                         | 288.0            | —            | 36    | 18.0 | 48.0                    | 144.0               | 216   | 288 | 360   | —   |
| 66.7                   | 2                 | 2                 | 533.4            | 133.3                         | 266.7            | 66.7         | 33.34 | 16.7 | Note 6                  | 133.3               | 200   | 267 | 333   | 400 |

<sup>1</sup> System PLL multiplication factor

<sup>2</sup> System PLL VCO divider

<sup>3</sup> When considering operating frequencies, the valid core VCO operating range of 400–800 MHz must not be violated.

<sup>4</sup> Due to erratum eTSEC40, csb\_clk frequencies of less than 133 MHz do not support Gigabit Ethernet data rates. The core frequency must be 333 MHz for Gigabit Ethernet operation. This erratum will be fixed in revision 2 silicon.

<sup>5</sup> Frequency of USB PLL input reference.

<sup>6</sup> USB reference clock must be supplied from a separate source as it must be 24 or 48 MHz, the USB reference must be supplied from a separate external source using USB\_CLK\_IN.

## 20 Thermal

This section describes the thermal specifications of the MPC8313E.

## 20.1 Thermal Characteristics

Table 67 provides the package thermal characteristics for the 516 27 × 27 mm TEPBGAI.

**Table 67. Package Thermal Characteristics for TEPBGAI**

| Characteristic                         | Board type              | Symbol           | TEPBGAI | Unit | Notes |
|----------------------------------------|-------------------------|------------------|---------|------|-------|
| Junction to Ambient Natural Convection | Single layer board (1s) | $R_{\theta JA}$  | 25      | °C/W | 1,2   |
| Junction to Ambient Natural Convection | Four layer board (2s2p) | $R_{\theta JA}$  | 18      | °C/W | 1,2,3 |
| Junction to Ambient (@200 ft/min)      | Single layer board (1s) | $R_{\theta JMA}$ | 20      | °C/W | 1,3   |
| Junction to Ambient (@200 ft/min)      | Four layer board (2s2p) | $R_{\theta JMA}$ | 15      | °C/W | 1,3   |
| Junction to Board                      | —                       | $R_{\theta JB}$  | 10      | °C/W | 4     |
| Junction to Case                       | —                       | $R_{\theta JC}$  | 8       | °C/W | 5     |
| Junction to Package Top                | Natural Convection      | $\Psi_{JT}$      | 7       | °C/W | 6     |

**Notes:**

1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
2. Per JEDEC JESD51-2 with the single layer board horizontal. Board meets JESD51-9 specification.
3. Per JEDEC JESD51-6 with the board horizontal.
4. Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
5. Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).
6. Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2. When Greek letters are not available, the thermal characterization parameter is written as Psi-JT.

## 20.2 Thermal Management Information

For the following sections,  $P_D = (V_{DD} \times I_{DD}) + P_{I/O}$  where  $P_{I/O}$  is the power dissipation of the I/O drivers.

### 20.2.1 Estimation of Junction Temperature with Junction-to-Ambient Thermal Resistance

An estimation of the chip junction temperature,  $T_J$ , can be obtained from the equation:

$$T_J = T_A + (R_{\theta JA} \times P_D)$$

where:

$T_J$  = junction temperature (°C)

$T_A$  = ambient temperature for the package (°C)

$R_{\theta JA}$  = junction to ambient thermal resistance (°C/W)

$P_D$  = power dissipation in the package (W)

The junction to ambient thermal resistance is an industry standard value that provides a quick and easy estimation of thermal performance. As a general statement, the value obtained on a single layer board is appropriate for a tightly packed printed circuit board. The value obtained on the board with the internal planes is usually appropriate if the board has low power dissipation and the components are well separated. Test cases have demonstrated that errors of a factor of two (in the quantity  $T_J - T_A$ ) are possible.

### 20.2.2 Estimation of Junction Temperature with Junction-to-Board Thermal Resistance

The thermal performance of a device cannot be adequately predicted from the junction to ambient thermal resistance. The thermal performance of any component is strongly dependent on the power dissipation of surrounding components. In addition, the ambient temperature varies widely within the application. For many natural convection and especially closed box applications, the board temperature at the perimeter (edge) of the package is approximately the same as the local air temperature near the device. Specifying the local ambient conditions explicitly as the board temperature provides a more precise description of the local ambient conditions that determine the temperature of the device.

At a known board temperature, the junction temperature is estimated using the following equation:

$$T_J = T_B + (R_{\theta JB} \times P_D)$$

where:

$T_J$  = junction temperature (°C)

$T_B$  = board temperature at the package perimeter (°C)

$R_{\theta JB}$  = junction to board thermal resistance (°C/W) per JESD51-8

$P_D$  = power dissipation in the package (W)

When the heat loss from the package case to the air can be ignored, acceptable predictions of junction temperature can be made. The application board should be similar to the thermal test condition: the component is soldered to a board with internal planes.

## 20.2.3 Experimental Determination of Junction Temperature

To determine the junction temperature of the device in the application after prototypes are available, the Thermal Characterization Parameter ( $\Psi_{JT}$ ) can be used to determine the junction temperature with a measurement of the temperature at the top center of the package case using the following equation:

$$T_J = T_T + (\Psi_{JT} \times P_D)$$

where:

$T_J$  = junction temperature (°C)

$T_T$  = thermocouple temperature on top of package (°C)

$\Psi_{JT}$  = thermal characterization parameter (°C/W)

$P_D$  = power dissipation in the package (W)

The thermal characterization parameter is measured per JESD51-2 specification using a 40 gauge type T thermocouple epoxied to the top center of the package case. The thermocouple should be positioned so that the thermocouple junction rests on the package. A small amount of epoxy is placed over the thermocouple junction and over about 1 mm of wire extending from the junction. The thermocouple wire is placed flat against the package case to avoid measurement errors caused by cooling effects of the thermocouple wire.

## 20.2.4 Heat Sinks and Junction-to-Case Thermal Resistance

In some application environments, a heat sink is required to provide the necessary thermal management of the device. When a heat sink is used, the thermal resistance is expressed as the sum of a junction to case thermal resistance and a case to ambient thermal resistance:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$$

where:

$R_{\theta JA}$  = junction to ambient thermal resistance (°C/W)

$R_{\theta JC}$  = junction to case thermal resistance (°C/W)

$R_{\theta CA}$  = case to ambient thermal resistance (°C/W)

$R_{\theta JC}$  is device related and cannot be influenced by the user. The user controls the thermal environment to change the case to ambient thermal resistance,  $R_{\theta CA}$ . For instance, the user can change the size of the heat sink, the air flow around the device, the interface material, the mounting arrangement on printed circuit board, or change the thermal dissipation on the printed circuit board surrounding the device.

To illustrate the thermal performance of the devices with heat sinks, the thermal performance has been simulated with a few commercially available heat sinks. The heat sink choice is determined by the application environment (temperature, air flow, adjacent component power dissipation) and the physical space available. Because there is not a standard application environment, a standard heat sink is not required.

**Table 68. Thermal Resistance for TEPBGAll with Heat Sink in Open Flow**

| Heat Sink Assuming Thermal Grease  | Air Flow           | Thermal Resistance (°C/W) |
|------------------------------------|--------------------|---------------------------|
| Wakefield 53 x 53 x 2.5 mm Pin Fin | Natural Convection | 13.0                      |
|                                    | 0.5 m/s            | 10.6                      |
|                                    | 1 m/s              | 9.7                       |
|                                    | 2 m/s              | 9.2                       |
|                                    | 4 m/s              | 8.9                       |
| Aavid 35 x 31 x 23 mm Pin Fin      | Natural Convection | 14.4                      |
|                                    | 0.5 m/s            | 11.3                      |
|                                    | 1 m/s              | 10.5                      |
|                                    | 2 m/s              | 9.9                       |
|                                    | 4 m/s              | 9.4                       |
| Aavid 30 x 30 x 9.4 mm Pin Fin     | Natural Convection | 16.5                      |
|                                    | 0.5 m/s            | 13.5                      |
|                                    | 1 m/s              | 12.1                      |
|                                    | 2 m/s              | 10.9                      |
|                                    | 4 m/s              | 10.0                      |
| Aavid 43 x 41 x 16.5 mm Pin Fin    | Natural Convection | 14.5                      |
|                                    | 0.5 m/s            | 11.7                      |
|                                    | 1 m/s              | 10.5                      |
|                                    | 2 m/s              | 9.7                       |
|                                    | 4 m/s              | 9.2                       |

Accurate thermal design requires thermal modeling of the application environment using computational fluid dynamics software which can model both the conduction cooling and the convection cooling of the air moving through the application. Simplified thermal models of the packages can be assembled using the junction-to-case and junction-to-board thermal resistances listed in the thermal resistance table. More detailed thermal models can be made available on request.

Heat sink Vendors include the following list:

|                                                                                |              |
|--------------------------------------------------------------------------------|--------------|
| Aavid Thermalloy                                                               | 603-224-9988 |
| 80 Commercial St.                                                              |              |
| Concord, NH 03301                                                              |              |
| Internet: <a href="http://www.aavidthermalloy.com">www.aavidthermalloy.com</a> |              |
| Alpha Novatech                                                                 | 408-749-7601 |
| 473 Sapena Ct. #12                                                             |              |
| Santa Clara, CA 95054                                                          |              |
| Internet: <a href="http://www.alphanovatech.com">www.alphanovatech.com</a>     |              |

## Thermal

|                                                                                                                                                                      |              |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------|
| International Electronic Research Corporation (IERC)<br>413 North Moss St.<br>Burbank, CA 91502<br>Internet: <a href="http://www.ctscorp.com">www.ctscorp.com</a>    | 818-842-7277 |
| Millennium Electronics (MEI)<br>Loroco Sites<br>671 East Brokaw Road<br>San Jose, CA 95112<br>Internet: <a href="http://www.mei-thermal.com">www.mei-thermal.com</a> | 408-436-8770 |
| Tyco Electronics<br>Chip Coolers™<br>P.O. Box 3668<br>Harrisburg, PA 17105<br>Internet: <a href="http://www.chipcoolers.com">www.chipcoolers.com</a>                 | 800-522-6752 |
| Wakefield Engineering<br>33 Bridge St.<br>Pelham, NH 03076<br>Internet: <a href="http://www.wakefield.com">www.wakefield.com</a>                                     | 603-635-2800 |

Interface material vendors include the following:

|                                                                                                                                                             |              |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------|
| Chomerics, Inc.<br>77 Dragon Ct.<br>Woburn, MA 01801<br>Internet: <a href="http://www.chomerics.com">www.chomerics.com</a>                                  | 781-935-4850 |
| Dow-Corning Corporation<br>Corporate Center<br>PO BOX 994<br>Midland, MI 48686-0994<br>Internet: <a href="http://www.dowcorning.com">www.dowcorning.com</a> | 800-248-2481 |
| Shin-Etsu MicroSi, Inc.<br>10028 S. 51st St.<br>Phoenix, AZ 85044<br>Internet: <a href="http://www.microsi.com">www.microsi.com</a>                         | 888-642-7674 |
| The Bergquist Company<br>18930 West 78th St.<br>Chanhassen, MN 55317<br>Internet: <a href="http://www.bergquistcompany.com">www.bergquistcompany.com</a>    | 800-347-4572 |

## 20.3 Heat Sink Attachment

When attaching heat sinks to these devices, an interface material is required. The best method is to use thermal grease and a spring clip. The spring clip should connect to the printed circuit board, either to the board itself, to hooks soldered to the board, or to a plastic stiffener. Avoid attachment forces which would lift the edge of the package or peel the package from the board. Such peeling forces reduce the solder joint lifetime of the package. Recommended maximum force on the top of the package is 10 lb (4.5 kg) force. If an adhesive attachment is planned, the adhesive should be intended for attachment to painted or plastic surfaces and its performance verified under the application requirements.

### 20.3.1 Experimental Determination of the Junction Temperature with a Heat Sink

When heat sink is used, the junction temperature is determined from a thermocouple inserted at the interface between the case of the package and the interface material. A clearance slot or hole is normally required in the heat sink. Minimizing the size of the clearance is important to minimize the change in thermal performance caused by removing part of the thermal interface to the heat sink. Because of the experimental difficulties with this technique, many engineers measure the heat sink temperature and then back calculate the case temperature using a separate measurement of the thermal resistance of the interface. From this case temperature, the junction temperature is determined from the junction to case thermal resistance.

$$T_J = T_C + (R_{\theta JC} \times P_D)$$

Where:

$T_J$  = junction temperature (°C)

$T_C$  = case temperature of the package

$R_{\theta JC}$  = junction-to-case thermal resistance

$P_D$  = power dissipation

## 21 System Design Information

This section provides electrical and thermal design recommendations for successful application of the MPC8313E SYS\_CLK\_IN

### 21.1 System Clocking

The MPC8313E includes three PLLs.

1. The platform PLL (AV<sub>DD2</sub>) generates the platform clock from the externally supplied SYS\_CLK\_IN input in PCI host mode or SYS\_CLK\_IN/PCI\_SYNC\_IN in PCI agent mode. The frequency ratio between the platform and SYS\_CLK\_IN is selected using the platform PLL ratio configuration bits as described in [Section 19.1, “System PLL Configuration.”](#)
2. The e300 Core PLL (AV<sub>DD1</sub>) generates the core clock as a slave to the platform clock. The frequency ratio between the e300 core clock and the platform clock is selected using the e300 PLL ratio configuration bits as described in [Section 19.2, “Core PLL Configuration.”](#)

- There is a PLL for the SerDes block.

## 21.2 PLL Power Supply Filtering

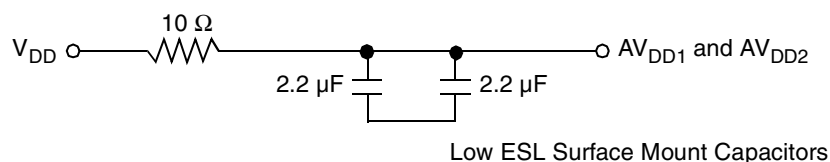
Each of the PLLs listed above is provided with power through independent power supply pins ( $AV_{DD1}$ ,  $AV_{DD2}$ , and  $SDAVDD$  respectively). The  $AV_{DD}$  level should always be equivalent to  $V_{DD}$ , and preferably these voltages are derived directly from  $V_{DD}$  through a low frequency filter scheme such as the following.

There are a number of ways to reliably provide power to the PLLs, but the recommended solution is to provide independent filter circuits as illustrated in Figure 43, one to each of the five  $AV_{DD}$  pins. By providing independent filters to each PLL the opportunity to cause noise injection from one PLL to the other is reduced.

This circuit is intended to filter noise in the PLLs resonant frequency range from a 500 kHz to 10 MHz range. It should be built with surface mount capacitors with minimum Effective Series Inductance (ESL). Consistent with the recommendations of Dr. Howard Johnson in *High Speed Digital Design: A Handbook of Black Magic* (Prentice Hall, 1993), multiple small capacitors of equal value are recommended over a single large value capacitor.

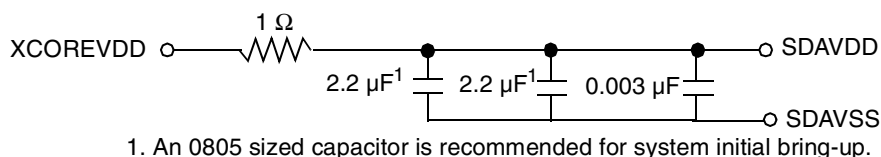
Each circuit should be placed as close as possible to the specific  $AV_{DD}$  pin being supplied to minimize noise coupled from nearby circuits. It should be possible to route directly from the capacitors to the  $AV_{DD}$  pin, which is on the periphery of package, without the inductance of vias.

Figure 43 shows the PLL power supply filter circuits.



**Figure 43. PLL Power Supply Filter Circuit**

The  $SDAVDD$  signal provides power for the analog portions of the SerDes PLL. To ensure stability of the internal clock, the power supplied to the PLL is filtered using a circuit like the one shown in Figure 44. For maximum effectiveness, the filter circuit should be placed as closely as possible to the  $SDAVDD$  ball to ensure it filters out as much noise as possible. The ground connection should be near the  $SDAVDD$  ball. The 0.003- $\mu$ F capacitor is closest to the ball, followed by the two 2.2- $\mu$ F capacitors, and finally the 1- $\Omega$  resistor to the board supply plane. The capacitors are connected from traces from  $SDAVDD$  to the ground plane. Use ceramic chip capacitors with the highest possible self-resonant frequency. All traces should be kept short, wide, and direct.



**Figure 44. SerDes PLL Power Supply Filter Circuit**

Note the following:

- SDAVDD should be a filtered version of XCOREVDD.
- Output signals on the SerDes interface are fed from the XPADVDD power plane. Input signals and sensitive transceiver analog circuits are on the XCOREVDD supply.
- Power: XPADVDD consumes less than 300 mW; XCOREVDD + SDAVDD consumes less than 750 mW.

## 21.3 Decoupling Recommendations

Due to large address and data buses, and high operating frequencies, the device can generate transient power surges and high frequency noise in its power supply, especially while driving large capacitive loads. This noise must be prevented from reaching other components in the MPC8313E system, and the MPC8313E itself requires a clean, tightly regulated source of power. Therefore, it is recommended that the system designer place at least one decoupling capacitor at each  $V_{DD}$ ,  $NV_{DD}$ ,  $GV_{DD}$ ,  $LV_{DD}$ ,  $LV_{DDA}$ , and  $LV_{DDB}$  pin of the device. These decoupling capacitors should receive their power from separate  $V_{DD}$ ,  $NV_{DD}$ ,  $GV_{DD}$ ,  $LV_{DD}$ ,  $LV_{DDA}$ ,  $LV_{DDB}$  and VSS power planes in the PCB, utilizing short traces to minimize inductance. Capacitors may be placed directly under the device using a standard escape pattern. Others may surround the part.

These capacitors should have a value of 0.01 or 0.1  $\mu\text{F}$ . Only ceramic SMT (surface mount technology) capacitors should be used to minimize lead inductance, preferably 0402 or 0603 sizes.

In addition, it is recommended that there be several bulk storage capacitors distributed around the PCB, feeding the  $V_{DD}$ ,  $NV_{DD}$ ,  $GV_{DD}$ ,  $LV_{DD}$ ,  $LV_{DDA}$ , and  $LV_{DDB}$  planes, to enable quick recharging of the smaller chip capacitors. These bulk capacitors should have a low ESR (equivalent series resistance) rating to ensure the quick response time necessary. They should also be connected to the power and ground planes through two vias to minimize inductance. Suggested bulk capacitors—100–330  $\mu\text{F}$  (AVX TPS tantalum or Sanyo OSCON). However, customers should work directly with their power regulator vendor for best values and types of bulk capacitors.

## 21.4 SerDes Block Power Supply Decoupling Recommendations

The SerDes block requires a clean, tightly regulated source of power (XCOREVDD and XPADVDD) to ensure low jitter on transmit and reliable recovery of data in the receiver. An appropriate decoupling scheme is outlined below.

Only surface mount technology (SMT) capacitors should be used to minimize inductance. Connections from all capacitors to power and ground should be done with multiple vias to further reduce inductance.

- First, the board should have at least  $10 \times 10\text{-nF}$  SMT ceramic chip capacitors as close as possible to the supply balls of the device. Where the board has blind vias, these capacitors should be placed directly below the chip supply and ground connections. Where the board does not have blind vias, these capacitors should be placed in a ring around the device as close to the supply and ground connections as possible.
- Second, there should be a 1- $\mu\text{F}$  ceramic chip capacitor from each SerDes supply (XCOREVDD and XPADVDD) to the board ground plane on each side of the device. This should be done for all SerDes supplies.

- Third, between the device and any SerDes voltage regulator there should be a 10- $\mu$ F, low equivalent series resistance (ESR) SMT tantalum chip capacitor and a 100- $\mu$ F, low ESR SMT tantalum chip capacitor. This should be done for all SerDes supplies.

## 21.5 Connection Recommendations

To ensure reliable operation, it is highly recommended to connect unused inputs to an appropriate signal level. Unused active low inputs should be tied to  $NV_{DD}$ ,  $GV_{DD}$ ,  $LV_{DD}$ ,  $LV_{DDA}$  or  $LV_{DDB}$  as required. Unused active high inputs should be connected to VSS. All NC (no-connect) signals must remain unconnected.

Power and ground connections must be made to all external  $V_{DD}$ ,  $NV_{DD}$ ,  $GV_{DD}$ ,  $LV_{DD}$ ,  $LV_{DDA}$ ,  $LV_{DDB}$ , and VSS pins of the device.

## 21.6 Output Buffer DC Impedance

The MPC8313E drivers are characterized over process, voltage, and temperature. For all buses, the driver is a push-pull single-ended driver type (open drain for I<sup>2</sup>C).

To measure  $Z_0$  for the single-ended drivers, an external resistor is connected from the chip pad to  $NV_{DD}$  or VSS. Then, the value of each resistor is varied until the pad voltage is  $NV_{DD}/2$  (see Figure 45). The output impedance is the average of two components, the resistances of the pull-up and pull-down devices. When data is held high, SW1 is closed (SW2 is open) and  $R_P$  is trimmed until the voltage at the pad equals  $NV_{DD}/2$ .  $R_P$  then becomes the resistance of the pull-up devices.  $R_P$  and  $R_N$  are designed to be close to each other in value. Then,  $Z_0 = (R_P + R_N)/2$ .

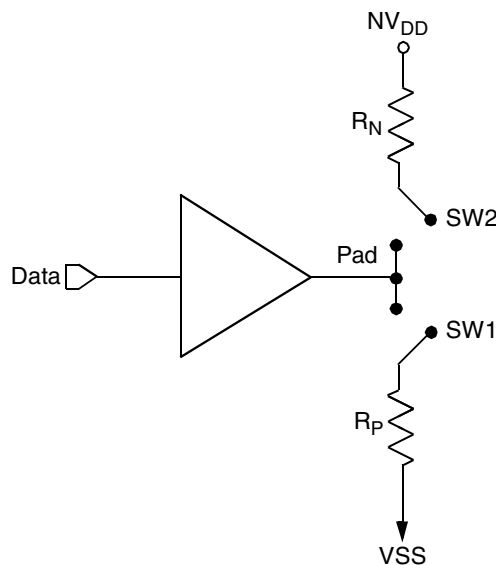


Figure 45. Driver Impedance Measurement

The value of this resistance and the strength of the driver's current source can be found by making two measurements. First, the output voltage is measured while driving logic 1 without an external differential termination resistor. The measured voltage is  $V_1 = R_{source} \times I_{source}$ . Second, the output voltage is measured while driving logic 1 with an external precision differential termination resistor of value  $R_{term}$ . The

measured voltage is  $V_2 = (1/(1/R_1 + 1/R_2)) \times I_{\text{source}}$ . Solving for the output impedance gives  $R_{\text{source}} = R_{\text{term}} \times (V_1/V_2 - 1)$ . The drive current is then  $I_{\text{source}} = V_1/R_{\text{source}}$ .

Table 69 summarizes the signal impedance targets. The driver impedance are targeted at minimum  $V_{\text{DD}}$ , nominal  $NV_{\text{DD}}$ , 105°C.

**Table 69. Impedance Characteristics**

| Impedance    | Local Bus, Ethernet, DUART, Control, Configuration, Power Management | PCI Signals (not including PCI output clocks) | PCI Output Clocks (including PCI_SYNC_OUT) | DDR DRAM  | Symbol            | Unit     |
|--------------|----------------------------------------------------------------------|-----------------------------------------------|--------------------------------------------|-----------|-------------------|----------|
| $R_N$        | 42 Target                                                            | 25 Target                                     | 42 Target                                  | 20 Target | $Z_0$             | $\Omega$ |
| $R_P$        | 42 Target                                                            | 25 Target                                     | 42 Target                                  | 20 Target | $Z_0$             | $\Omega$ |
| Differential | NA                                                                   | NA                                            | NA                                         | NA        | $Z_{\text{DIFF}}$ | $\Omega$ |

**Note:** Nominal supply voltages. See Table 1,  $T_j = 105^\circ\text{C}$ .

## 21.7 Configuration Pin Muxing

The MPC8313E provides the user with power-on configuration options which can be set through the use of external pull-up or pull-down resistors of 4.7 k $\Omega$  on certain output pins (see customer visible configuration pins). These pins are generally used as output only pins in normal operation.

While  $\overline{\text{HRESET}}$  is asserted however, these pins are treated as inputs. The value presented on these pins while  $\overline{\text{HRESET}}$  is asserted, is latched when  $\overline{\text{PORESET}}$  deasserts, at which time the input receiver is disabled and the I/O circuit takes on its normal function. Careful board layout with stubless connections to these pull-up/pull-down resistors coupled with the large value of the pull-up/pull-down resistor should minimize the disruption of signal quality or speed for output pins thus configured.

## 21.8 Pull-Up Resistor Requirements

The MPC8313E requires high resistance pull-up resistors (10 k $\Omega$  is recommended) on open drain type pins including I<sup>2</sup>C pins, Ethernet Management MDIO pin and EPIC interrupt pins.

Correct operation of the JTAG interface requires configuration of a group of system control pins as demonstrated in Figure 46. Care must be taken to ensure that these pins are maintained at a valid deasserted state under normal operating conditions because most have asynchronous behavior and spurious assertion, which give unpredictable results.

Refer to the PCI 2.2 specification for all pull-ups required for PCI.

## 21.9 JTAG Configuration Signals

Boundary scan testing is enabled through the JTAG interface signals. The  $\overline{\text{TRST}}$  signal is optional in IEEE 1149.1, but is provided on all processors that implement the PowerPC architecture. The device requires  $\overline{\text{TRST}}$  to be asserted during reset conditions to ensure the JTAG boundary logic does not interfere with normal chip operation. While it is possible to force the TAP controller to the reset state using only the TCK and TMS signals, systems generally assert  $\overline{\text{TRST}}$  during power-on reset. Because the JTAG interface

is also used for accessing the common on-chip processor (COP) function, simply tying  $\overline{\text{TRST}}$  to  $\overline{\text{PORESET}}$  is not practical.

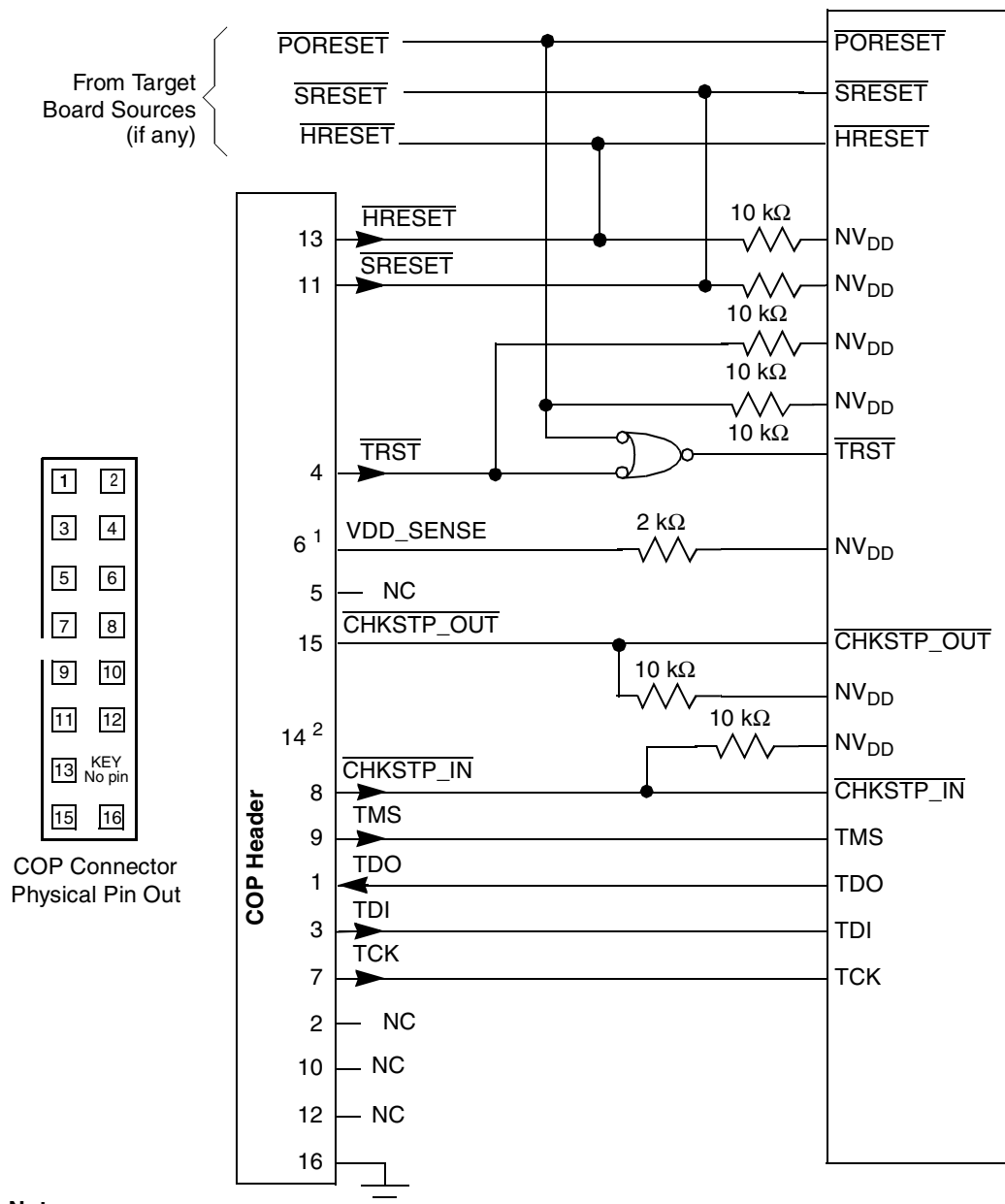
The COP function of these processors allows a remote computer system (typically, a PC with dedicated hardware and debugging software) to access and control the internal operations of the processor. The COP interface connects primarily through the JTAG port of the processor, with some additional status monitoring signals. The COP port requires the ability to independently assert  $\overline{\text{TRST}}$  without causing  $\overline{\text{PORESET}}$ . If the target system has independent reset sources, such as voltage monitors, watchdog timers, power supply failures, or push-button switches, then the COP reset signals must be merged into these signals with logic.

The arrangement shown in [Figure 46](#) allows the COP to independently assert  $\overline{\text{HRESET}}$  or  $\overline{\text{TRST}}$ , while ensuring that the target can drive  $\overline{\text{HRESET}}$  as well. If the JTAG interface and COP header are not used,  $\overline{\text{TRST}}$  should be tied to  $\overline{\text{PORESET}}$  so that it is asserted when the system reset signal ( $\overline{\text{PORESET}}$ ) is asserted.

The COP header shown in [Figure 46](#) adds many benefits—breakpoints, watchpoints, register and memory examination/modification, and other standard debugger features are possible through this interface—and can be as inexpensive as an unpopulated footprint for a header to be added when needed.

The COP interface has a standard header for connection to the target system, based on the 0.025" square-post, 0.100" centered header assembly (often called a Berg header).

There is no standardized way to number the COP header shown in [Figure 46](#); consequently, many different pin numbers have been observed from emulator vendors. Some are numbered top-to-bottom then left-to-right, while others use left-to-right then top-to-bottom, while still others number the pins counter clockwise from pin 1 (as with an IC). Regardless of the numbering, the signal placement recommended in [Figure 46](#) is common to all known emulators.

**Notes:**

1. Some systems require power to be fed from the application board into the debugger repeater card via the COP header. In this case the resistor value for VDD\_SENSE should be around 20Ω.
2. Key location; pin 14 is not physically present on the COP header.

**Figure 46. JTAG Interface Connection**

## 22 Document Revision History

Table 70 provides a revision history for this hardware specification.

**Table 70. Document Revision History**

| Rev. Number | Date   | Substantive Change(s)                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                               |
|-------------|--------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1           | 3/2008 | <ul style="list-style-type: none"> <li>Replaced OVDD with NV<sub>DD</sub> everywhere</li> <li>Added XCOREVDD and XPADVDD to Table 1</li> <li>Moved VDD and VDDC to the top of the table before SerDes supplies in Table 2</li> <li>In Table 2 split DDR row into two from total current requirement of 425 mA. One for DDR1 (131 mA) and other for DDR2 (140 mA).</li> <li>In Table 2 corrected current requirement numbers for NV<sub>DD</sub> from 27 mA to 74 mA, LV<sub>DD</sub> from 60 mA to 16 mA, LV<sub>DDA</sub> from 85 mA to 22 mA and LV<sub>ddb</sub> from 85 mA to 44 mA.</li> <li>In Table 2 corrected Vdd and Vddc current requirements from 560 mA and 454 mA to 469 and 377 mA, respectively. Corrected Avdd1 and Avdd2 current requirements from 10 mA to 2–3 mA, and XCOREVDD from 100 mA to 170 mA.</li> <li>In Table 2, added row stating junction temperature range of 0 to 105°C. Added footnote 2 stating GPIO pins may operate from 2.5-V supply as well when configured for different functionality.</li> <li>In Section 2.1.2, “Power Supply Voltage Specification,” added a note describing the purpose of Table 2.</li> <li>In Section 3, “Power Characteristics,” added a note describing the purpose of Table 5.</li> <li>Rewrote Section 2.2, “Power Sequencing,” and added Figure 2.</li> <li>In Table 4, added “but do include core, USB PLL, and a portion of SerDes digital power...” to Note 1.</li> <li>In Table 4 corrected “Typical power” to “Maximum power” in note 2 and added a note for Typical Power.</li> <li>In Table 4 removed 266-MHz row as 266-MHz core parts are not offered.</li> <li>In Table 5, moved Local bus typical power dissipation under LVdd.</li> <li>Added Table 6 to show the low power mode power dissipation for D3warm mode.</li> <li>In Table 8 corrected SYS_CLK_IN frequency range from 25–66 MHz to 24–66.67 MHz.</li> <li>Added Section 8.3, “eTSEC IEEE 1588 AC Specifications”</li> <li>In Table 39 changed minimum value of USB input hold t<sub>USIXKH</sub> from 0 to 1ns</li> <li>Added Table 40 and Table 41 showing USB clock in specifications</li> <li>In Table 43, added rows for t<sub>LALEHOV</sub>, t<sub>LALETOT1</sub>, t<sub>LALETOT2</sub>, and t<sub>LALETOT3</sub> parameters. Added Figure 25.</li> <li>In Table 47, removed row for rise time (t<sub>I2CR</sub>). Removed minimum value of t<sub>I2CF</sub>. Added note 5 stating that the device does not follow the I2C-BUS Specifications version 2.1 regarding the t<sub>I2CF</sub> AC parameter.</li> <li>In Table 53, added a note stating: “This specification only applies to GPIO pins that are operating from a 3.3-V supply. See Table 60 for the power supply listed for the individual GPIO signal.” [</li> <li>Added Table 54 to show DC characteristics for GPIO pins supplied by a 2.5-V supply. Same as eTSEC DC characteristics when operating at 2.5 V.</li> <li>In Section 19, “Clocking,” corrected the sentence “When the device is configured as a PCI agent device, PCI_SYNC_IN is the primary input clock.” to state “When the device is configured as a PCI agent device, PCI_CLK is the primary input clock.”</li> <li>Added “Value is decided by RCWLR[COREPLL]” to note 1 of Figure 42</li> <li>Added paragraph and Figure 44 to Section 21.2, “PLL Power Supply Filtering.”</li> <li>Added Section 21.4, “SerDes Block Power Supply Decoupling Recommendations</li> <li>Removed the two figures on PCI undershoot/overshoot voltages and maximum AC waveforms from Section 2.1.2, “Power Supply Voltage Specification,”</li> </ul> |

Table 70. Document Revision History

|   |        |                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
|---|--------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1 | 3/2008 | <ul style="list-style-type: none"> <li>• In <a href="#">Table 60</a>, added LBC_PM_REF_10 &amp; LSRCID3 as muxed with USBDR_PCTL1</li> <li>• In <a href="#">Table 60</a>, added LSRCID2 as muxed with USBDR_PCTL0</li> <li>• In <a href="#">Table 60</a>, added LSRCID1 as muxed with USBDR_PWRFAULT</li> <li>• In <a href="#">Table 60</a>, added LSRCID0 as muxed with USBDR_DRIVE_VBUS</li> <li>• In <a href="#">Table 60</a>, moved T1, U2, &amp; V2 from <math>V_{DD}</math> to XCOREVDD.</li> <li>• In <a href="#">Table 60</a>, moved P2, R2, &amp; T3 from <math>V_{SS}</math> to XCOREVSS.</li> <li>• In <a href="#">Table 60</a>, moved P5, &amp; U4 from <math>V_{DD}</math> to XPADVDD.</li> <li>• In <a href="#">Table 60</a>, moved P3, &amp; V4 from <math>V_{SS}</math> to XPADVSS.</li> <li>• In <a href="#">Table 60</a>, removed “Double with pad” for <math>AV_{DD1}</math> and <math>AV_{DD2}</math> and moved <math>AV_{DD1}</math> and <math>AV_{DD2}</math> to Power and Ground Supplies section</li> <li>• In <a href="#">Table 60</a>, added impedance control requirements for SD_IMP_CAL_TX (100 ohms to GND) and SD_IMP_CAL_RX (200 ohms to GND).</li> <li>• In <a href="#">Table 60</a>, updated muxing in pinout to show new options for selecting IEEE 1588 functionality. Added footnote 8</li> <li>• In <a href="#">Table 60</a>, updated muxing in pinout to show new LBC ECC boot enable control muxed with eTSEC1_MDC</li> <li>• Added pin type information for power supplies.</li> <li>• Removed N1 and N3 from Vss section of <a href="#">Table 60</a>. Added Therm0 and Therm1 (N1 and N3, respectively). Added note 7 to state: “Internal thermally sensitive resistor, resistor value varies linearly with temperature. Useful for determining the junction temperature.”</li> <li>• In <a href="#">Table 62</a> corrected maximum frequency of Local Bus Frequency from “33–66” to 66 MHz</li> <li>• In <a href="#">Table 62</a> corrected maximum frequency of PCI from “24–66” to 66 MHz</li> <li>• Added “which is determined by RCWLR[COREPLL],” to the note in <a href="#">Section 19.2, “Core PLL Configuration”</a> about the vco divider.</li> <li>• Added “(vcod)” next to VCO divider column in <a href="#">Table 65</a>. Added footnote stating that core_clk frequency must not exceed its maximum, so 2.5:1 and 3:1 core_clk:csb_clk ratios are invalid for certain csb_clk values.</li> <li>• In <a href="#">Table 66</a>, notes were confusing. Added note 3 for vco column, note 4 for CSB (csb_clk) column, note 5 for USB ref column, and note 6 to replace “Note 1”. Clarified note 4 to explain erratum eTSEC40.</li> <li>• In <a href="#">Table 66</a>, updated note 6 to specify USB reference clock frequencies limited to 24 and 48 for rev. 2 silicon.</li> <li>• Replaced <a href="#">Table 68</a> “Thermal Resistance for TEPBGAI1 with Heat Sink in Open Flow”.</li> <li>• Removed last row of <a href="#">Table 19</a>.</li> <li>• Removed 200 MHz rows from <a href="#">Table 20</a> and <a href="#">Table 5</a>.</li> <li>• Changed VIH minimum spec from 2.0 to 2.1 for clock, PIC, JTAG, SPI, and reset pins in <a href="#">Table 9</a>, <a href="#">Table 44</a>, <a href="#">Table 51</a>, <a href="#">Table 56</a>, and <a href="#">Table 58</a>.</li> <li>• Added <a href="#">Figure 3</a> showing the DDR input timing diagram.</li> <li>• In <a href="#">Table 19</a>, removed “/MDM” from the “MDQS-MDQ/MECC/MDM” text under the Parameter column for the tCISKEW parameter. MDM is an output signal and should be removed from the input AC timing spec table (tCISKEW).</li> <li>• Added “and power” to rows 2 and 3 in <a href="#">Table 10</a></li> <li>• Added the sentence “Once both the power supplies...” and <math>\overline{PORESET}</math> to <a href="#">Section 2.2, “Power Sequencing,”</a> and <a href="#">Figure 2</a>.</li> <li>• In <a href="#">Figure 20</a>, corrected “USB0_CLK/USB1_CLK/DR_CLK” with “USBDR_CLK”</li> <li>• In <a href="#">Table 39</a>, clarified that AC specs are for ULPI only.</li> </ul> |
| 0 | 6/2007 | Initial release.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          |

## 23 Ordering Information

Ordering information for the parts fully covered by this specification document is provided in [Section 23.1, “Part Numbers Fully Addressed by This Document.”](#)

### 23.1 Part Numbers Fully Addressed by This Document

[Table 71](#) provides the Freescale part numbering nomenclature for the MPC8313E. Note that the individual part numbers correspond to a maximum processor core frequency. For available frequencies, contact your local Freescale sales office. In addition to the processor frequency, the part numbering scheme also includes an application modifier which may specify special application conditions. Each part number also contains a revision code which refers to the die mask revision number.

**Table 71. Part Numbering Nomenclature**

| <b>MPC</b>          | <b>nnnn</b>            | <b>e</b>                             | <b>t</b>                              | <b>pp</b>                   | <b>aa</b>                               | <b>a</b>             | <b>x</b>                                   |
|---------------------|------------------------|--------------------------------------|---------------------------------------|-----------------------------|-----------------------------------------|----------------------|--------------------------------------------|
| <b>Product Code</b> | <b>Part Identifier</b> | <b>Encryption Acceleration</b>       | <b>Temperature Range <sup>3</sup></b> | <b>Package <sup>1</sup></b> | <b>e300 core Frequency <sup>2</sup></b> | <b>DDR Frequency</b> | <b>Revision Level</b>                      |
| MPC                 | 8313                   | Blank = Not included<br>E = included | Blank = 0 to 105°C<br>C= -40 to 105°C | VR= PB free<br>TEPBGAII     | AF = 333 MHz                            | F = 333 MHz          | Contact local<br>Freescale<br>sales office |

**Notes:**

1. See [Section 18, “Package and Pin Listings,”](#) for more information on available package types.
2. Processor core frequencies supported by parts addressed by this specification only. Not all parts described in this specification support all core frequencies. Additionally, parts addressed by Part Number Specifications may support other maximum core frequencies.
3. Contact local Freescale office on availability of parts with C temperature range

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